

Status of GridPix Developments

Harry van der Graaf (Nikhef, Amsterdam)
6th RD51 Collaboration Meeting
Bari, Oct 7, 2010

- approval GridPix/Gossip as **ATLAS Upgrade** R & D project;

- MEMS Technology

 - 18 pcs GridPix made in 2 weeks @ MESA+

 - Univ. Bonn & IZM-Fraunhofer Berlin

- Testbeam Aug 2010 @RD-51 site, CERN

 - discharge proof

 - confirm simulations

 - New Gas system

 - ReLaXd readout system operational

- Saclay/Freiburg: Avalanche statistics and single electron counting with a Timepix-InGrid detector

- Applications:

 - XENON/DARWIN WIMP-search experiments

 - Polarized photon detection PolaPix

 - CAST

 - NA61

 - LHeC

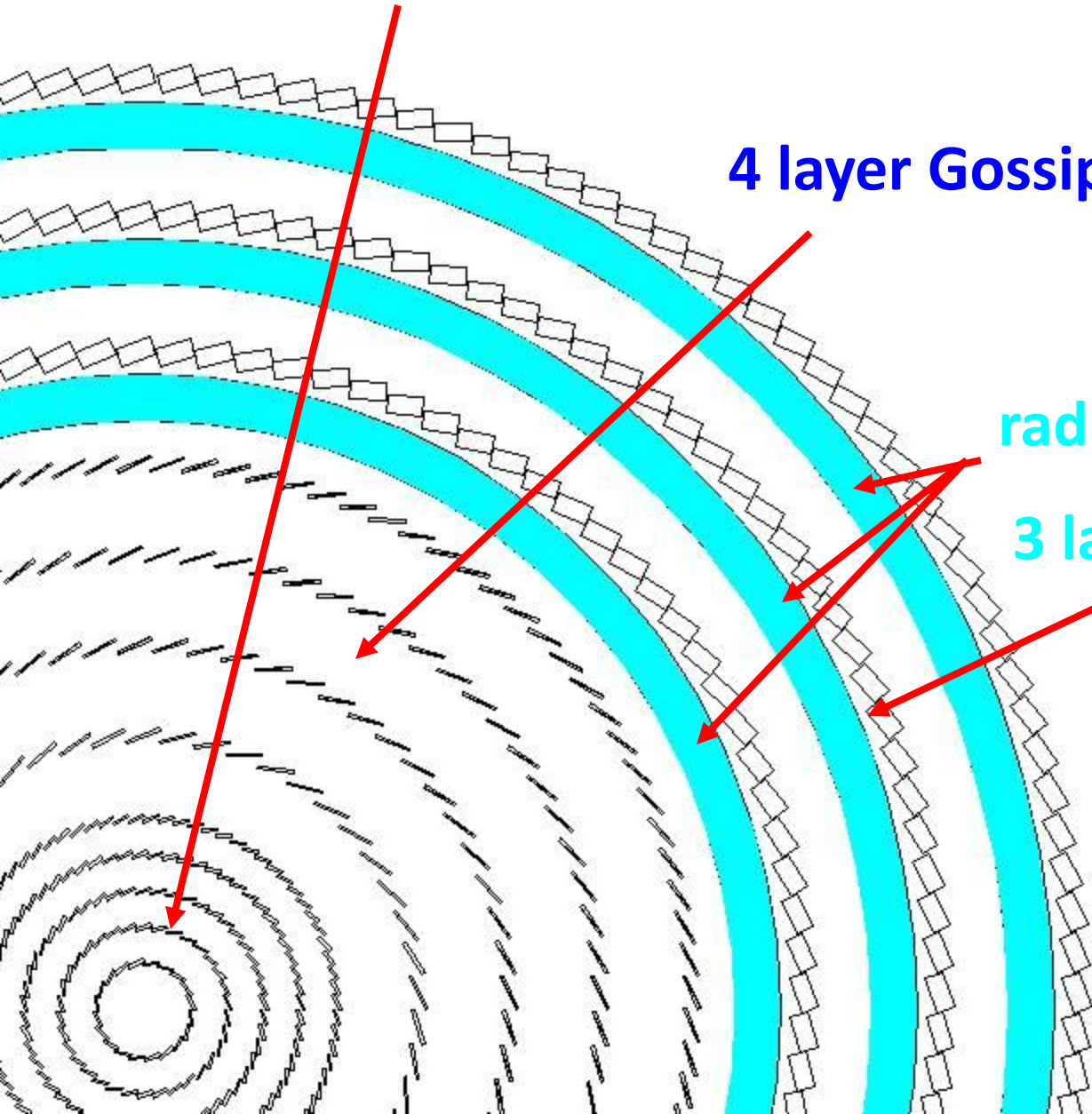
- mini-HV

NEW

ATLAS:

“The baseline ATLAS inner tracker upgrade is an all- silicon detector. New technologies such as GridPix and the Gossip version of it could become an alternative sensor technology to pursue for part of the detector. They would only be adopted in case of major performance or cost advantages over silicon technology, or if technical issues are found in the silicon projects in the next 2--3 years. The EB has considered the Gossip R&D proposal, **and supports this R&D for a limited duration of 3 years to demonstrate and quantify performance, cost and reliability.** In 2013, ATLAS will review the results and consider if there are sufficient elements for further pursuance of this technology for ATLAS”

5 (double) layer Gossip Pixel



4 layer Gossip Strixel

radiator

3 layers Gossip TRT

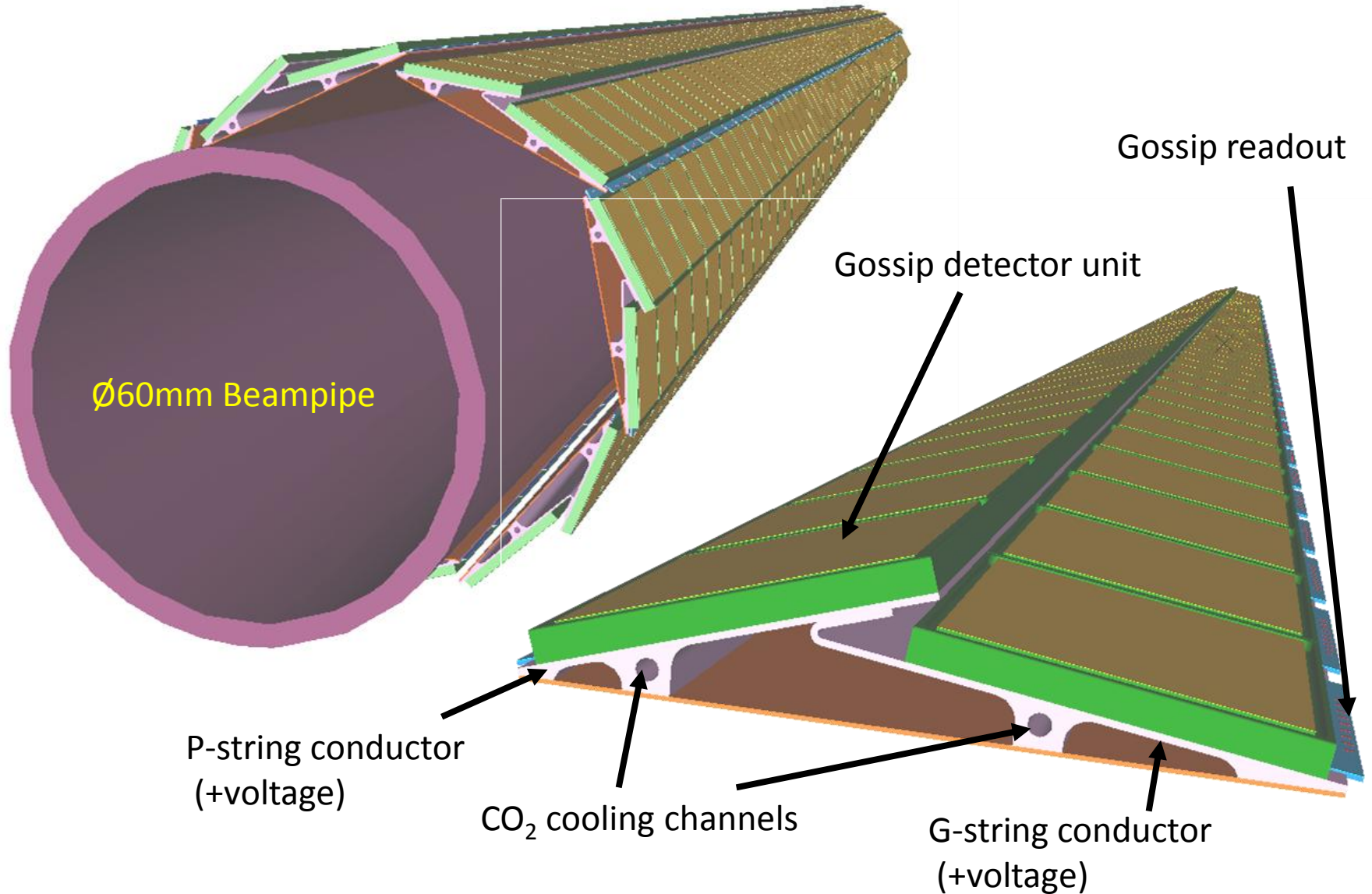
ATLAS: FE-I4 (vertex pixel) chip from foundry:
make proto vertex detector of it.

Alternative for TimePix:

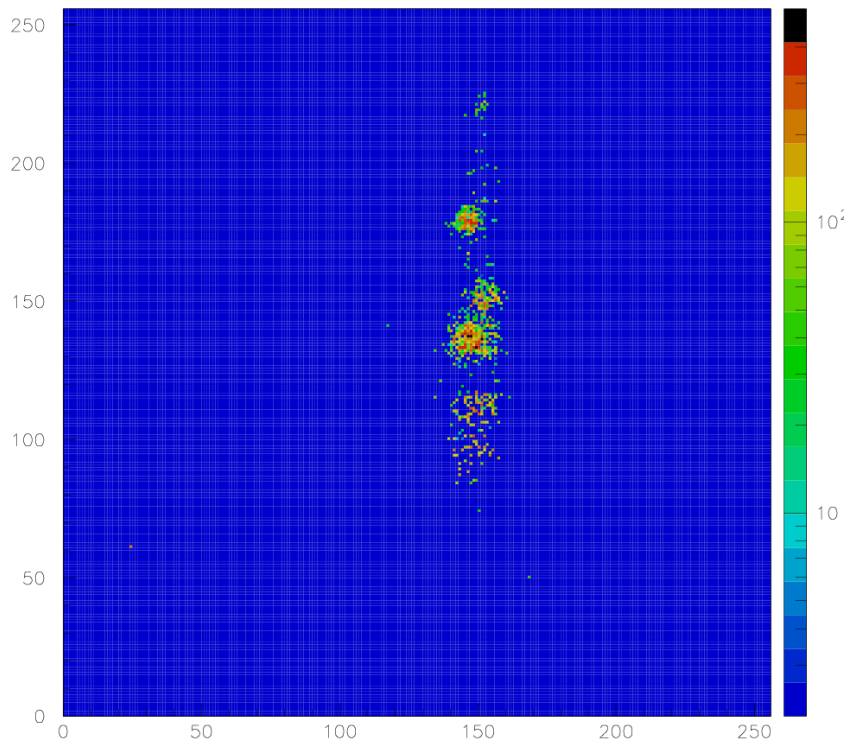
Gossip made with FE-I4 pixel chip:
rate effect studies (in testbeam)

GOAT: GOssip in ATLAS

Inner Layer: 7 double Goat strings

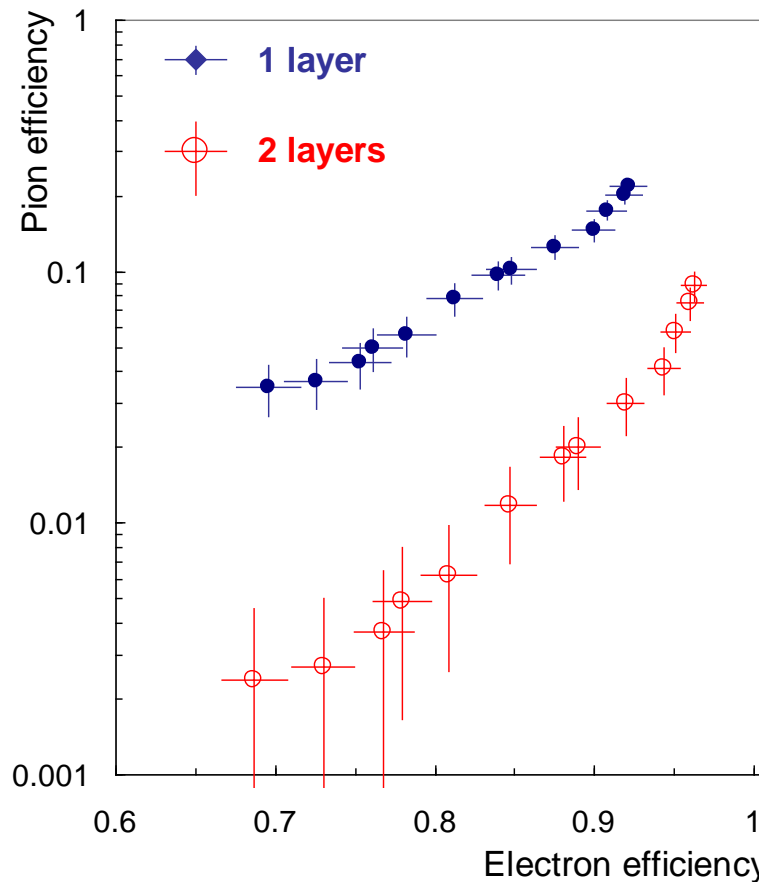


Test beam results: Particle Identification



Two methods were used

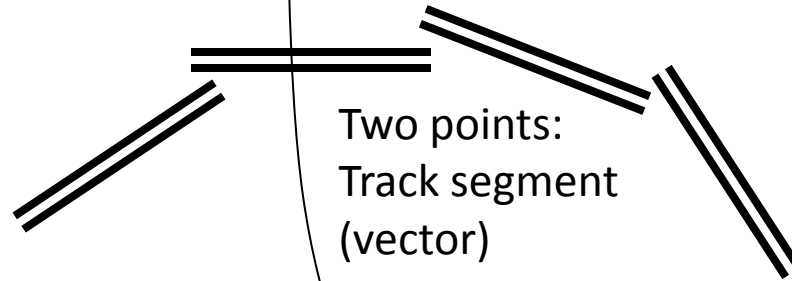
1. Total energy deposition
2. Cluster counting technique



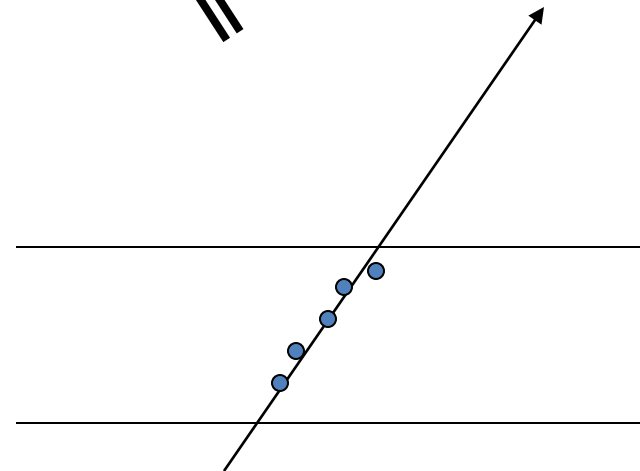
Pion registration efficiency as a function of electron efficiency for 1 and 2 layers of the detector. Cluster counting method.

TRD with two detector layers (total thickness ~ 40 cm) allows to achieve rejection factor of ~ 50 for 90% electron efficiency.

Double (Si) layers



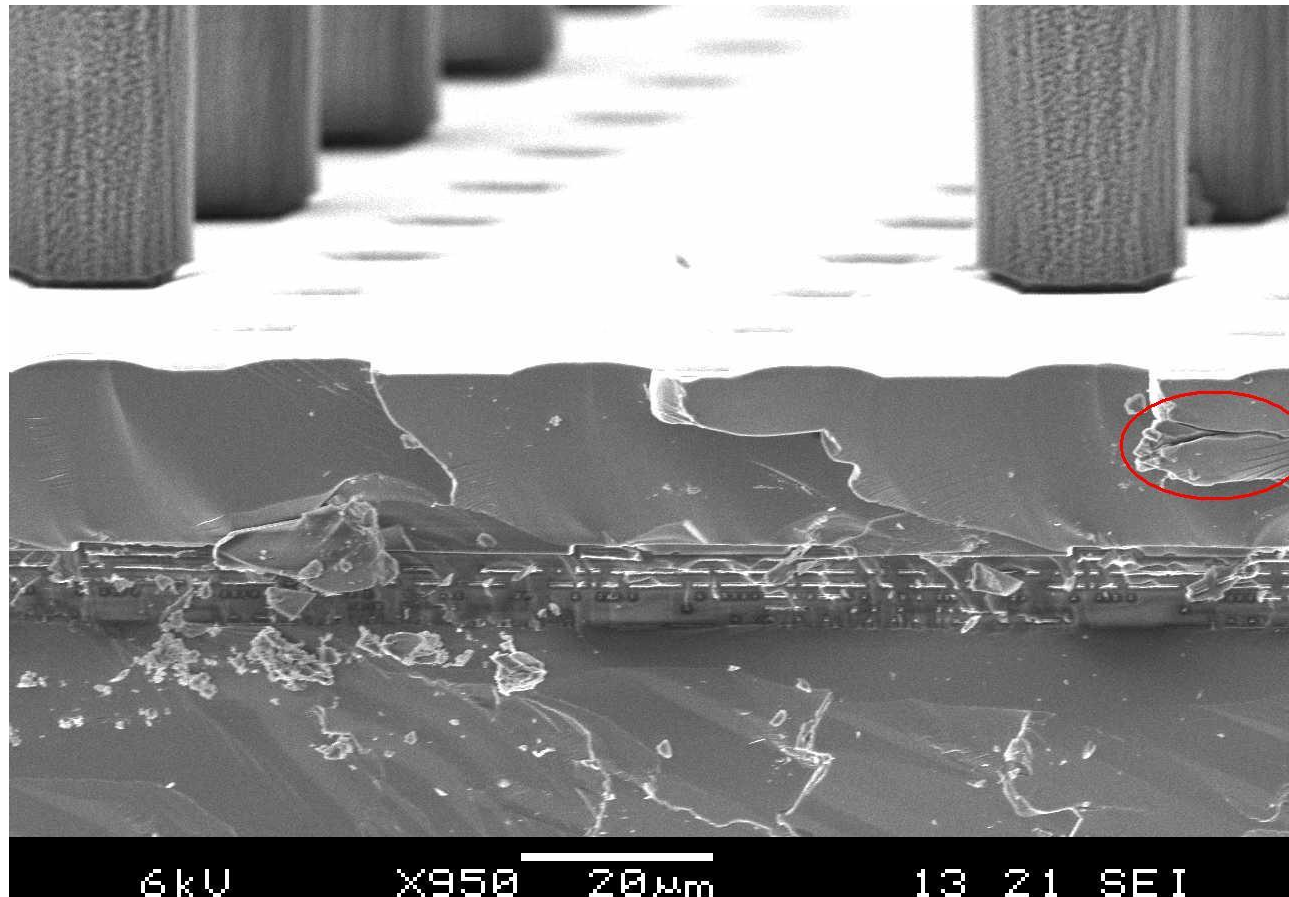
Requires inter-pixel chip communication

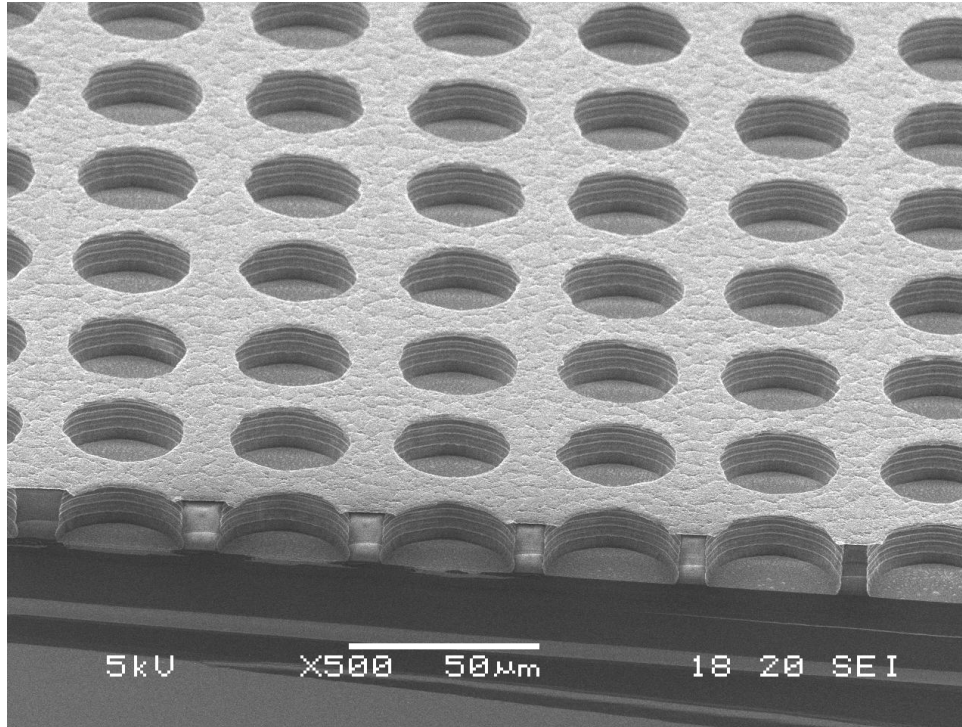


Gossip measures track segment in single layer

MEMS Technology

- May 2010: 18 pcs GridPix (= TimePix + SiNProt + InGrid) made
 - quite good sparkproof!
- weak spots in protection layer found: future: all ceramic InGrid

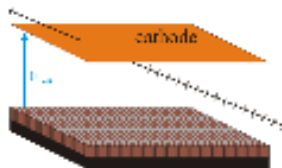




First GEMGrid with SiO₂ as insulating spacer between grid and substrate
Victor Blanco Carballo, MESA+/Nikhef

- Technology transfer to SMC, Edinburgh: failure
- Technology transfer to IZM-Berlin: first working GEMGrids

Goal: to make robust, lasting InGrids on 8" wafers, for a low price



New Wafer-level Process



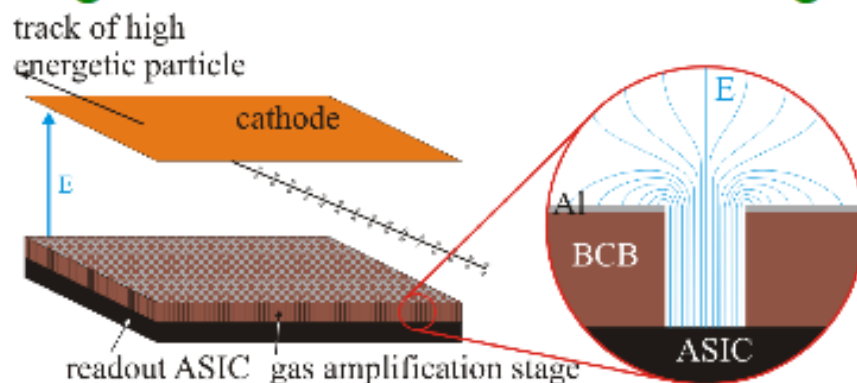
Small number of InGrids produced at Twente satisfy neither the demand of R&D nor for any large experiments.

=> Need to transfer process to wafer-level production

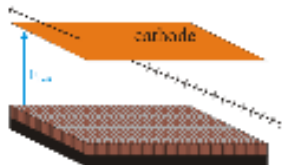
Problem: very delicate structure → **need more mechanical stability**



At GEMGrid the grid rests on a solid insulating layer with holes.



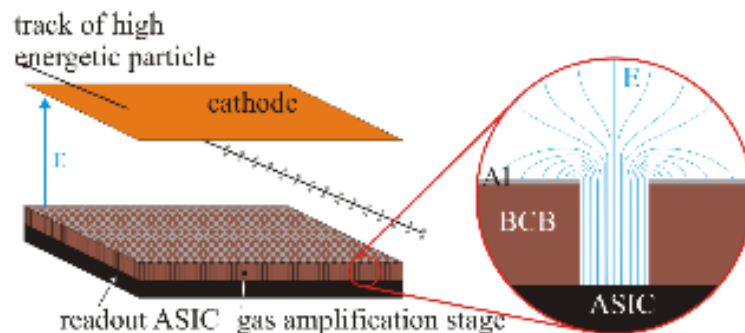
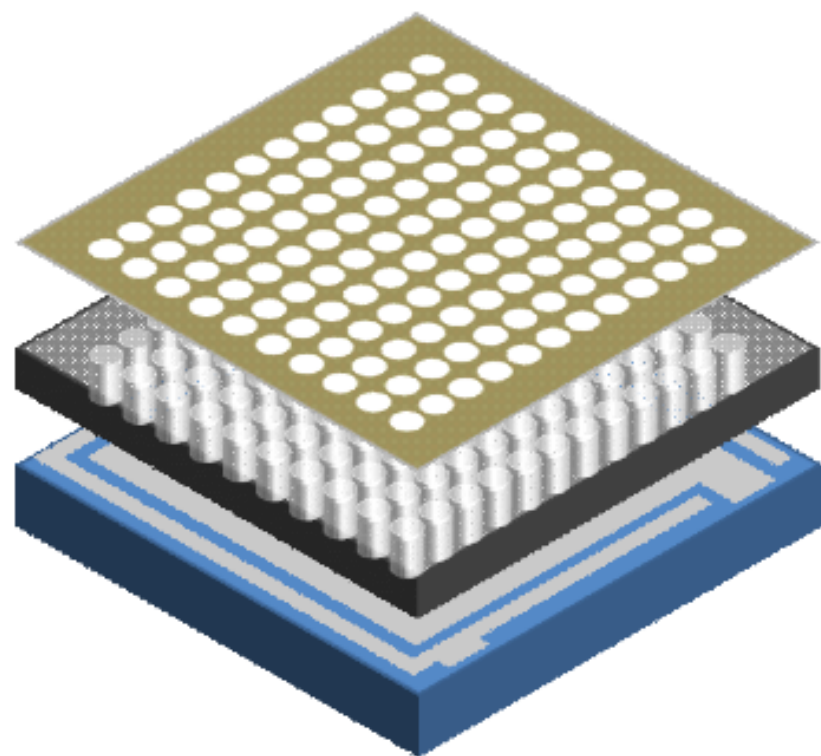
V. Blanco Carballo, et al.,
Nucl. Instrum. Meth. A
608 (2009) 86



Wafer Level Design of GEMGrid Test Chip (I)



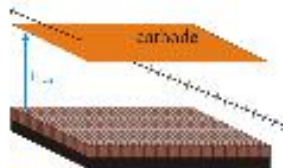
Setup of GEMGrid Test Chip



Perforated top electrode – Aluminum

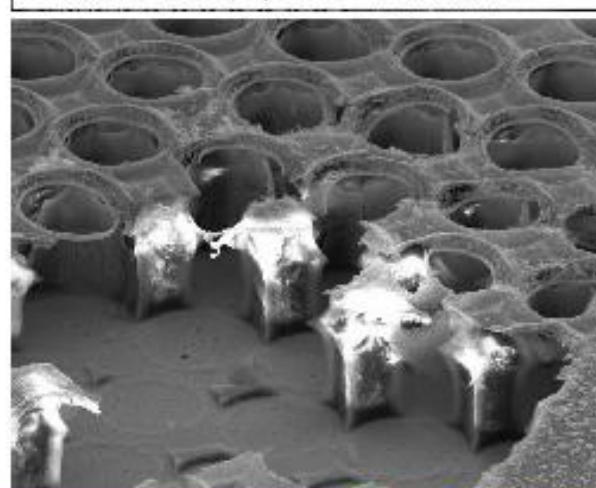
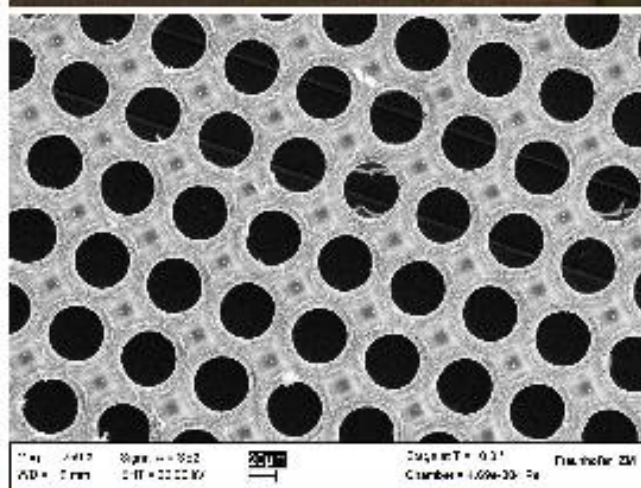
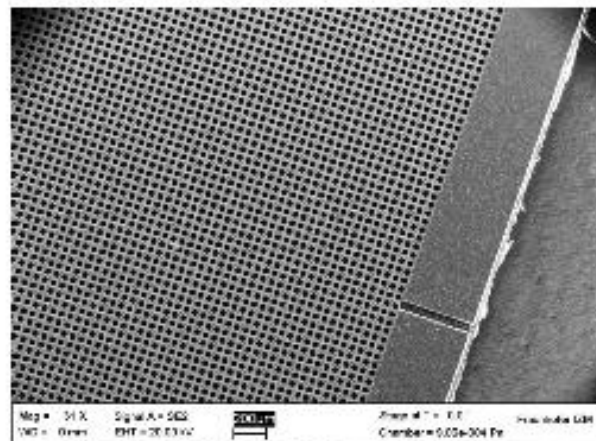
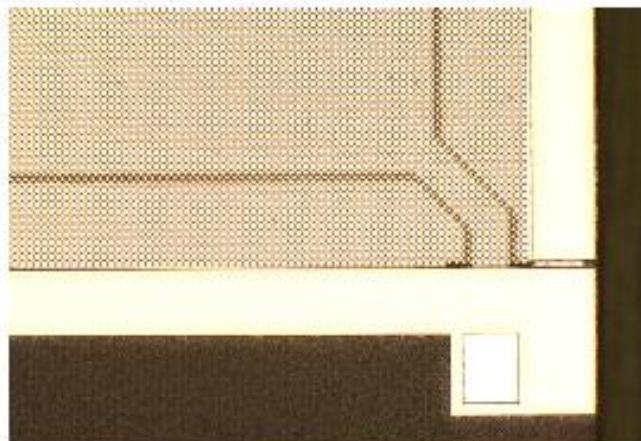
Meshed dielectric layer – BCB

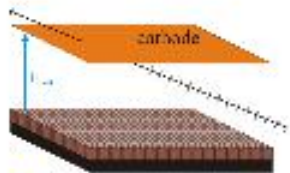
Siliconwafer with bottom electrode
- Aluminum



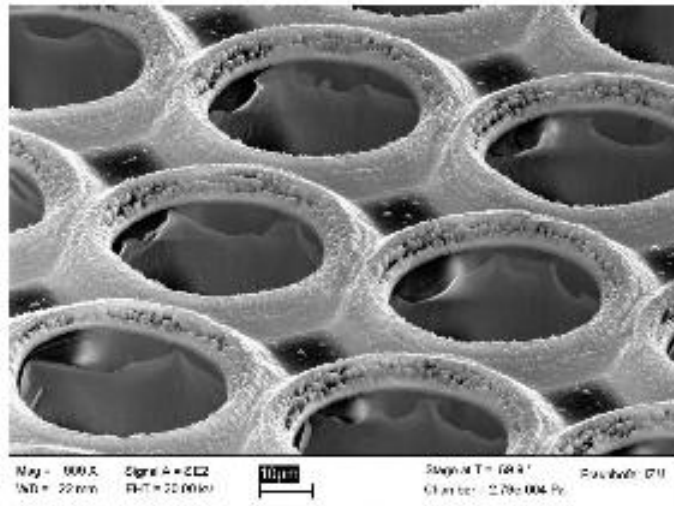
Processing of GEMGrid Test Chip (II)

GEMGrid Test Chip after BCB Dry Etch



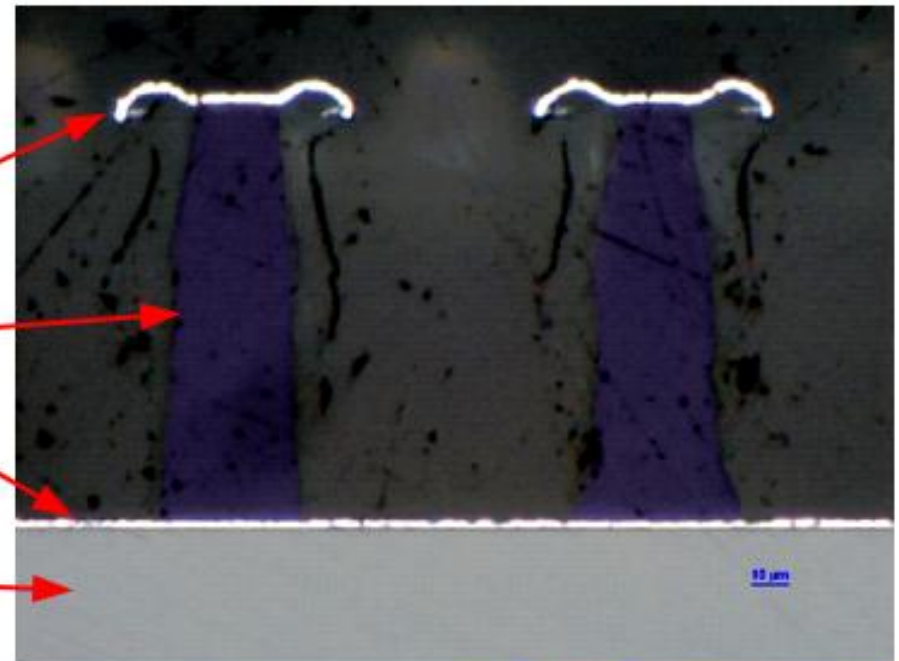


Processing of GEMGrid Test Chip (III)



Cross section of GEMGrid test chip
embedded in a transparent Epoxy

BCB pillars blue coloured

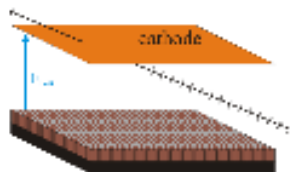


Top electrode – aluminum

Dielectric layer- BCB

Bottom electrode – aluminum

Silicon wafer



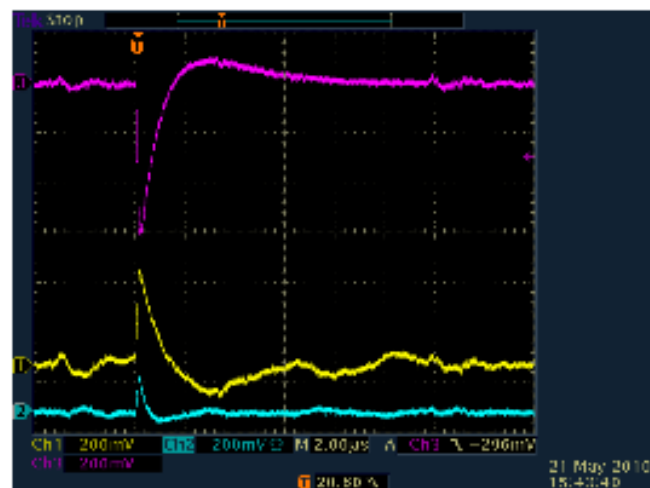
First Signals



- The detector was flushed with various gas mixtures.
- High voltage was applied to the grid. → low leakage current.
- All 3 signals (**pad**, **ring**, **decouple from grid**) were fed into a slow preamplifier (rise time 180 ns) and visualized with an oscilloscope.
- Occasional signals in agreement with cosmic rays were observed
- Rate was strongly increased by radioactive sources.

signals of ^{90}Sr in Ar:iButan 95:5

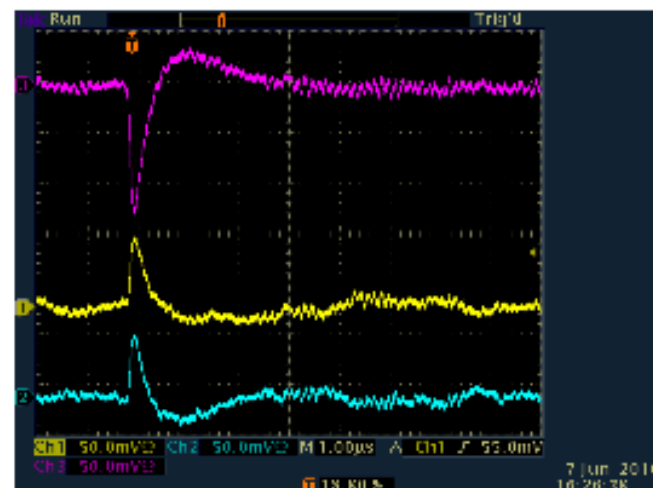
signals of ^{55}Fe in He:iButan 95:5



signal of grid

signal of pad

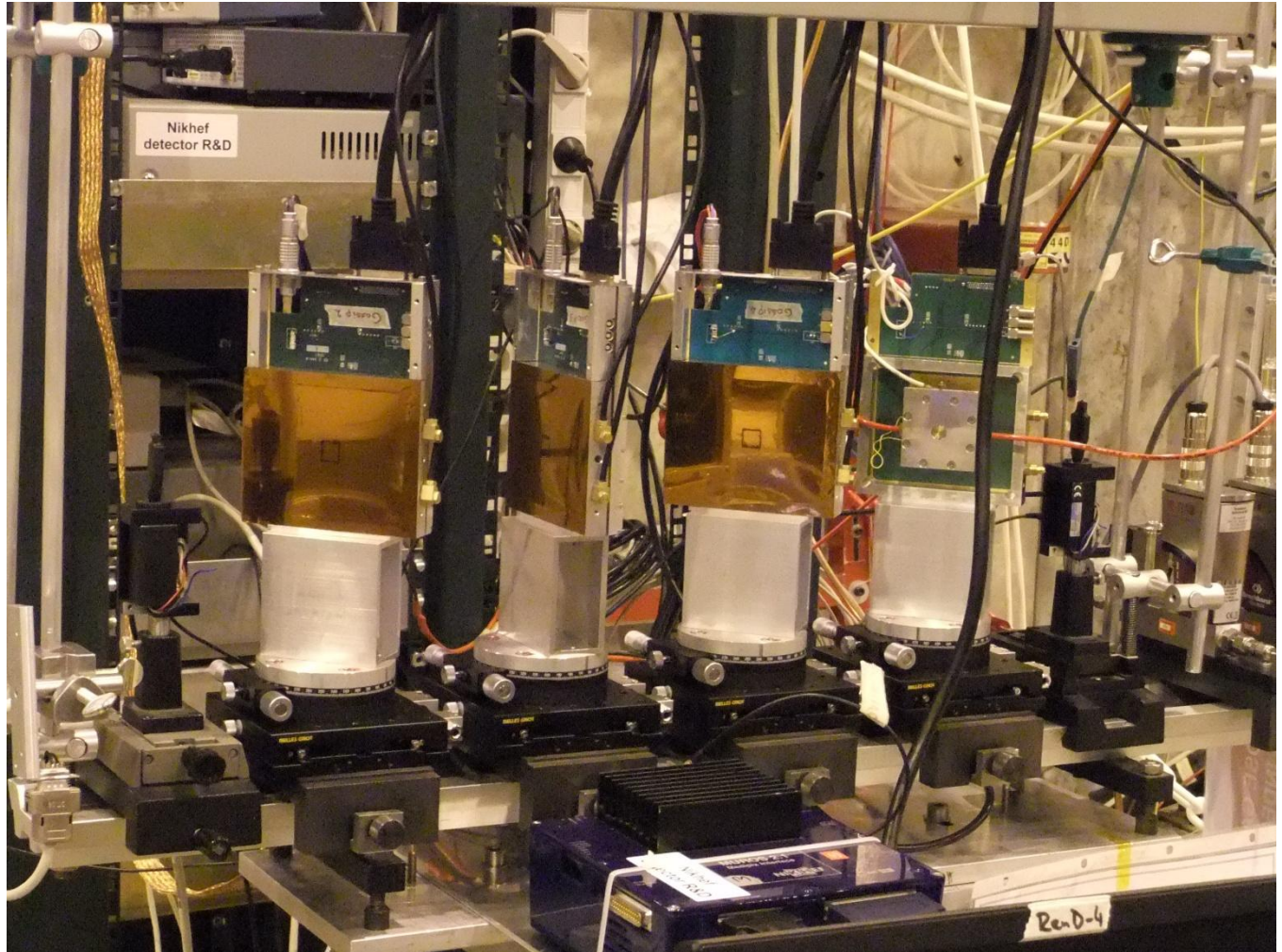
signal of ring





Gossip testbeam August 12 – 22 , 2010

Maarten van Dijk
Martin Fransen
Harry van der Graaf
Fred Hartjes
Wilco Koppert
Sjoerd Nauta
Rolf Schön



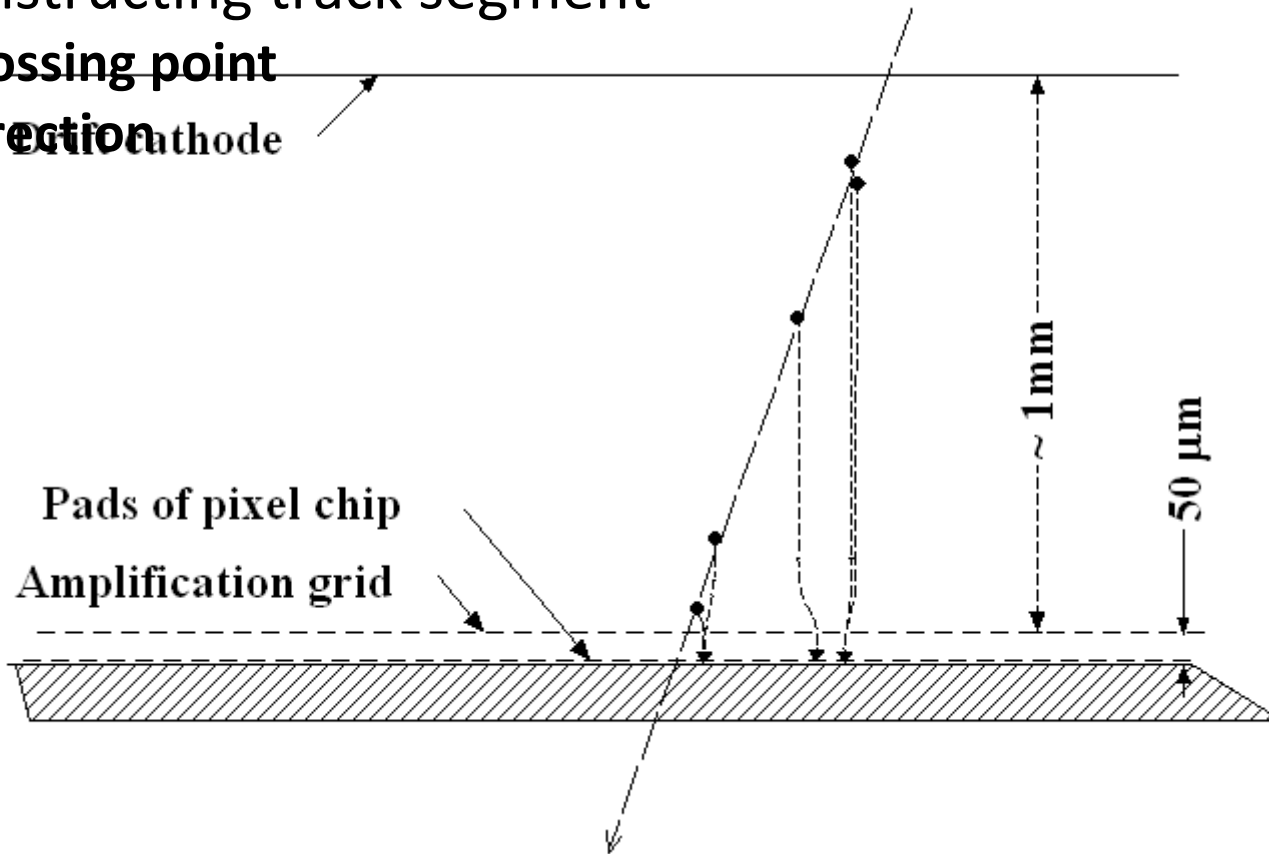
Testbeam Aug 2010, RD51/H4, SPS, CERN

Gossip functioning

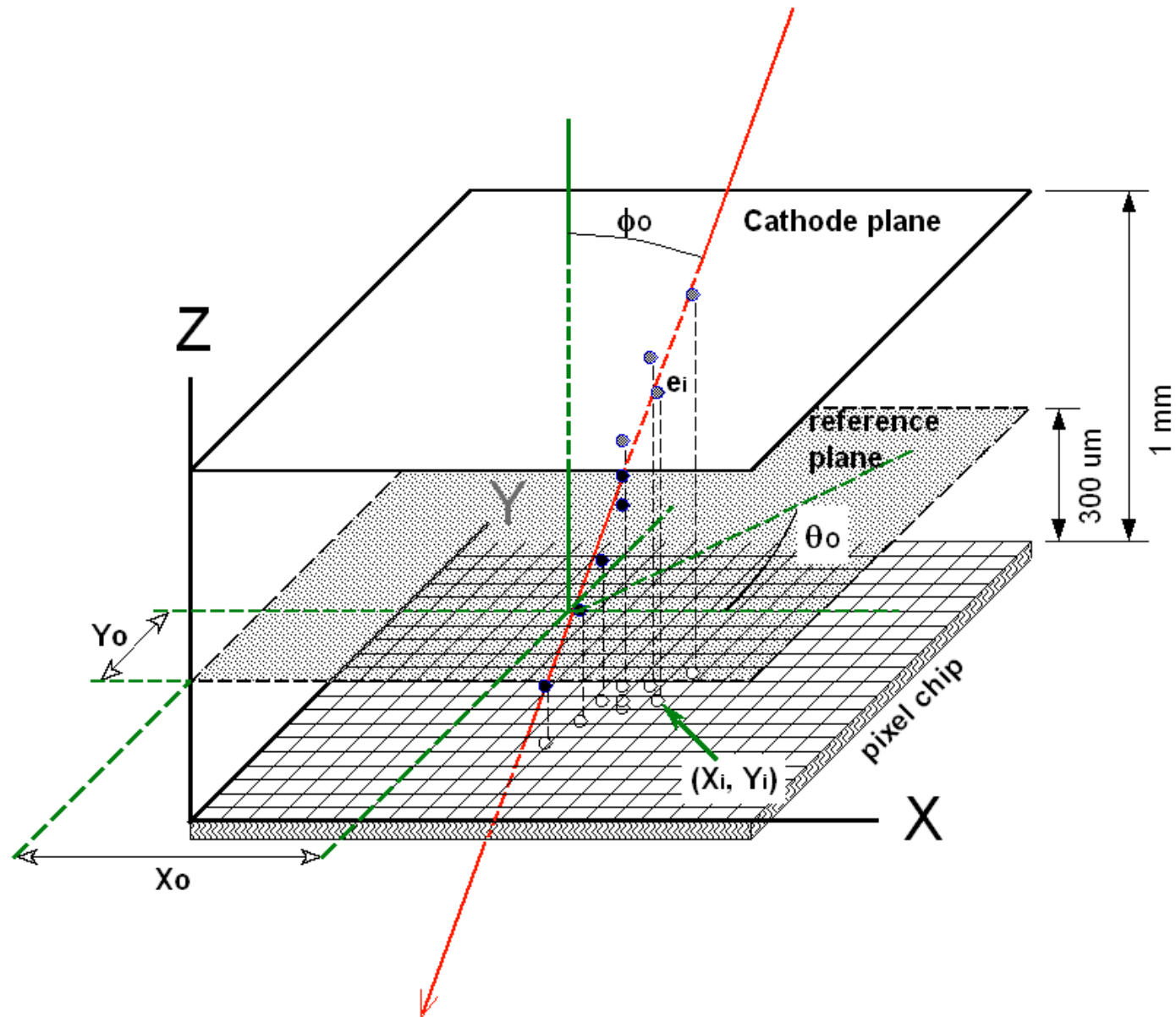
- Pixel chip with integrated Micromegas (InGrid)
- Drift gap height 1 mm
 - Getting > 95% track detection efficiency
- Often detecting individual electrons
- Reconstructing track segment

● **Crossing point**

● **Direction**



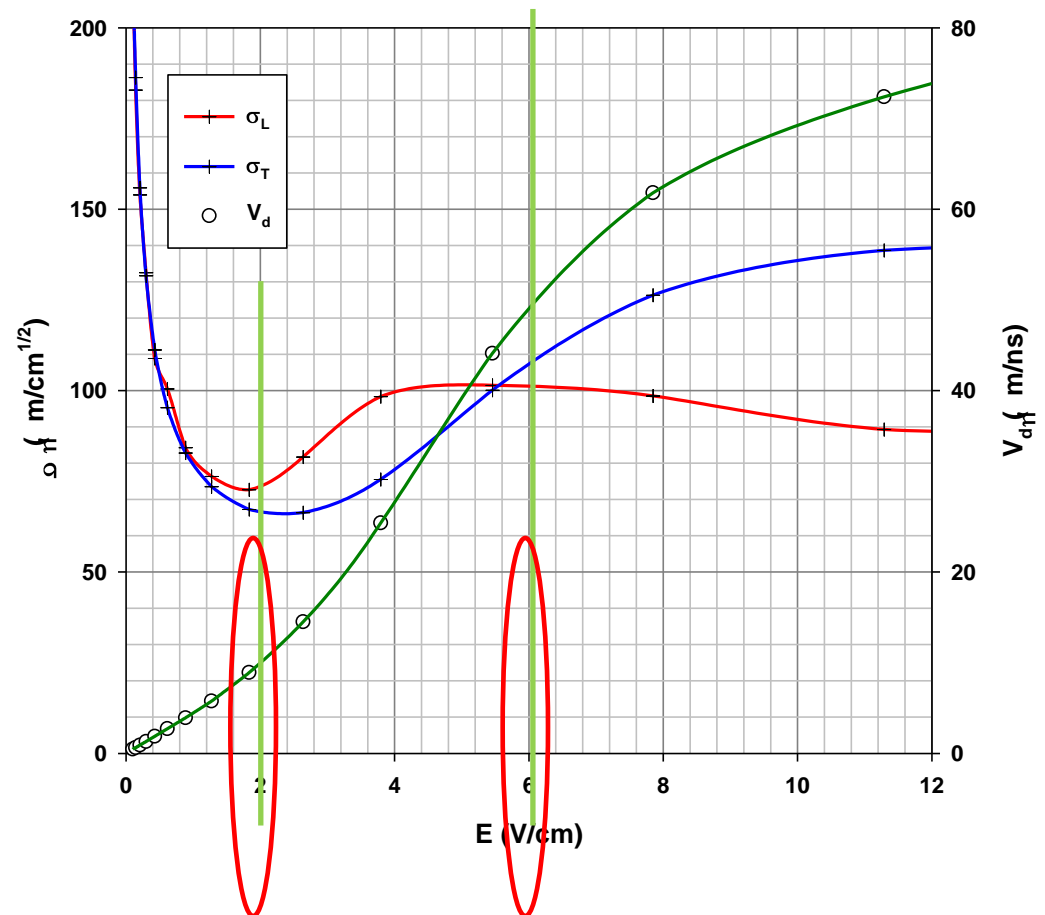
Reconstructing track segment



Chamber gas: DME/CO₂ 50/50

Calculated diffusion (σ) and drift velocity (V_d) of DME/CO₂ 50/50 vs electrical field (E)

- DME/CO₂ 50/50
 - Very slow and “cool” gas
 - High drift field required
 - Very low diffusion
- Drift fields used in Gossips
 - **2 kV/cm** (lowest diffusion)
 - **6 kV/cm** ($V_d = 50 \mu\text{m/ns}$)

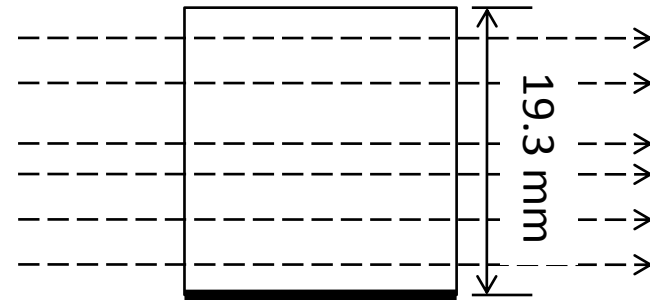
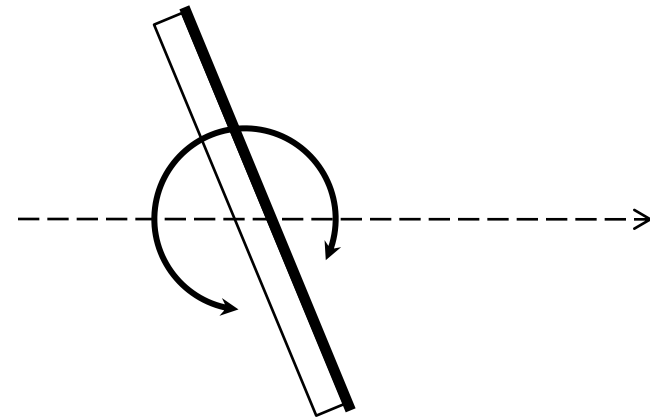


1. Gossip parameters

- Position resolution
- Angular resolution of track segment
- Track detection efficiency
- Dependence on gas gain
- Double track separation

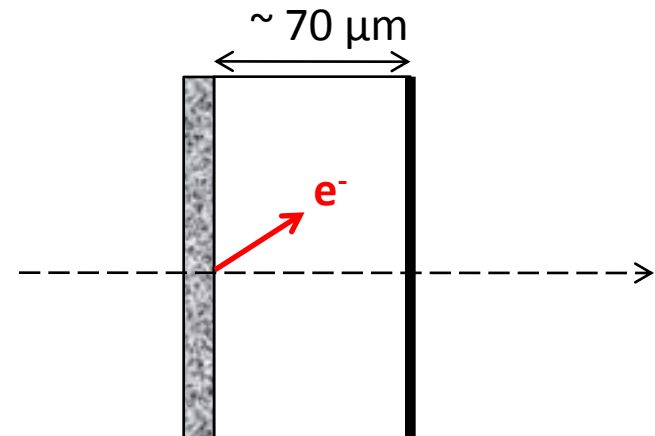
2. Characterisation of DME/CO₂ 50/50 mixture

- Primary ionisation/cluster density
- Drift velocity
- Transverse diffusion



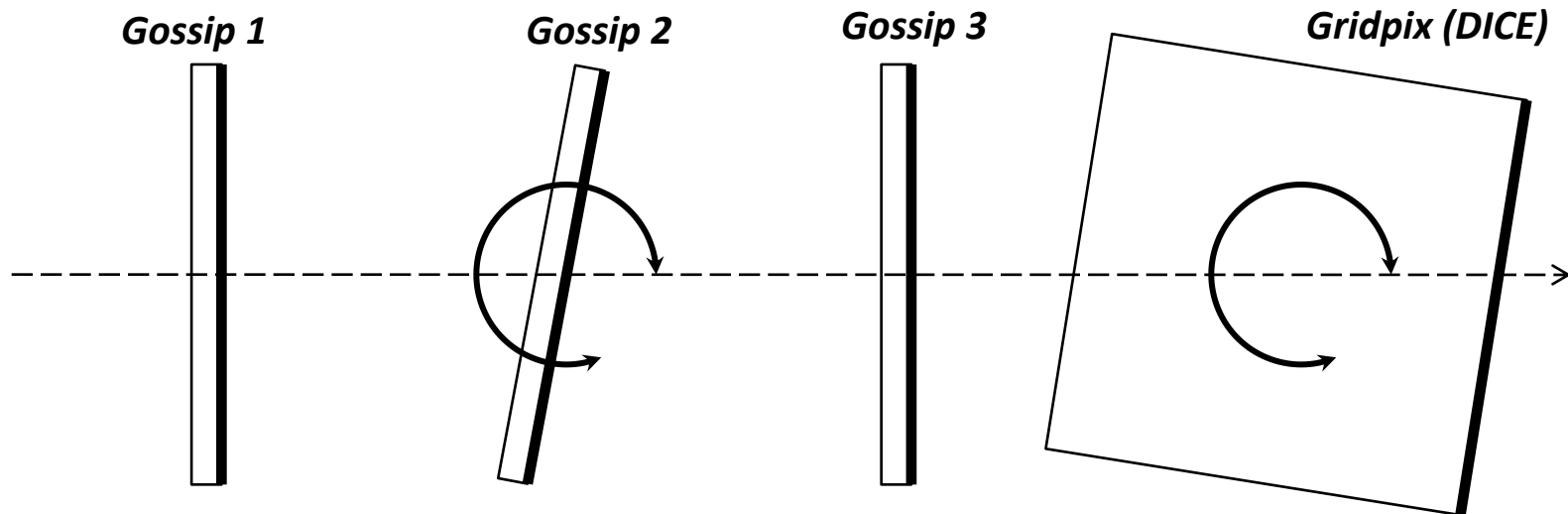
3. Knock off emission from cathode

- PillarPix detector, NO drift gap
- Detecting knock-off electrons from cathode surface
- Cathode from three different materials: **doped diamond; Cu; Al**



Using Gossip/GridPix telescope as a reference

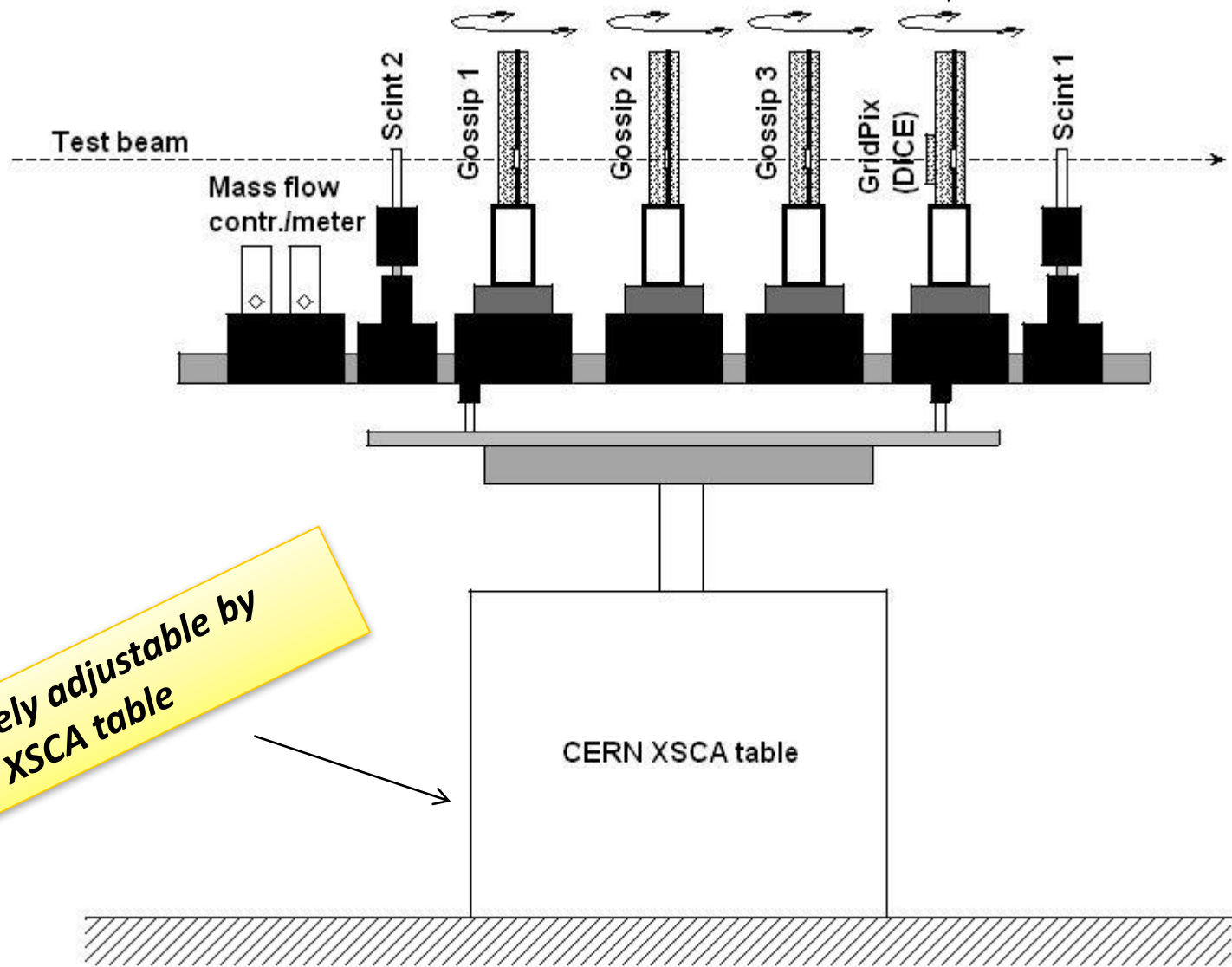
- Measurements done with Gossip 2
- Define track with Gossip 1 and 3
- Reject bad events using the Gridpix detector
 - Wrong angle (background tracks)
 - Outside fiducial volume
 - Multiple tracks (showers)



Mechanical set-up in testbeam

Angular adjustment

- Optical bench
- 4 Gridpix detectors
 - 3 x Gossip
 - GridPix
- 2 Scintillators 15 x 15 mm
- Mass flow controller/meter

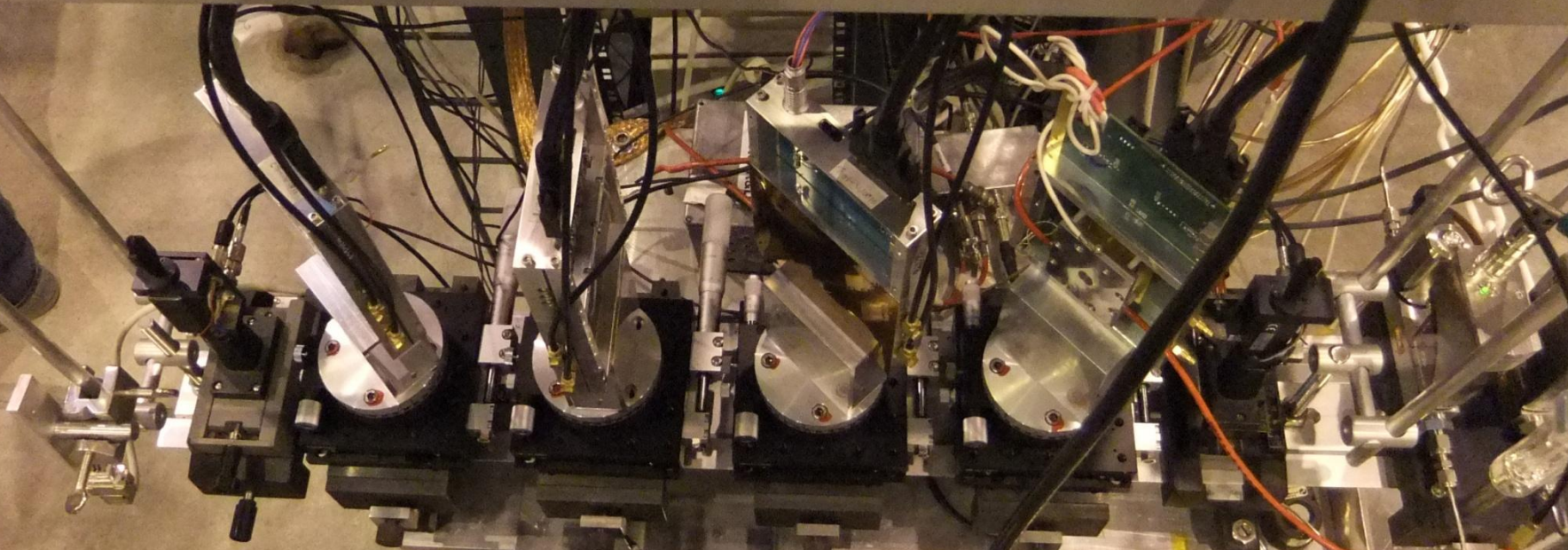


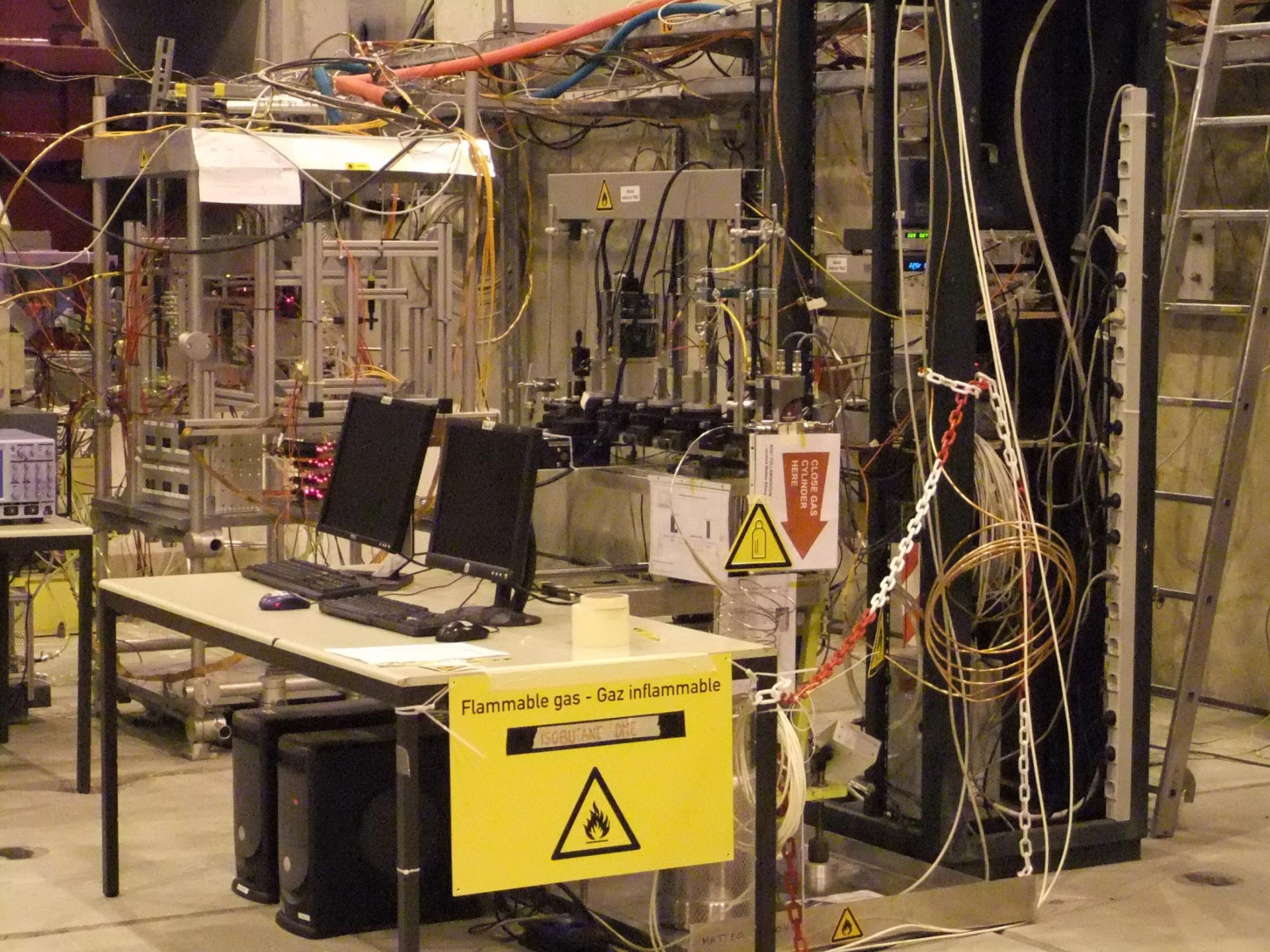
Remotely adjustable by CERN XSCA table

CERN XSCA table



Nikhef
detector R&D





Flammable gas - Gaz inflammable

ISOBUTANE ONE

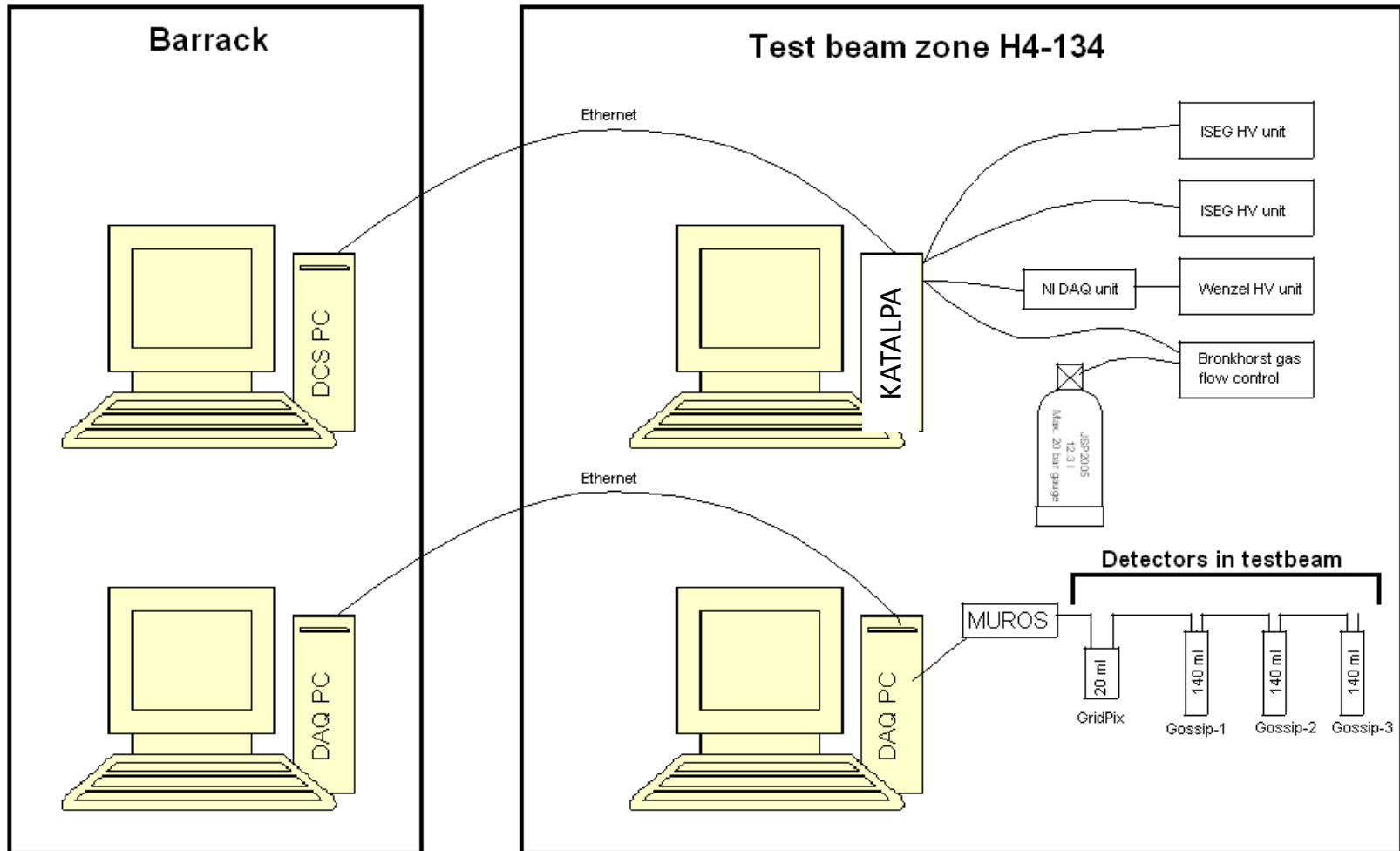


CLOSE GAS
CYLINDER
HERE

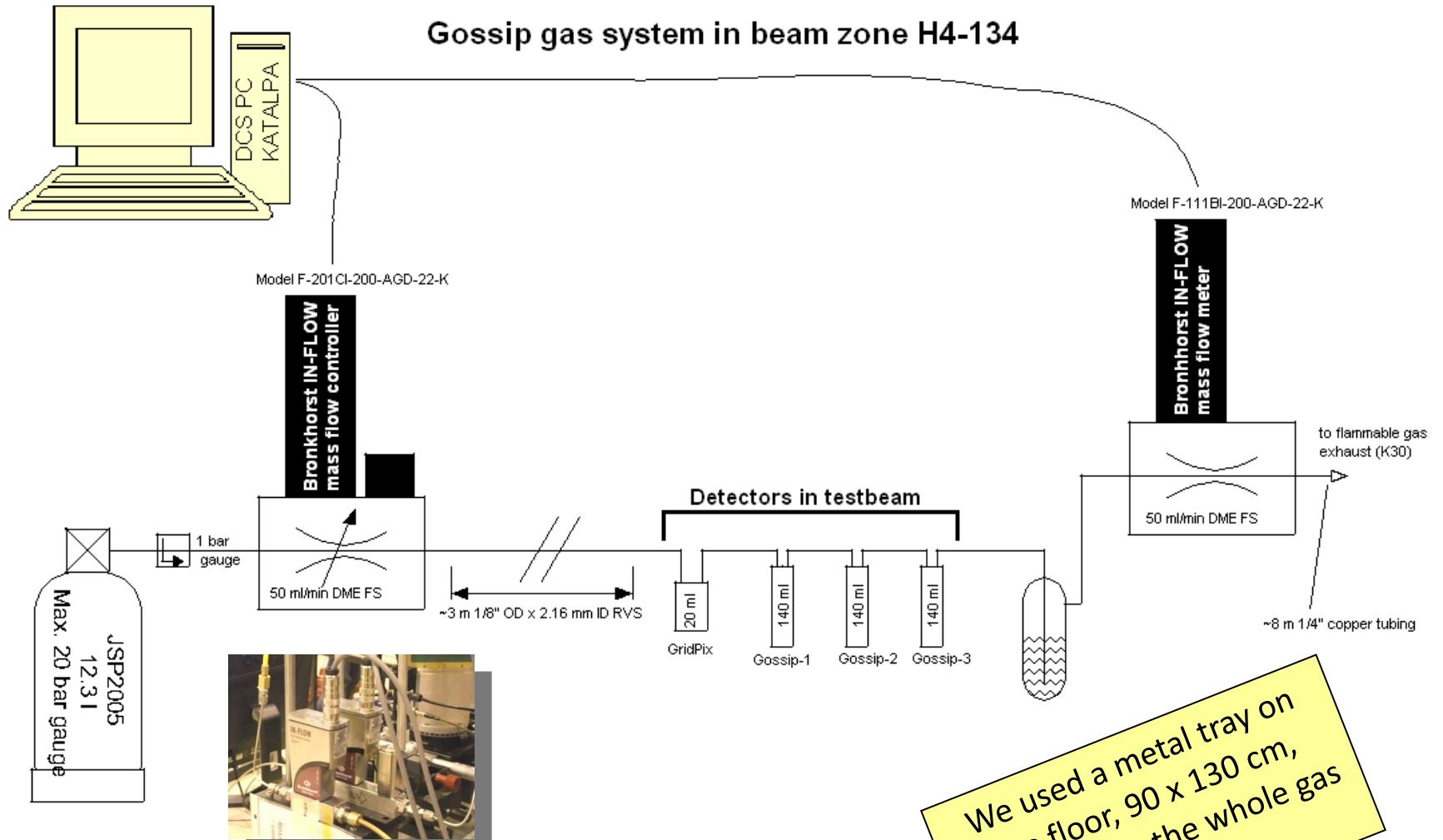


Completely remotely controlled

- Communication between barrack and experimental area by 2 Ethernet cables
- Using Remote Desktop



Gossip gas system in beam zone H4-134



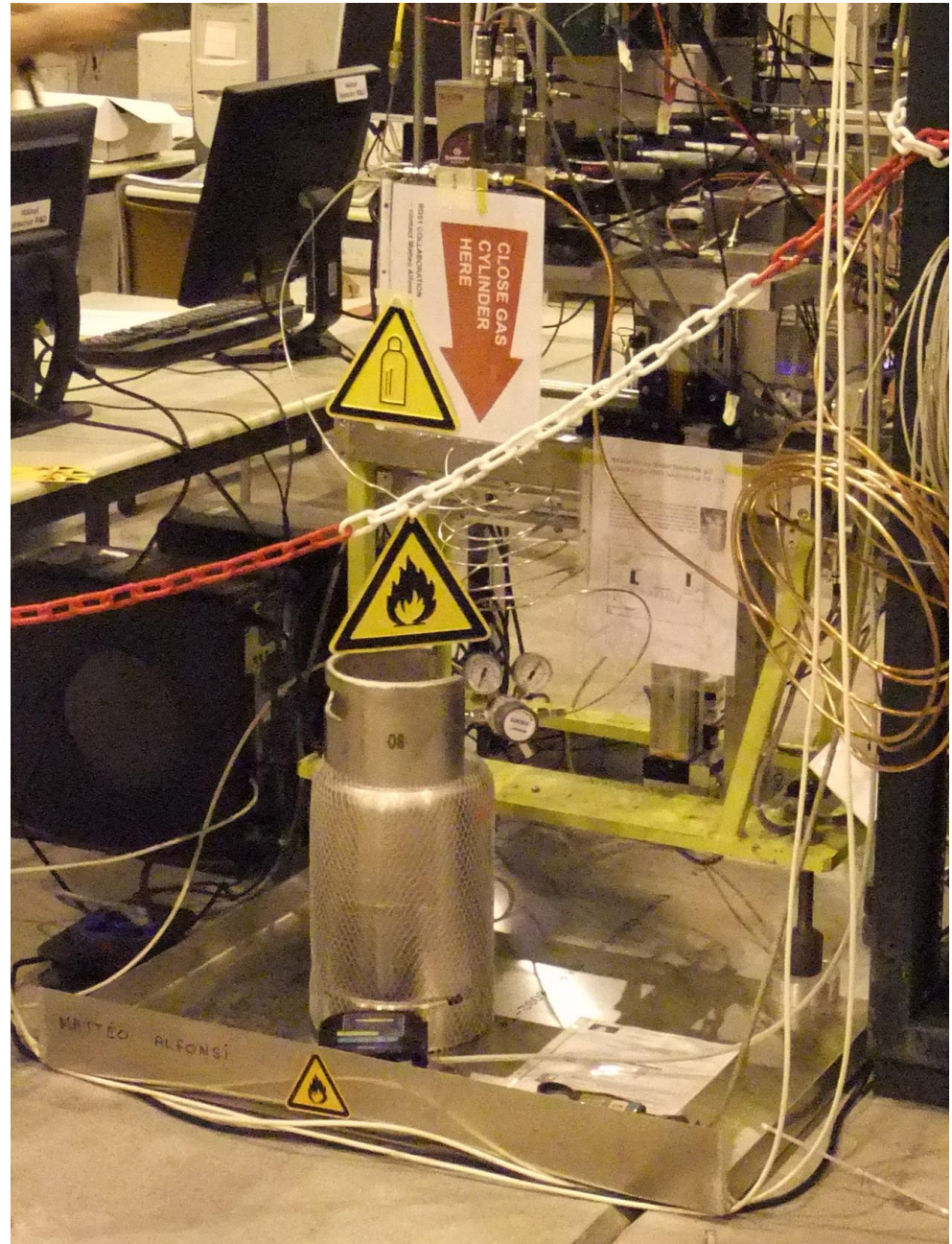
We used a metal tray on the floor, 90 x 130 cm, surrounding the whole gas system

Gas system Gossip test beam in H4-134

Fred Hartjes
Nikhef
2-8-2010

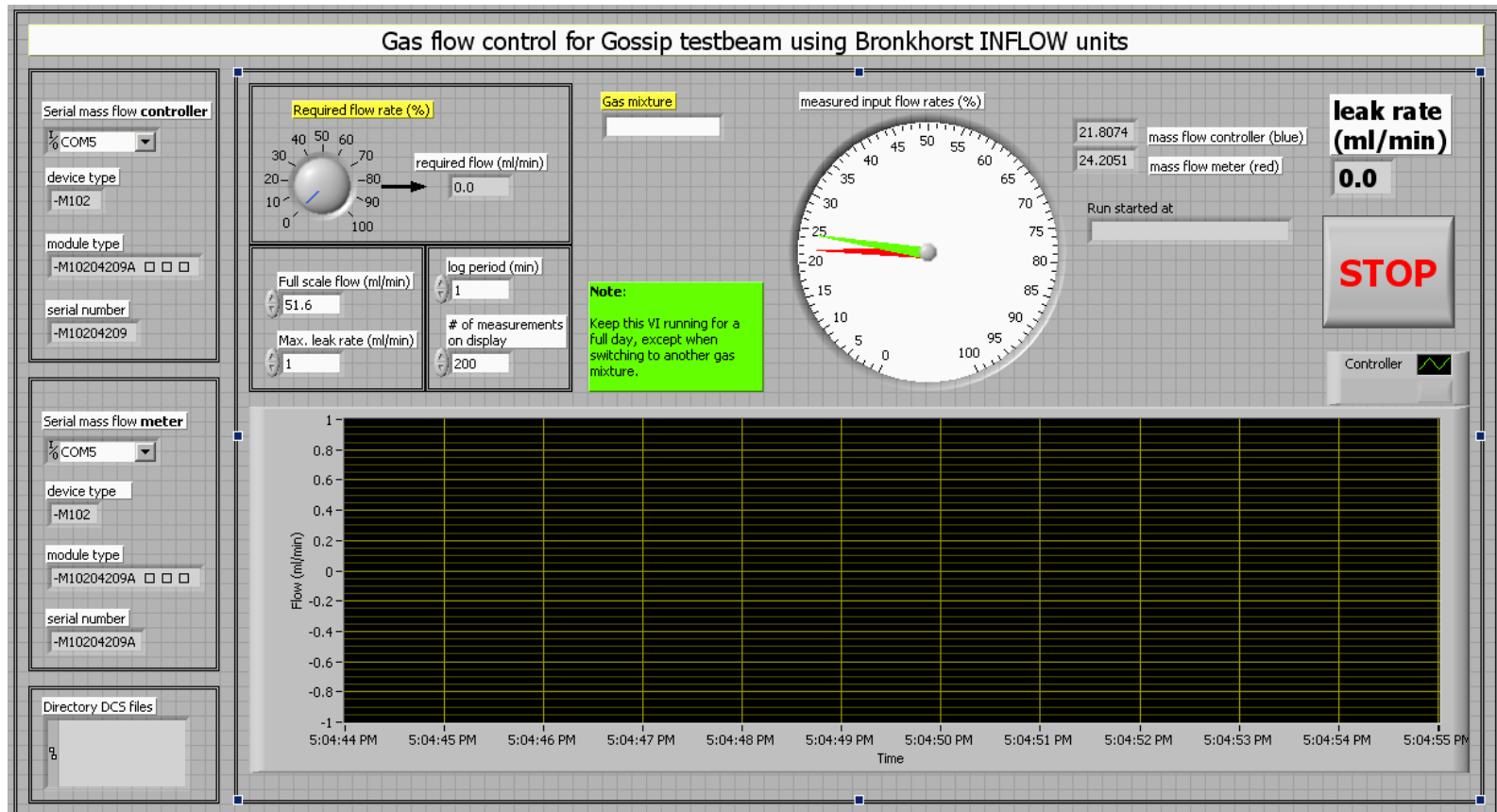
Special requirements for flammable gas

- Gas mixture from 120 l JSP gas bottle
- Whole gas system including bottle contained in leak tray
- Checking gas leaks by measuring deficit between input flow and exhaust flow
- Connected to flammable gas exhaust line



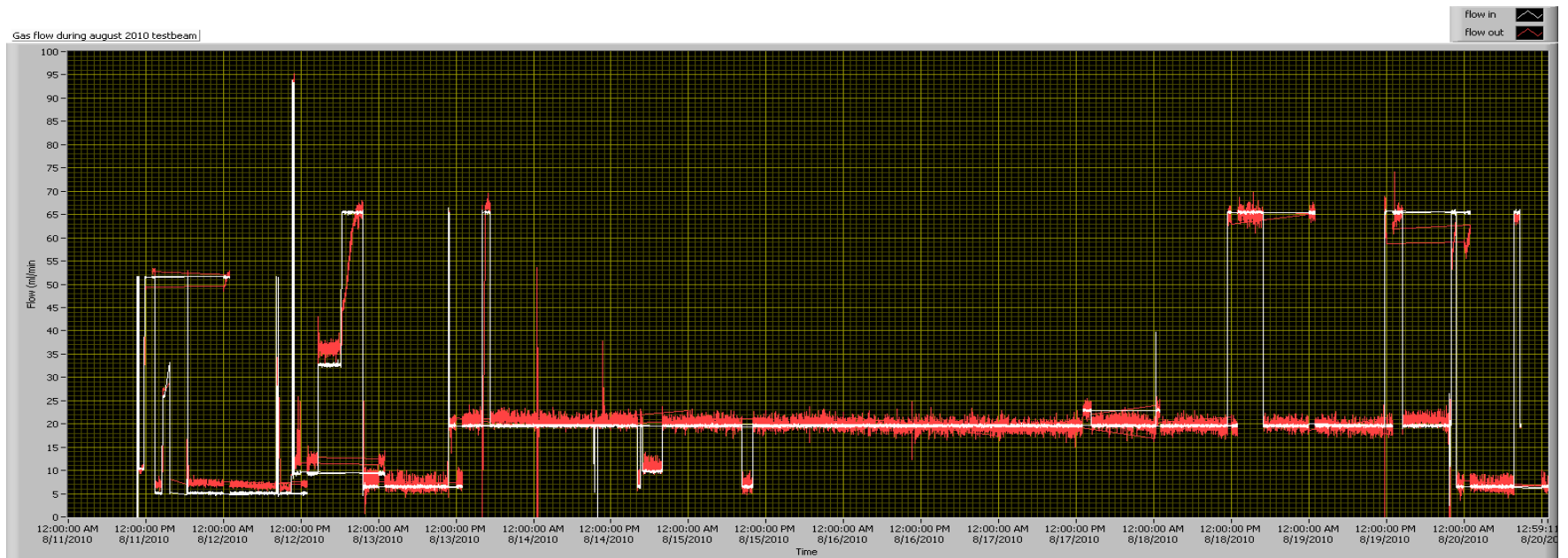
LabView controlled gas system

- Operation
 - Flow logged each minute
 - Alarm at leak rate > 3 ml/min
 - Shut off at integrated leak volume of 30 ml
- Gas flow set between 5 and 50 ml/min
 - Possible calibration error by factory (flow too low)



Gas flow during August testbeam

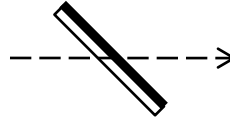
- White: inlet gas steam
- Red: exhaust gas stream
- Adjusted between 50 ml/min (purge) and 5 ml/min (standby)



What has been measured?

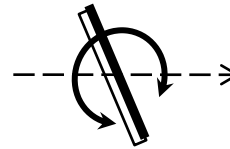
- Much data for Gossip under 45°

- 50k events
- Grid voltage scan from -510 to -620 V
- Mostly at field 2 kV/cm
- 2.8 k eV at 6 kV/cm

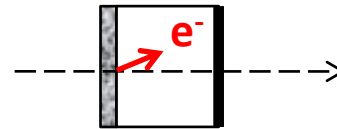


- Also 10k events under 4 other angles

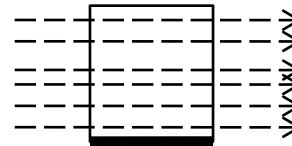
- 0; 5.75; 11.5 and 23°
- Both at drift field of 2 and 6 kV/cm



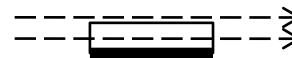
- 25k events with secondary emission detector



- 44k events with tracks in GridPix under 90°

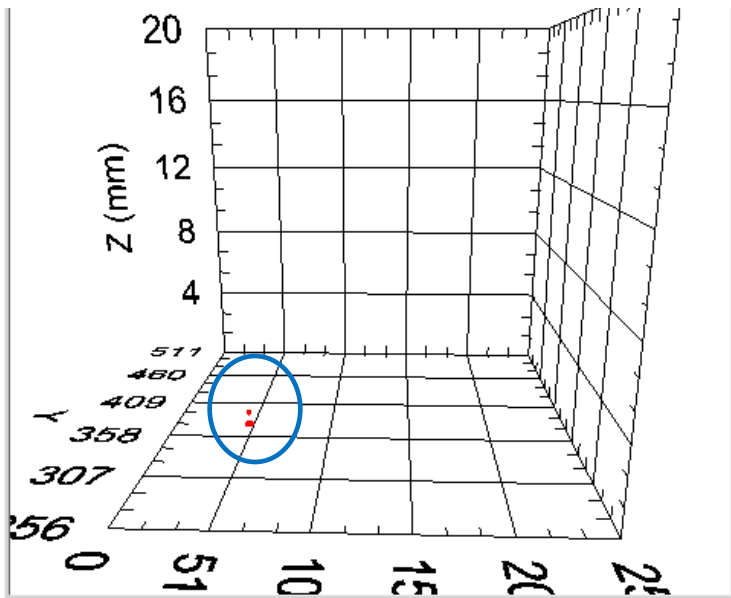


- 5k events with parallel tracks in Gossip

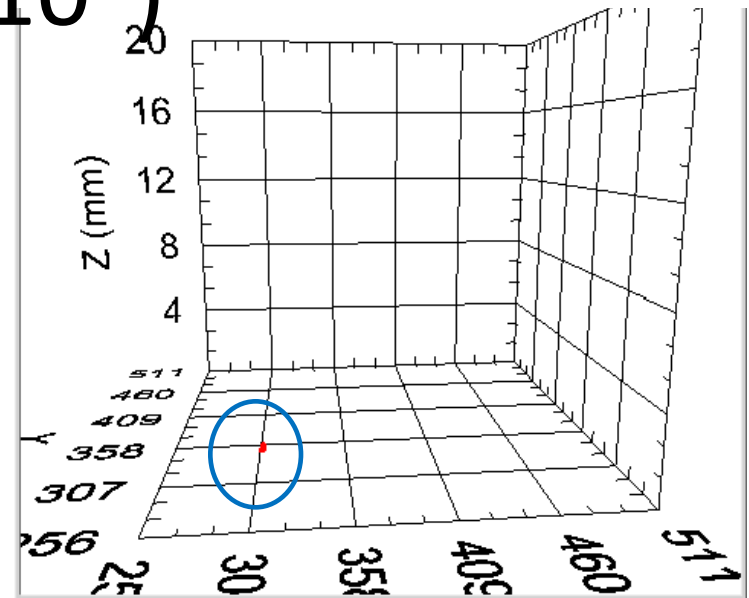


Typical event in an 4 detectors (angle

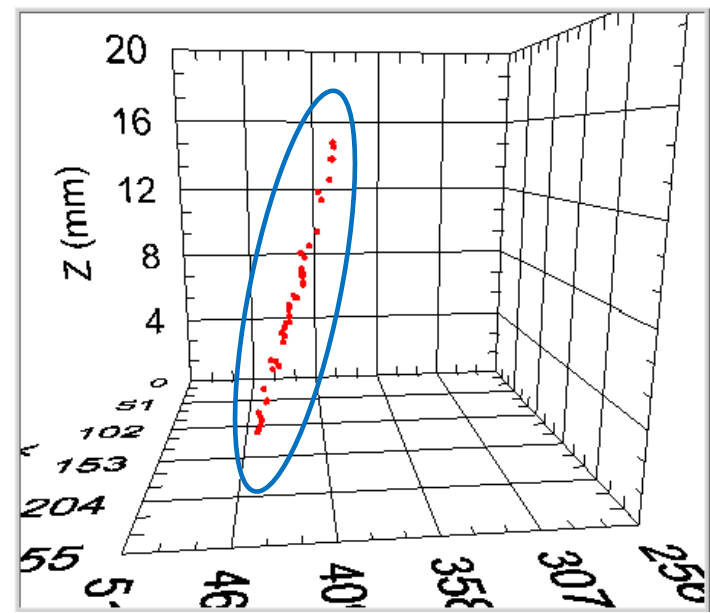
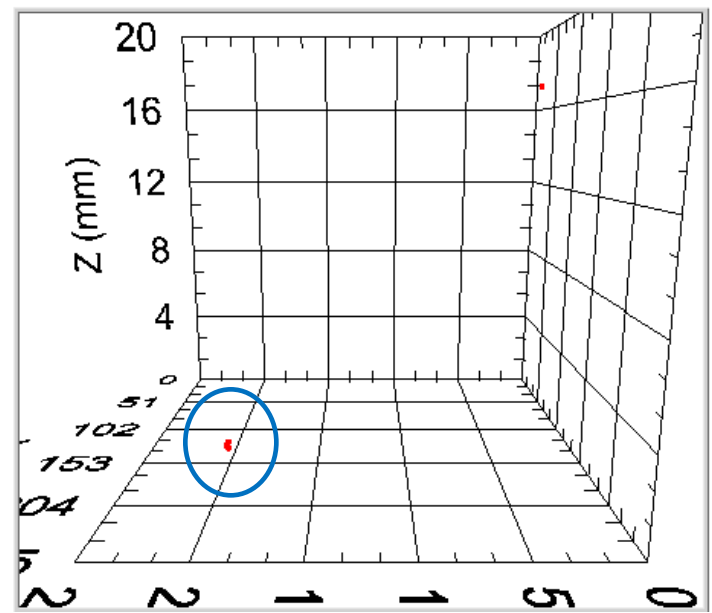
10°)



Position 3



DICE

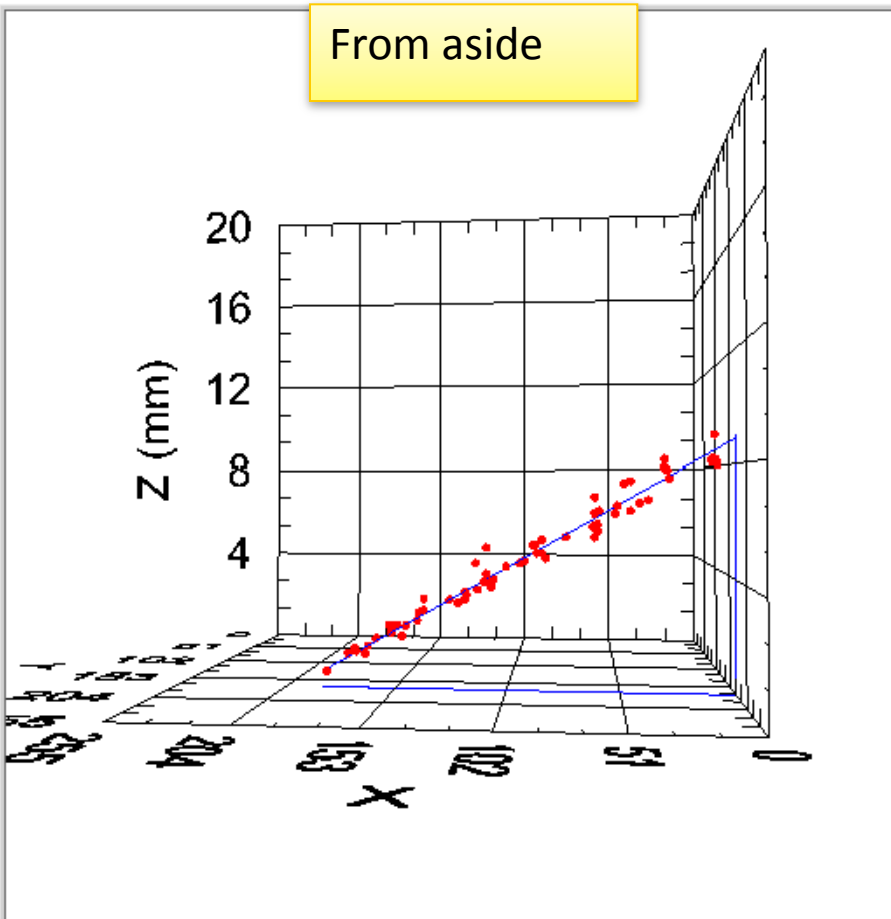


Typical event in GridPix under 45°

- Very small diffusion but big time slewing

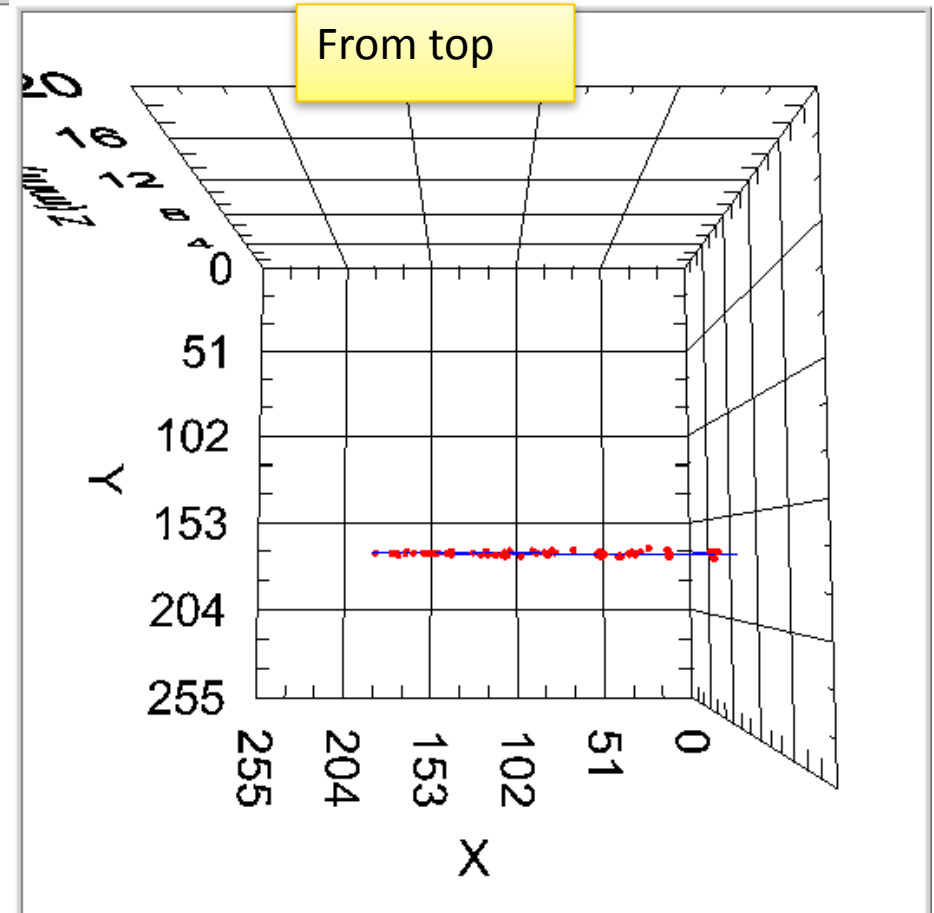
TimePix

From aside



TimePix

From top



Data analysis

- Just started, only preliminary results are given here
- **Cuts** on each detector individually
- Fitted tracks
 - Slope
 - Intercept Z=0
 - Fit residue
- Pixel hits
 - Fiducial area
 - Maximum drift time

Fit Cut Matrix

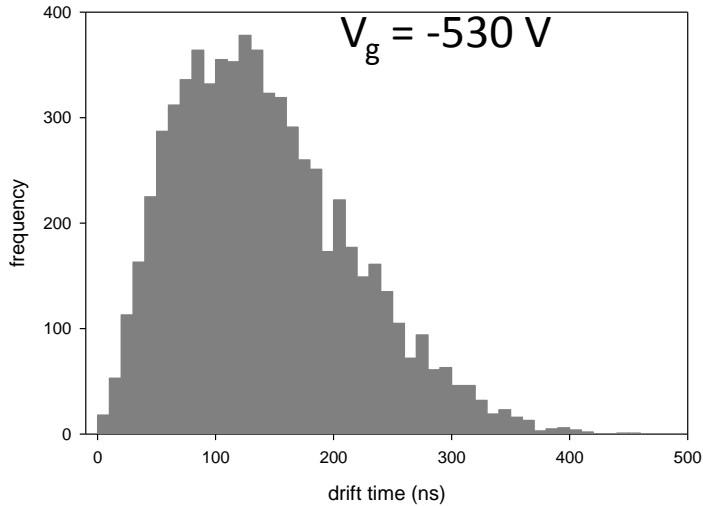
0	1	1	1	-0.15	Max Z-X slope
1	-1	-1	-1	-0.25	Min Z-X slope
2	1	1	1	1	Z-X slope enable
3	0	0	0	0.04	Max Z-Y slope
4	0	0	0	-0.02	Min Z-Y slope
5	0	0	0	1	Z-Y slope enable
6	0	0	0	13	Max X intercept (Z=0, mm)
7	0	0	0	5	Min X intercept (Z=0, mm)
8	0	0	0	1	X intercept enable
9	0	0	0	10	Max Y intercept (Z=0, mm)
10	0	0	0	2	Min Y intercept (Z=0, mm)
11	0	0	0	1	Y intercept enable
12	0	0	0	1	Max X-slope residue
13	0	0	0	1	X slope residue enable
14	0	0	0	0.01	Max Y-slope residue
15	0	0	0	1	Y slope residue enable
	Position 1	Position 2	Position 3	DICE	

Pixel Cut Matrix

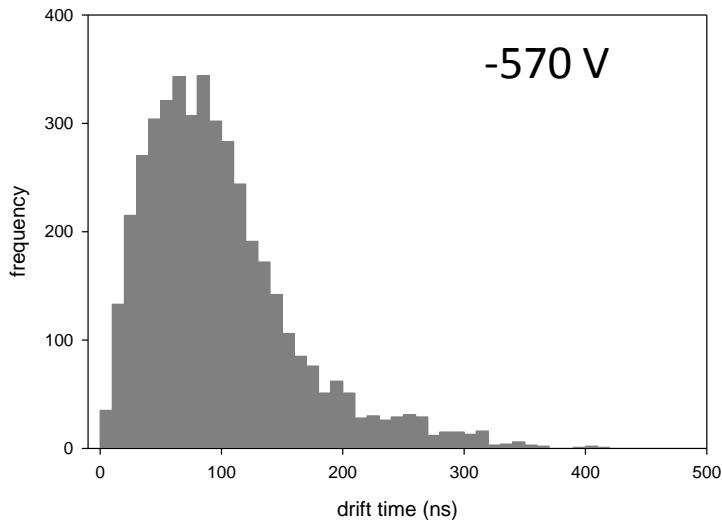
0	245	245	245	245	X upper limit (pix)
1	10	10	10	10	X lower limit (pix)
2	1	1	1	1	X fid enable
3	245	245	245	245	Y upper limit (pix)
4	10	10	10	10	Y lower limit (pix)
5	1	1	1	1	Y fid enable
6	2	2	2	10	# of hits
7	0	0	0	0	# of hits enable
8	150	150	130	0	Max drift time (ns)
9	1	1	1	0	Max drift time enable
	Position 1	Position 2	Position 3	DICE	(1: cut; 2: coerce)

Drift time spectrum

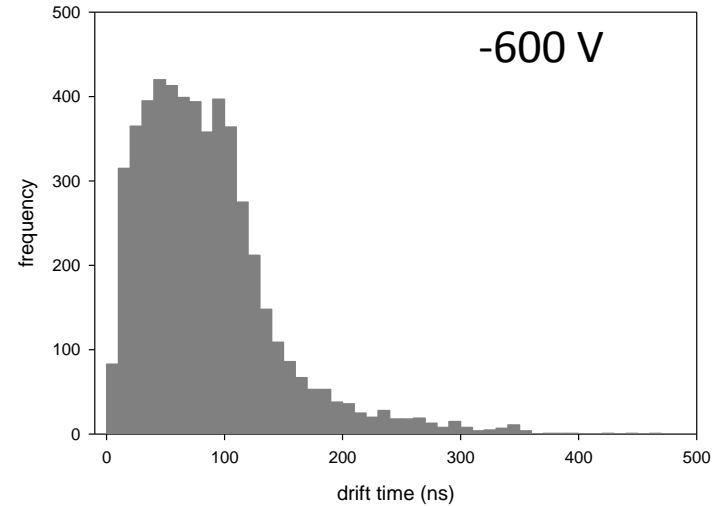
- TimePix suffering from time slewing
- Less dominant at high gain



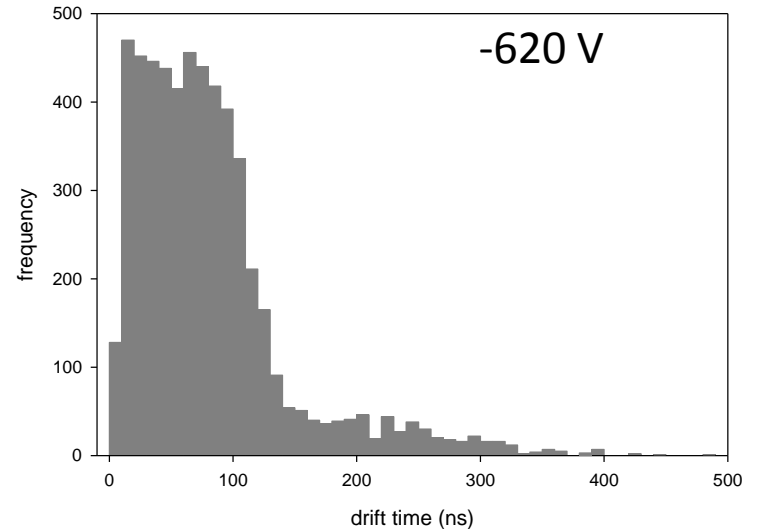
Drift time spectrum
 $V_g = 570$ V run 24



Drift time spectrum
 $V_g = 600$ V run 28

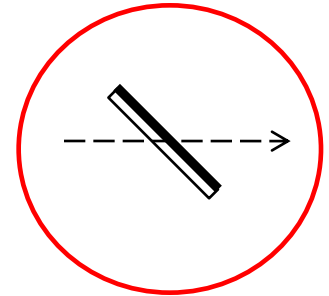
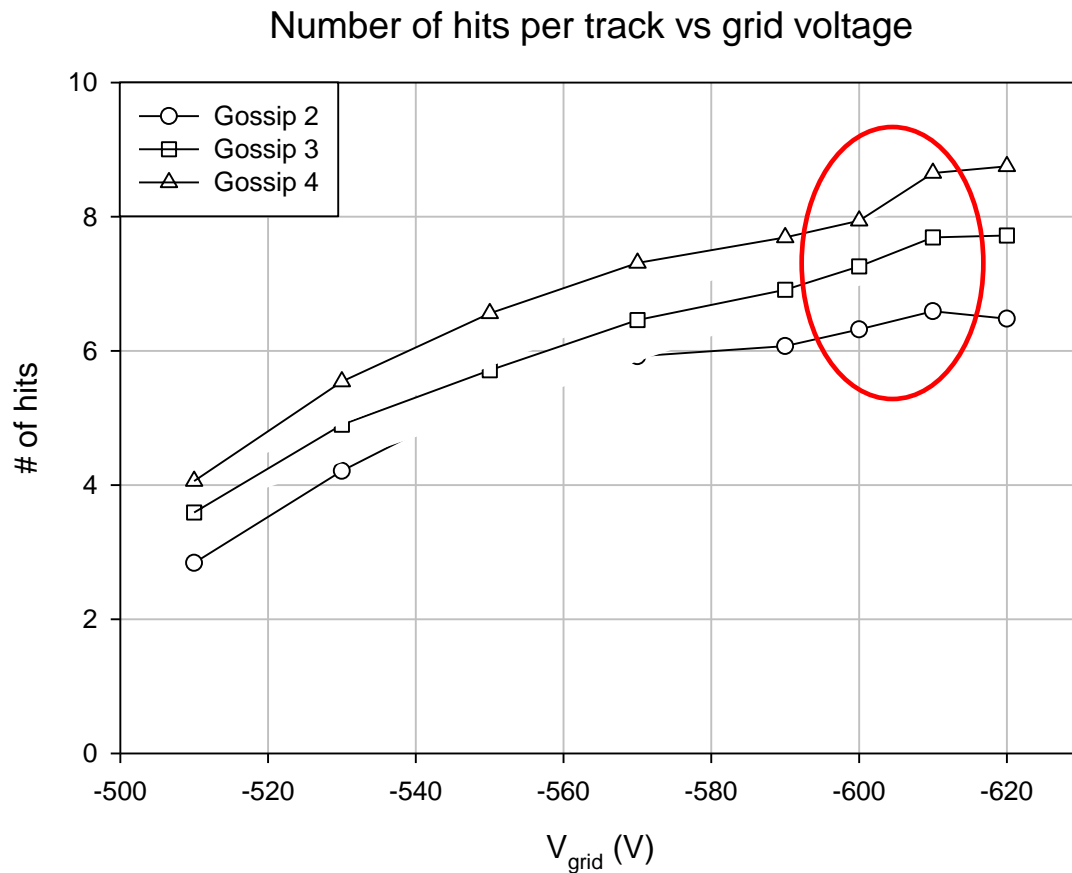


Drift time spectrum
 $V_g = 620$ V run 32



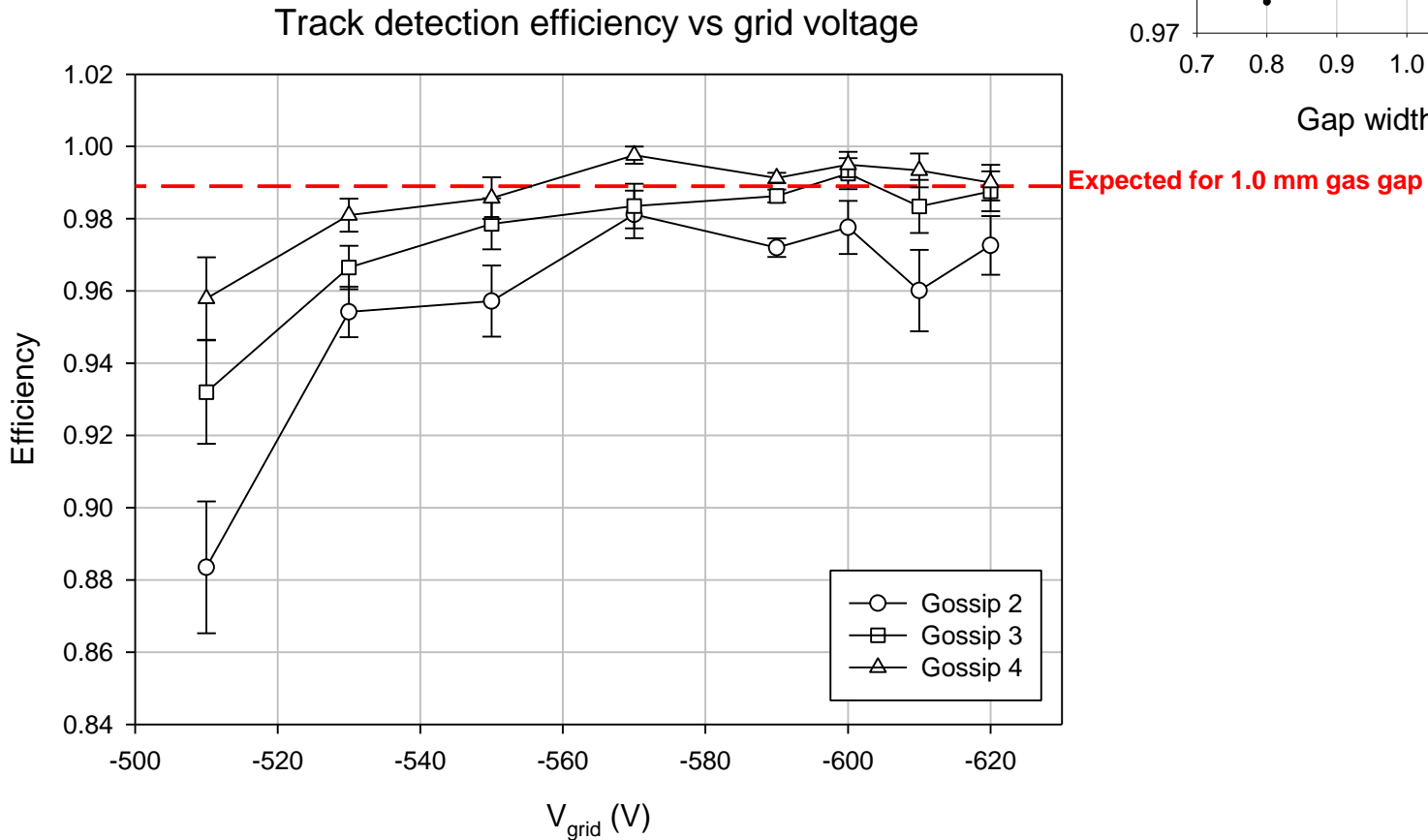
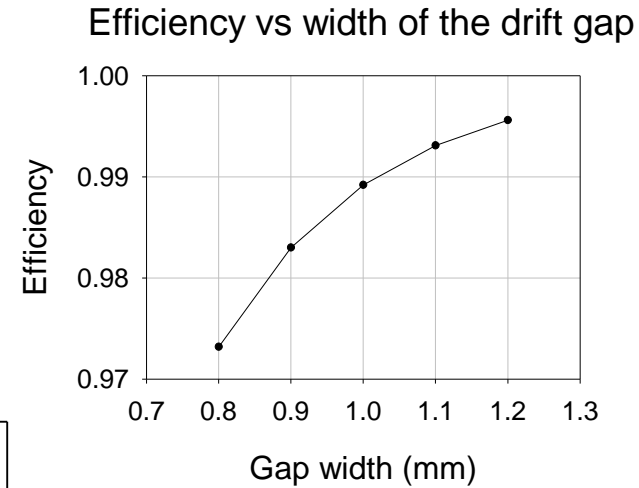
Number of hits per track in Gossip vs grid voltage

- Angle 45°
- Unexpected difference between the three Gossips
 - If Gas gap of Gossip 2 were 1.0 mm, then the gap of Gossip 4 should be 1.3 mm
- Jump in number of hits from -600 to -610



Track detection efficiency

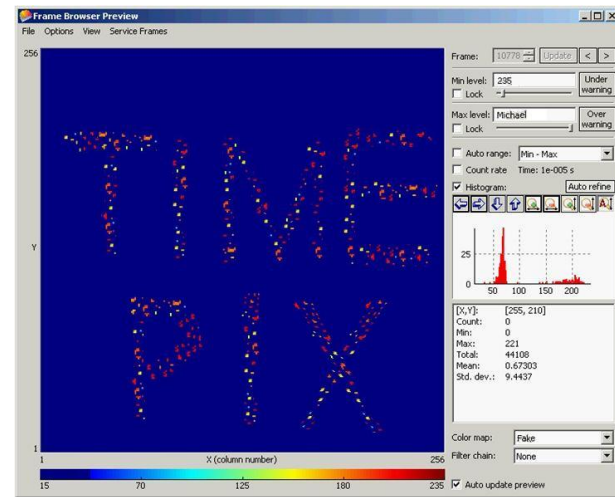
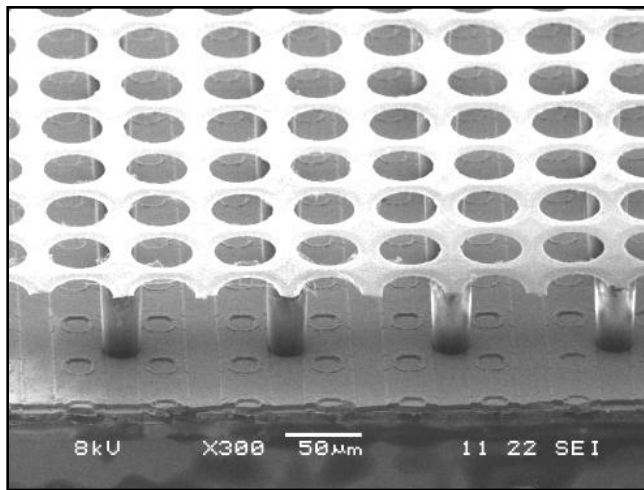
- Tracks selected by GridPix detector
- Completely flat plateau from ~ -570 V on
- Expected for 1.0 mm DME/CO₂: 98.9%



Concluding:

Detectors operating well, but some results not yet understood

- All three Gossips were operating reliably without any HV problem at high gain
- GridPix (mostly running at -560 V has less good gain, but probably still good single electron efficiency
- Infrastructure of remote control of HV and gas advantageous
 - May be modified when beam is on
 - Values permanently logged
- Data to determine position resolution and angular resolution for 5 difference angles of incidence
- Gossips have excellent track detection efficiency from -570 V on
- Jump in number of hits for V_{grid} going from -600 V to -610 V not yet understood
- Difference in number of hits between Gossip 2, 3 and 4 not understood
 - Difference confirmed by drift time spectrum
 - Metrology before testbeam showed difference in drift gap height of only 4%



Avalanche statistics and single electron counting with a Timepix-InGrid detector

Michael Lupberger

EUDET Annual Meeting

29.09-01.10.2010 DESY, Hamburg, Germany

Hardware Setup

Gas box, volume: 1,5 l

Source: Fe55, directly on cathode

Gas: ArIs0 95/5 (ArIs0 80/20, P10, CF4)

Readout: MUROS, 36MHz, Pixelman

Filter: > 10 Pixel per Frame

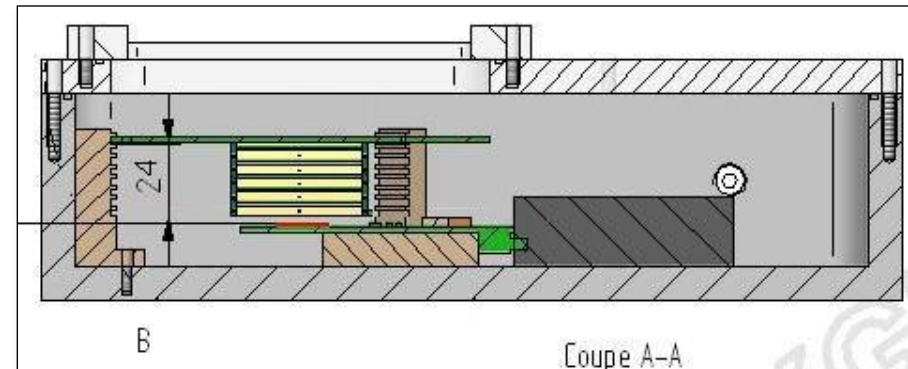
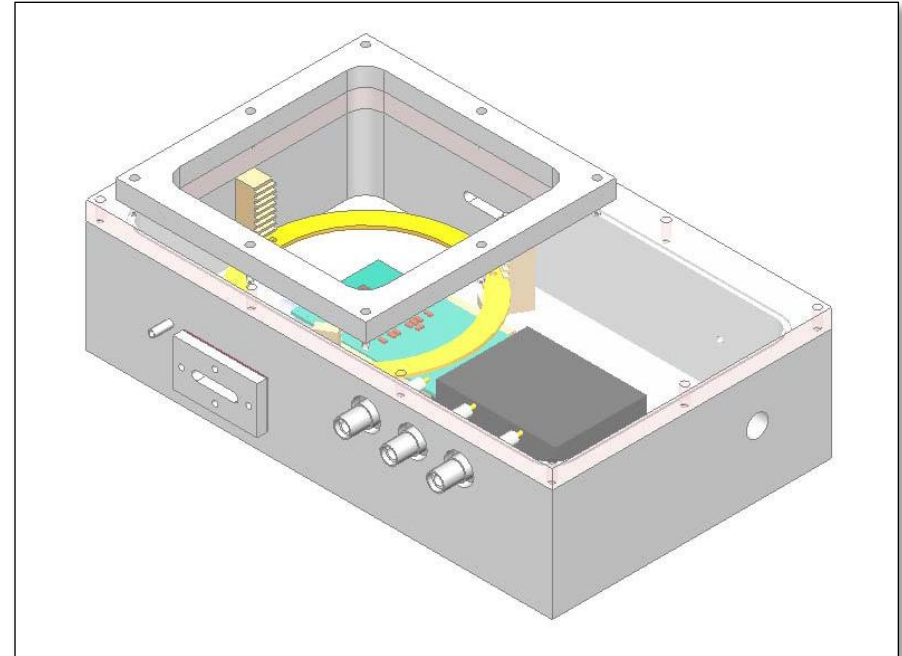
Drift distance: max. 2,4 cm

Amplification gap: 50 μ m

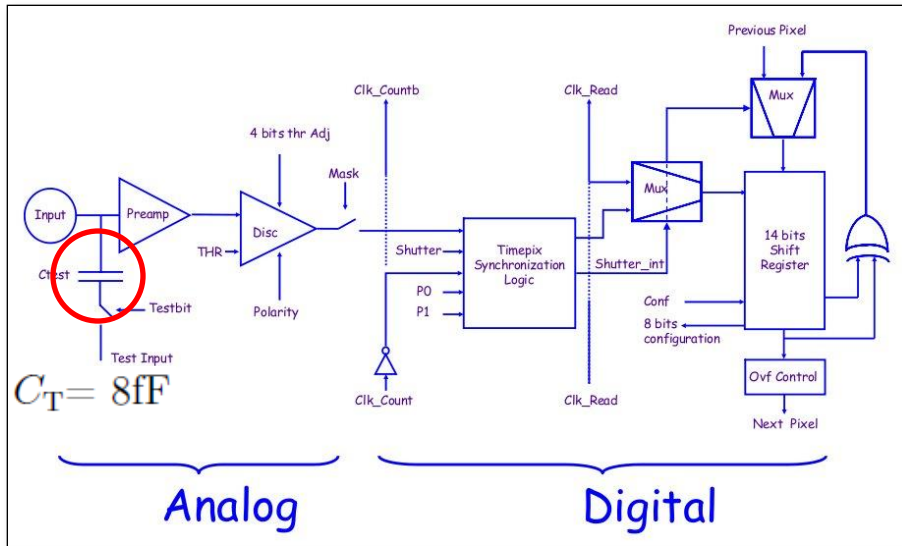
SiProt: 7 μ m

Field degrader

No anode plate around InGrid

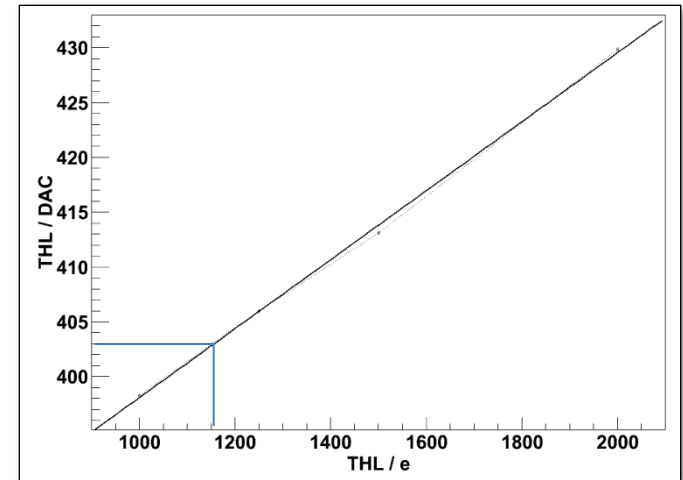


Hardware Calibration

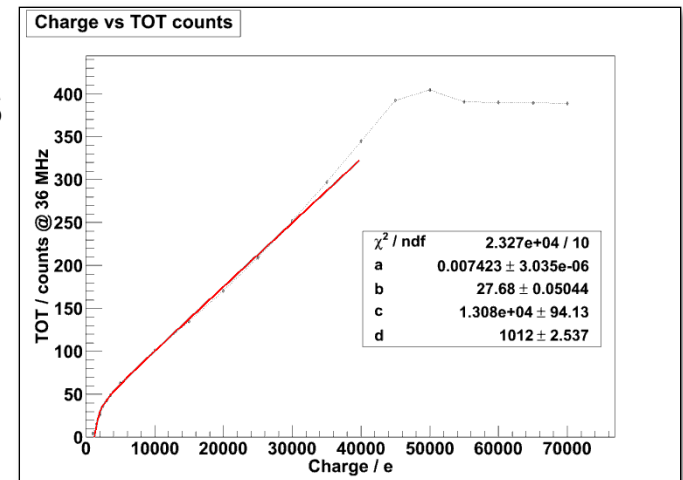


$$Q_{\text{inj}} [e^-] = 50 \cdot \Delta U_{\text{inj}} [\text{mV}] \quad Q_{\text{inj}} = C_T \cdot \Delta U_{\text{inj}}$$

Threshold DAC → #e- calibration



TOT → #e- calibration



Internal test pulses applied to each pixel via MUROS

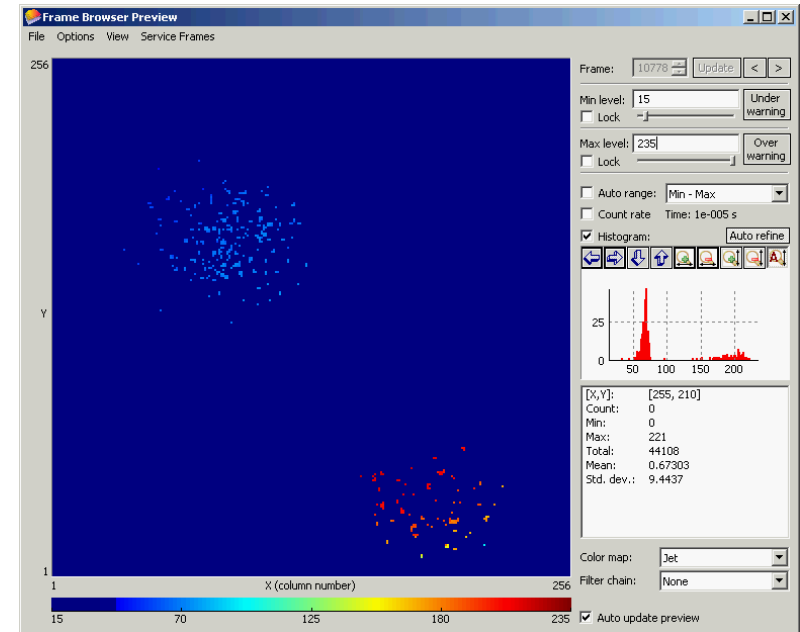
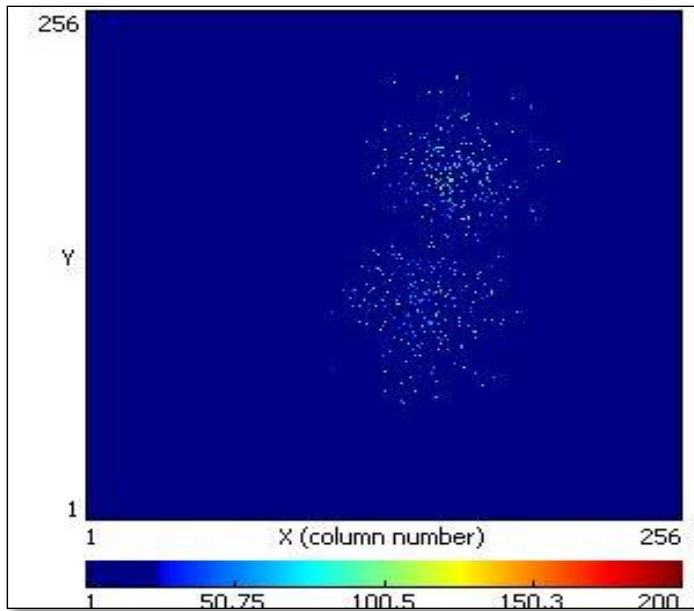
→ Known input charge into electronics

→ Threshold calibration

→ TOT calibration !Non linear for low charge

Software

Analysis code



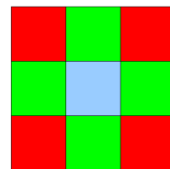
TOT Mode: 1. Check circularity of clouds

2. Check if cloud near centre

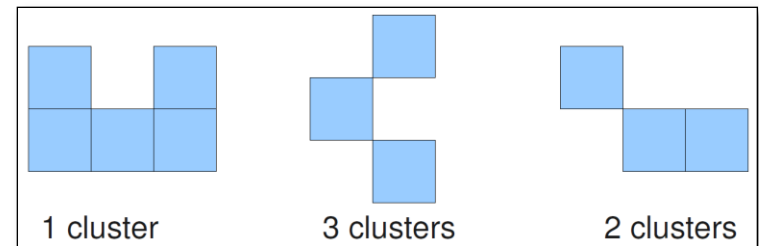
3. Check cloud size RMS

Find clusters (group attached pixels)

→ Histograms, Fits, TOT to electrons ...



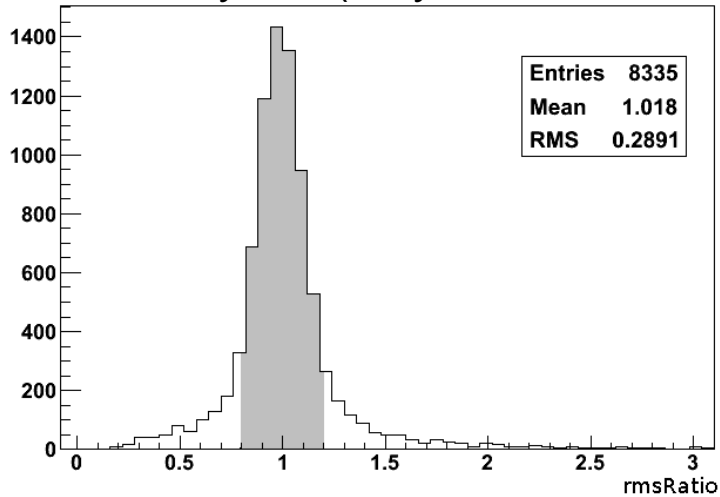
TIME Mode: 1. Separate clouds with time information



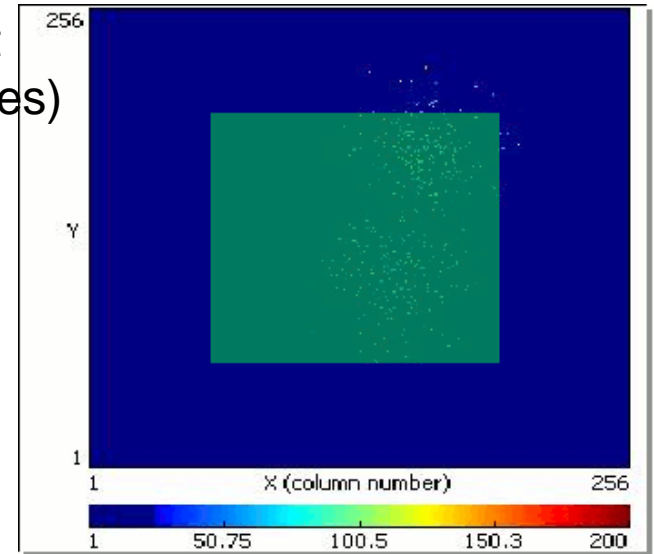
Software

Analysis code

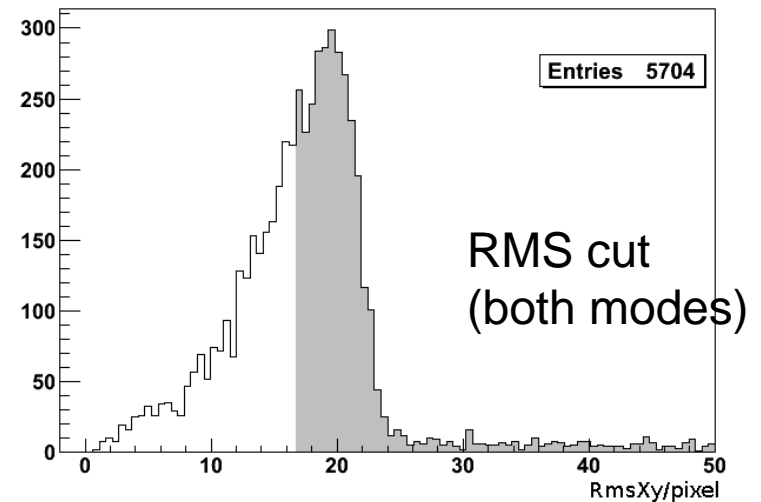
Circularity cut (only in TOT mode)



Centre cut
(both modes)



Physical interpretation of RMS cut:
Only take electron clouds, that have drifted a long distance:
⇒ Primary electrons separated by diffusion
Cut: RMS of 16.4 pixels on chip

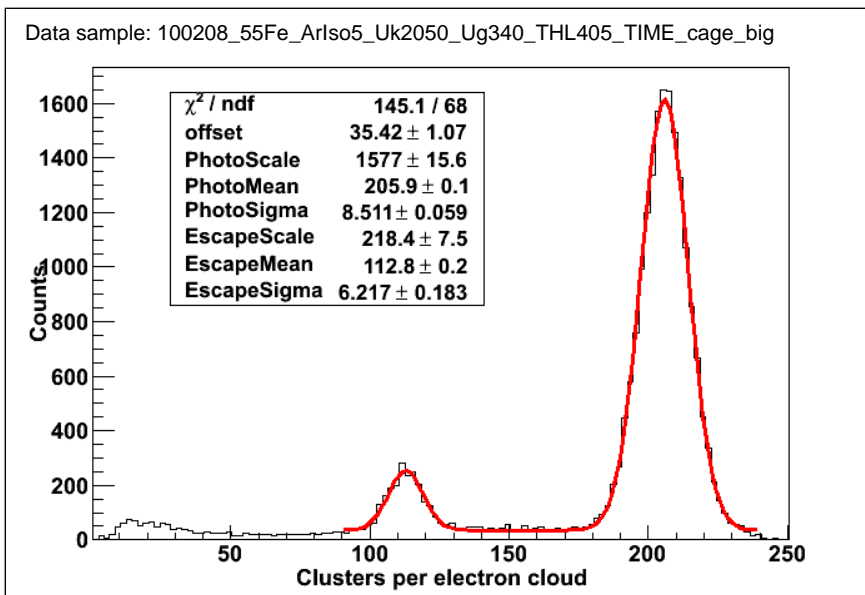


Fe55 Spectra

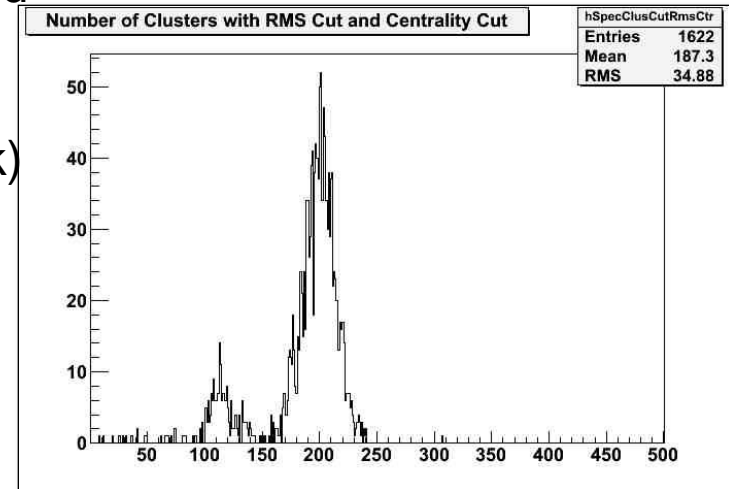
Resolution

- Count number of hit pixels/clusters per electron cloud
- Chromium foil to absorb K_{β} photons
- long term measurement and hard cut on cloud size
- best resolution achieved: 9,73% FWHM (photo peak)

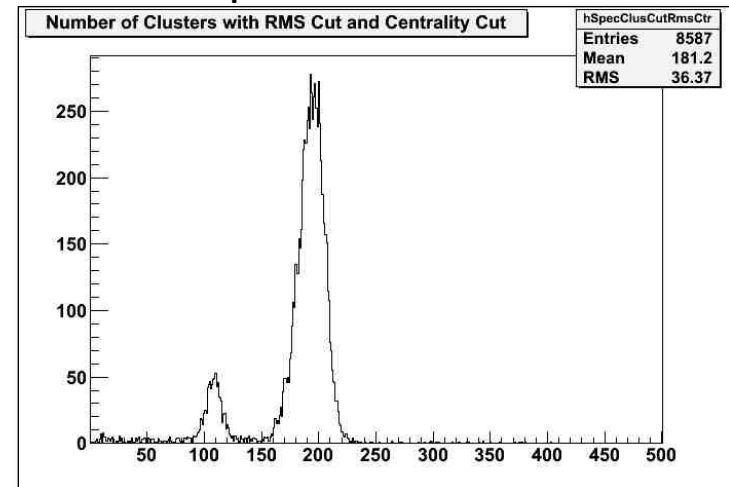
$$\left(\frac{\sigma_{N_d}}{N_d}\right)^2 = \frac{1}{N_p} \left[F + \frac{1 - \frac{N_d}{N_p}}{\frac{N_d}{N_p}} \right] [1] \Rightarrow F = 0.26 \text{ (upper limit)}$$



Fe55 spectrum without Cr foil



Fe55 spectrum with Cr foil



[1] Max Chefdeville, Development of Micromegas-like gaseous detectors using a pixel readout chip as collecting anode

Fe55 Spectra

Clusters in escape peak

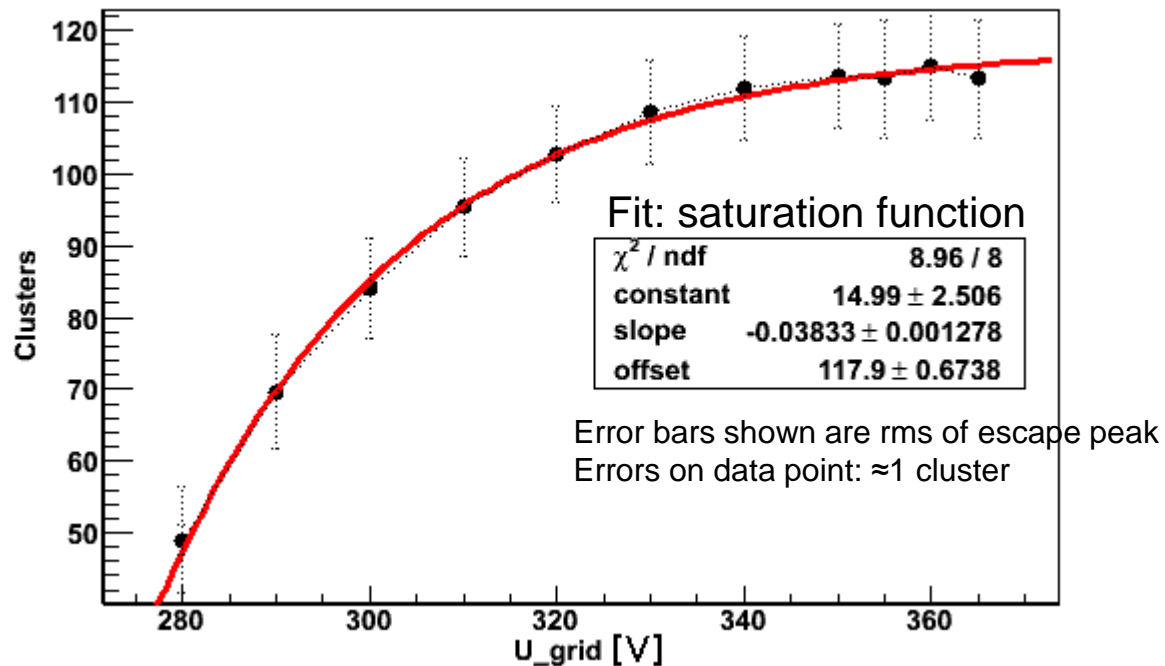
In ArIso 95/5:

- have a look on escape peak: less electrons, better separated by diffusion
- enough diffusion to arrive at plateau for escape peak: 117.9 ± 0.7 cluster
- most clusters include just one pixel (also some charge sharing)
⇒ 1 cluster \cong 1 primary electron at plateau
- applying harder cuts on RMS of electron cloud does not effect number of clusters

- escape peak at: 2,9 keV
- photo peak at: 5,899 keV

- ⇒ 236 ± 1 electrons expected in photo peak (max counted: 215 cluster)

Simulations (H.Schindler):
233 electrons in photo peak
(MAGBOLTZ)



TimeOverThreshold

TOT Spectra

Data sample:

$U_{\text{grid}}=330 \text{ V}$

Polya fit forced starting from 4000

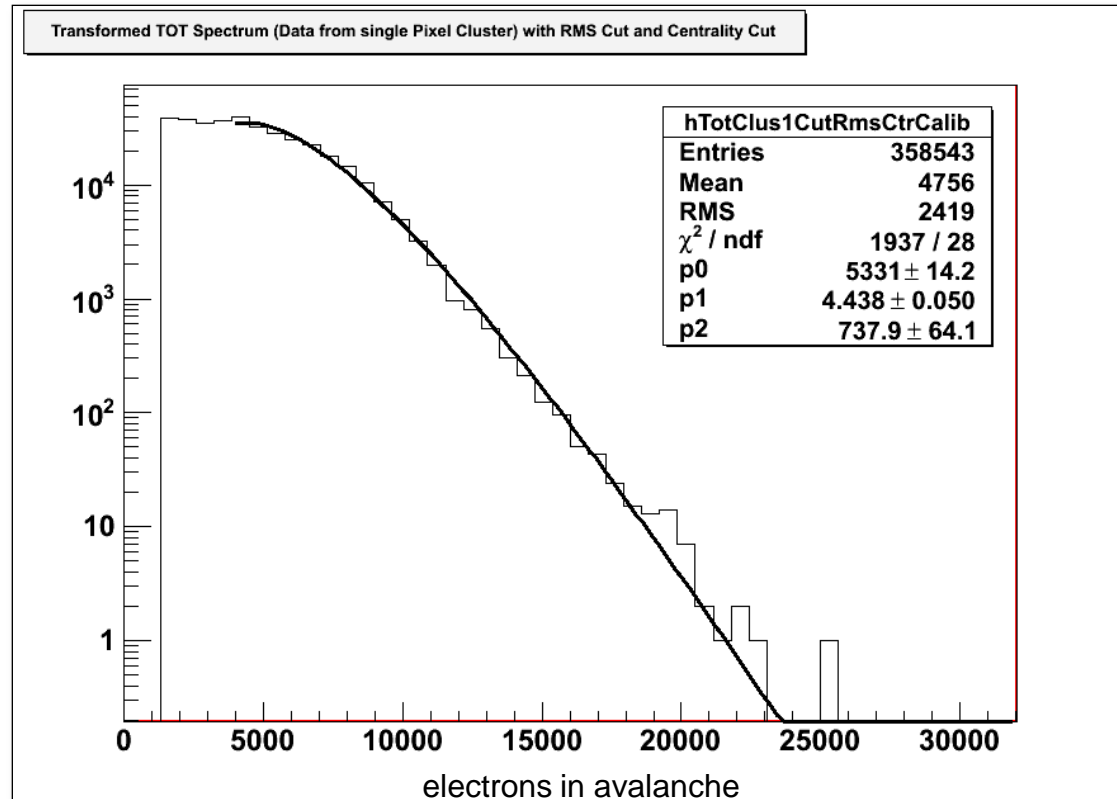
Advantages:

- TOT \rightarrow #e- calibration reliable

Disadvantages:

- few data points for low voltages

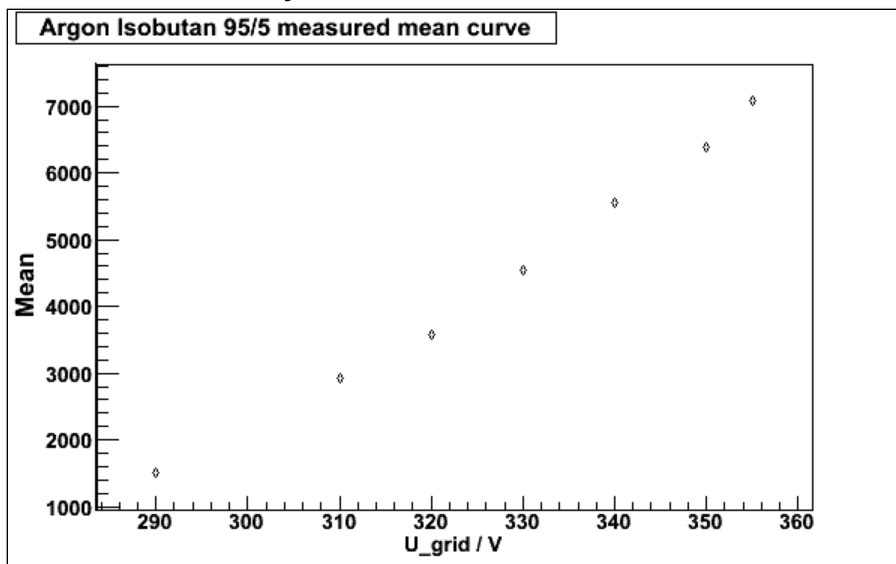
- just tail fit



TimeOverThreshold

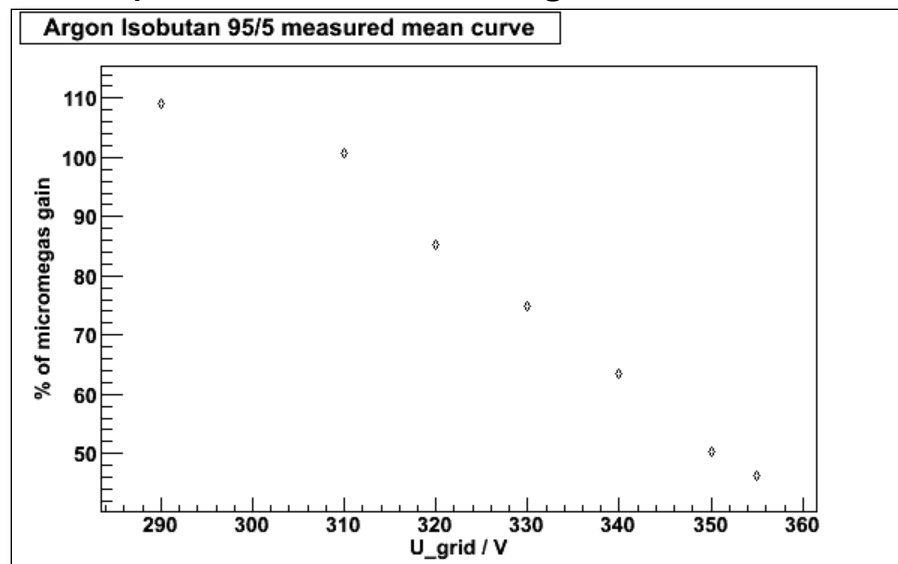
Gain Curve

Mean of Polya fit curve



- Use TOT → #e- calibration ⇒ gain curve
- Not exponential at all
- Very low gain at high voltages

Comparison to Micromegas results

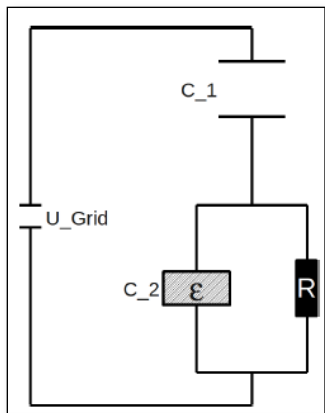


- Higher gain at lower voltages?
 - lowest gain ≈ threshold
 - inaccurate calibration for low gains
- Gain drop with voltage
 - difference to Micromegas:
SiProt

TimeOverThreshold

Influence of SiProt

Reason for lower gain: SiProt layer over anode. Look on single Pixel:
 SiProt acts as capacitor that charges with avalanches and discharges over high resistance



$$\frac{dQ}{dt} = Gf - \frac{Q}{RC}$$

$$G[C](U_{Si}) = e \exp(A + B \times \Delta U)$$

$$\Delta U = U_{grid} - U_{Si}$$

$$\frac{U_{Si}(t \rightarrow \infty)}{R} = G(U_{Si}(t \rightarrow \infty)) f \Rightarrow \frac{U_{Si}(t \rightarrow \infty)}{R f e} = \exp(A + B \times (U_{grid} - U_{Si}(t \rightarrow \infty)))$$

f = avalanche frequency, Q=C·U

G = number of electrons per avalanche

R = resistance of SiProt

C = capacitance of SiProt

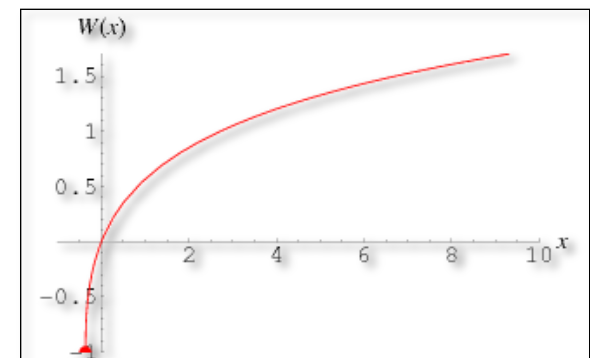
$$U_{Si}(t \rightarrow \infty) = \frac{W(B R f e \exp(A + B \times U_{grid}))}{B}$$

$$\tau = RC = \epsilon_0 \rho \epsilon$$

	a-Si:H	Si ₃ N ₄
$\rho/[\Omega\text{cm}]$	10 ¹¹ [2]	10 ¹⁴ [3]
ϵ	11.8 [1]	7.5 [3]

$$\Rightarrow \tau \approx 1 \text{ min}$$

W: Lambert W-function



[1] S. C. Deane and M. J. Powell, Field-effect conductance in amorphous silicon thin-film transistors with a defect pool density of states, Journal of applied physics 1993, vol. 74, no11, pp. 6655-6666

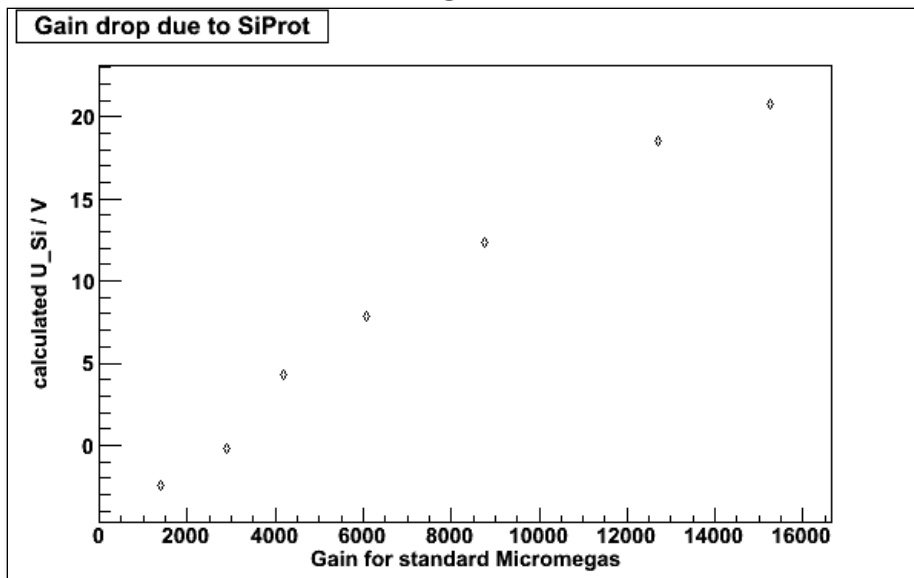
[2] M.A. Chefdeville, Development of micromegas-like gaseous detectors using a pixel readout chip as collecting anode, Univ. of Twente, January 2009

[3] <http://www.siliconfareast.com/sio2si3n4.htm>

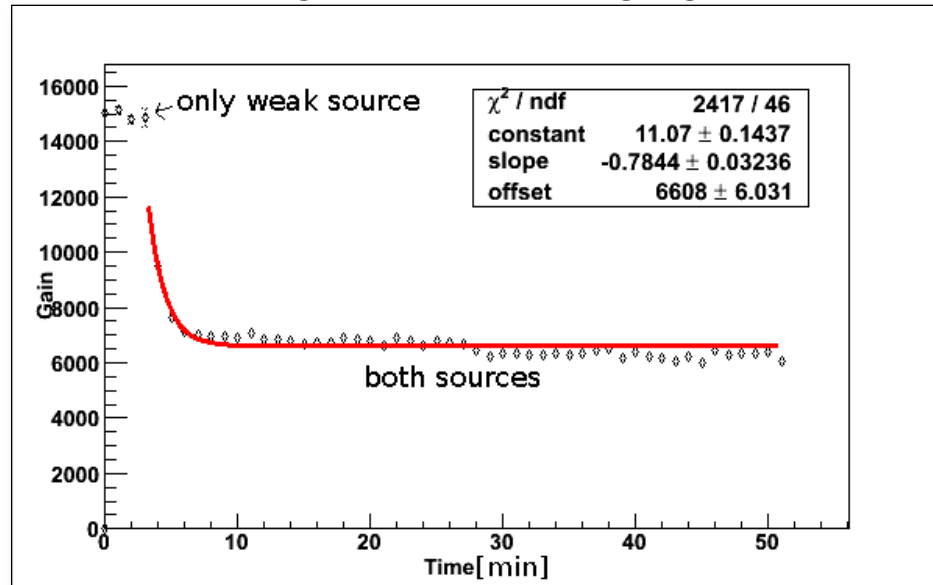
TimeOverThreshold

Influence of SiProt

Calculation of voltage on SiProt surface



Example for gain drop (charging of SiProt)



$$G = \exp(A + B \cdot U)$$

$$\text{mean} = G_{\text{measured}} = \exp(A + B \cdot \Delta U)$$

$$\Rightarrow \Delta U = \frac{\ln(\text{mean}) - A}{B}$$

$$U_{\text{Si}} = U - \Delta U \quad U_{\text{Si}} = \frac{W(B \cdot f \cdot R \cdot G)}{B}$$

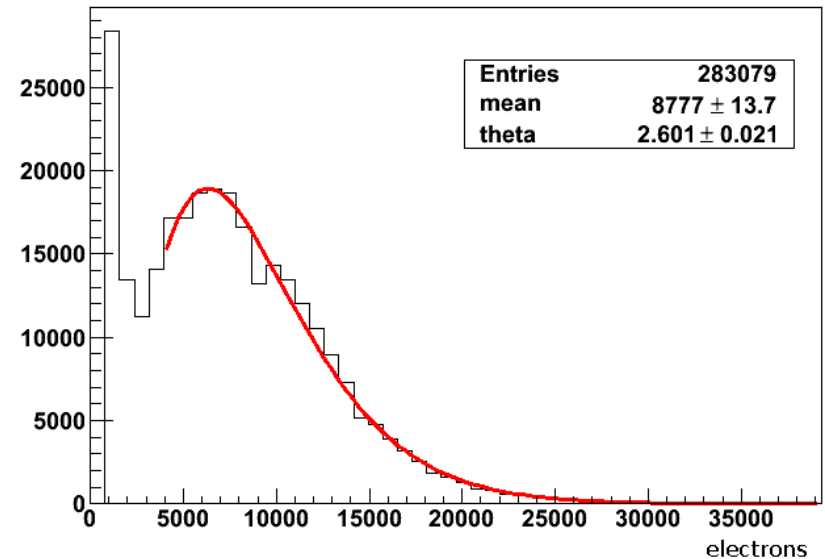
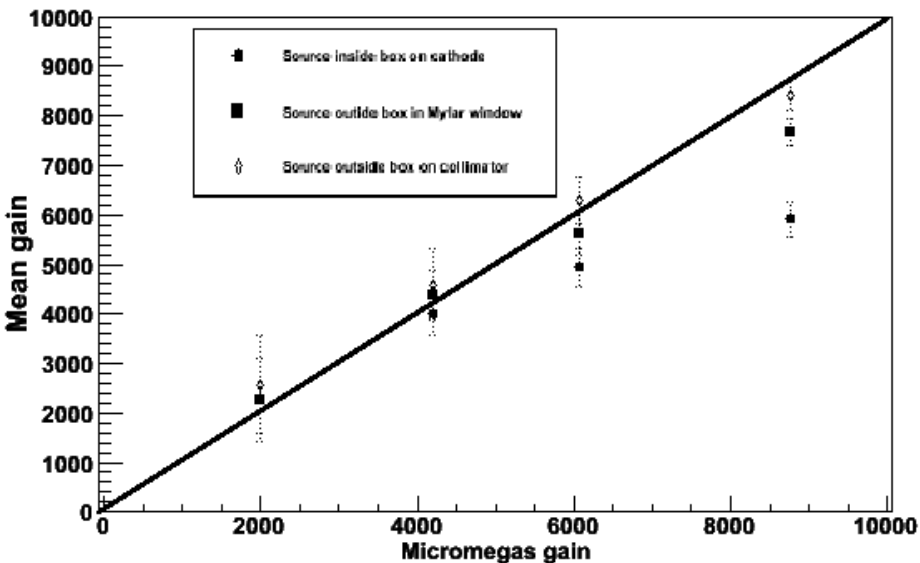
Put on second, stronger source during measurements:

Gain drop from 15000 to 6600

with $\tau = 1.27 \pm 0.05$ min

TimeOverThreshold

Low rate measurements



- Place source further away from detector
- > inside detector (high rate)
- > outside detector box (low rate)
- > outside detector box + collimator (highest rate)

- Measurement at lowest rate
- high gain
- noise visible, as acq. time needs to be longer
- $\Theta = 2.6$

InGrid gain approaches Micromegas gain

Combined Measurement

Detection Efficiency

Comparison of theory and measurements assuming Polya distribution
 Combine gain and primary electron measurements

From gain (TOT) measurements: Polya mean = gain

From primary electron (TIME) meas.:
 number of prim. electrons,
 117,9 electrons = 100 % det. Eff.

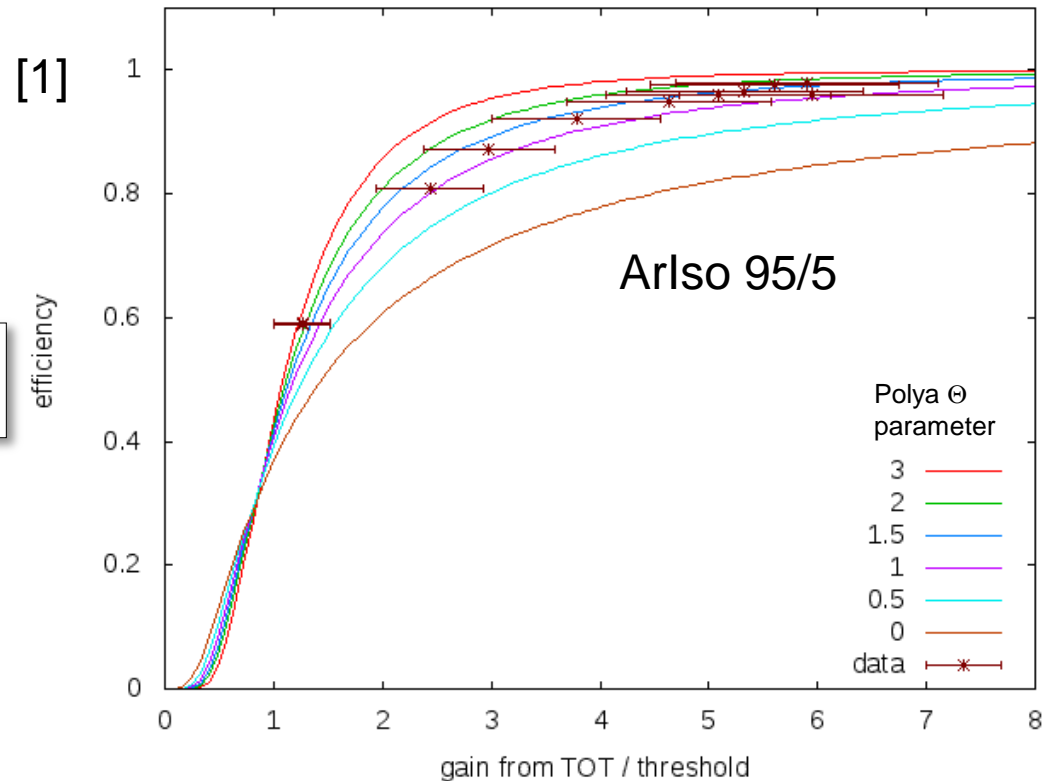
Detection efficiency:

$$\kappa(m, G, t) = \int_t^\infty \frac{m^m}{\Gamma(m)} \frac{1}{G} \left(\frac{g}{G}\right)^{m-1} \exp\left(-m\frac{g}{G}\right) dg$$

$$m = \Theta + 1$$

Threshold: $t = 1150$ electrons

$$\Rightarrow 0.5 < \Theta < 2$$



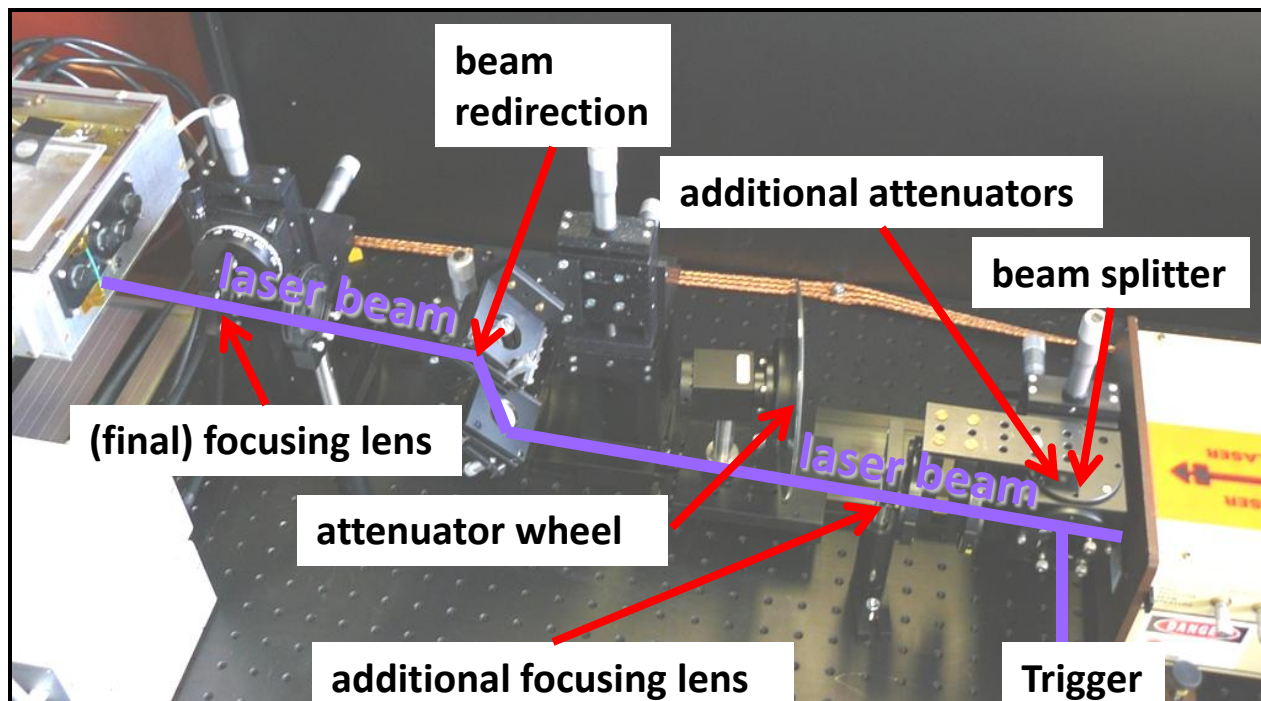
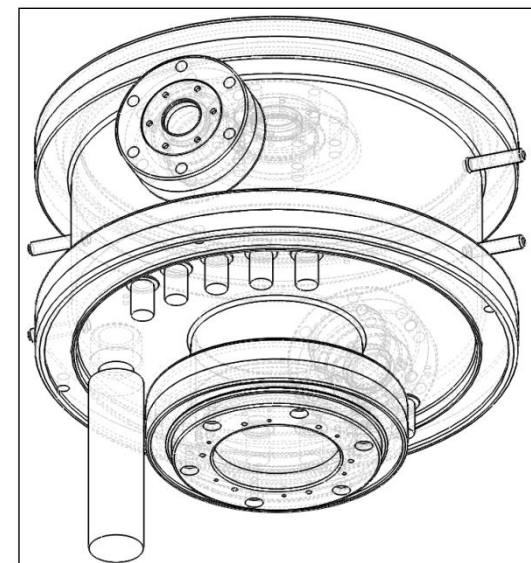
[1] Max Chefdeville, Development of Micromegas-like gaseous detectors using a pixel readout chip as collecting anode

TimeOverThreshold

Laser measurements

Quantitative measurements of gain – rate dependence

- Use (pulsed) LASER test bench and gas box in Freiburg
 - photo effect on cathode, few electrons
 - defined frequency and position of primary electrons
 - temperature und pressure registration

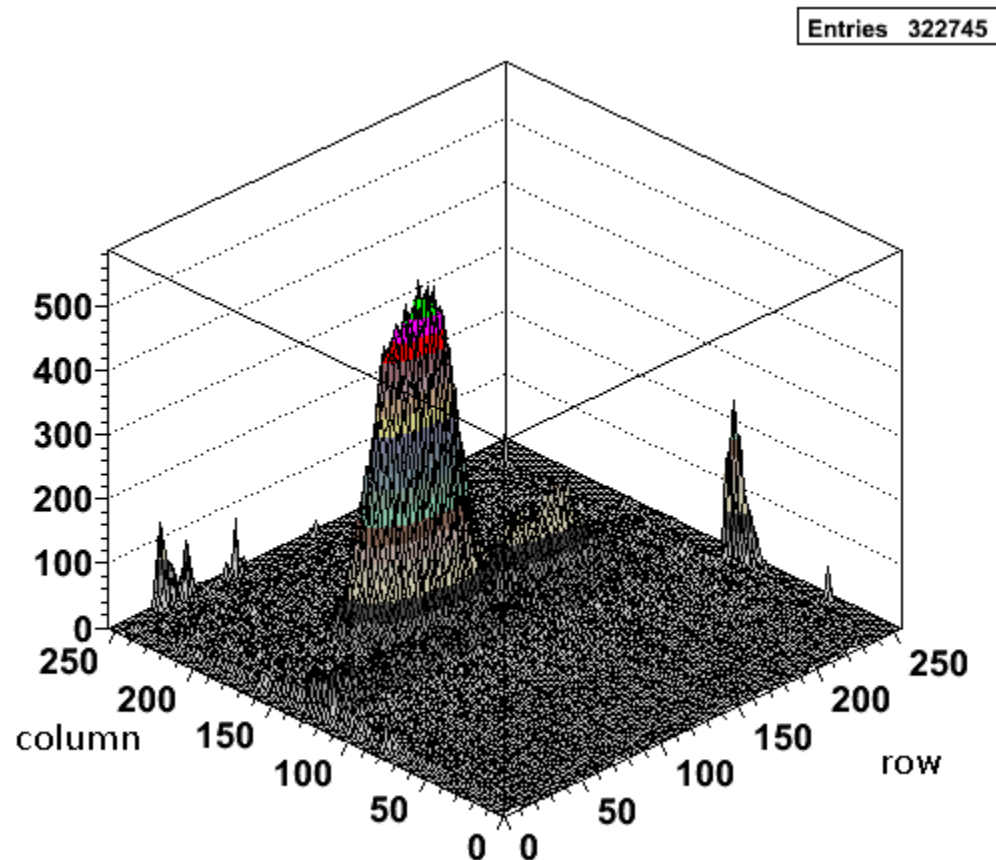
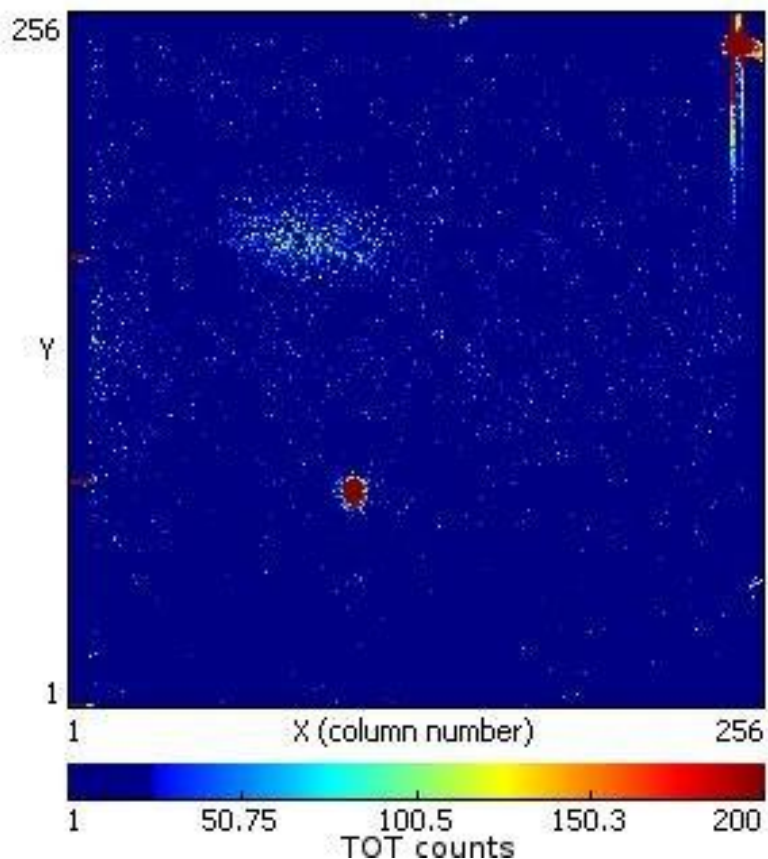


Measurement program:

- TIME mode:
 - drift velocity
 - electron counting
- TOT mode:
 - charging effect of SiProt
 - surface scan

TimeOverThreshold

Laser measurements



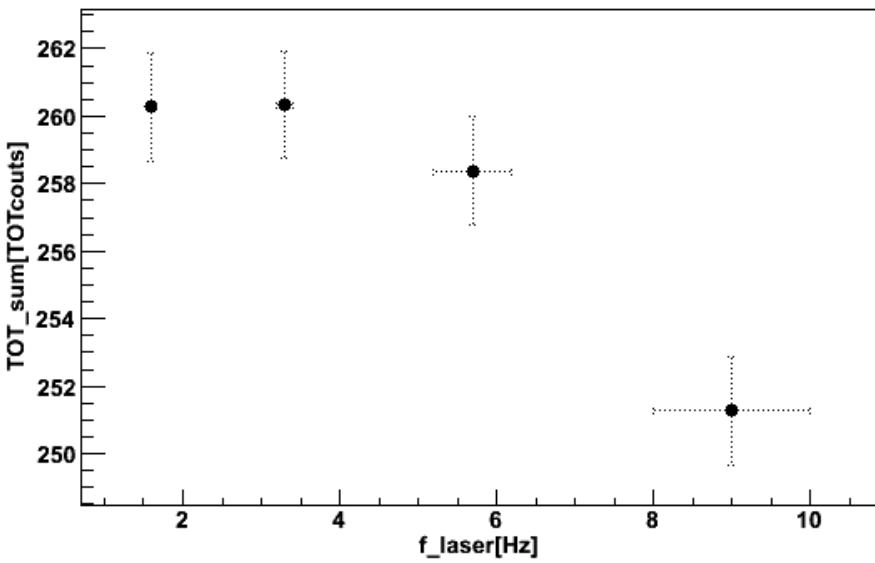
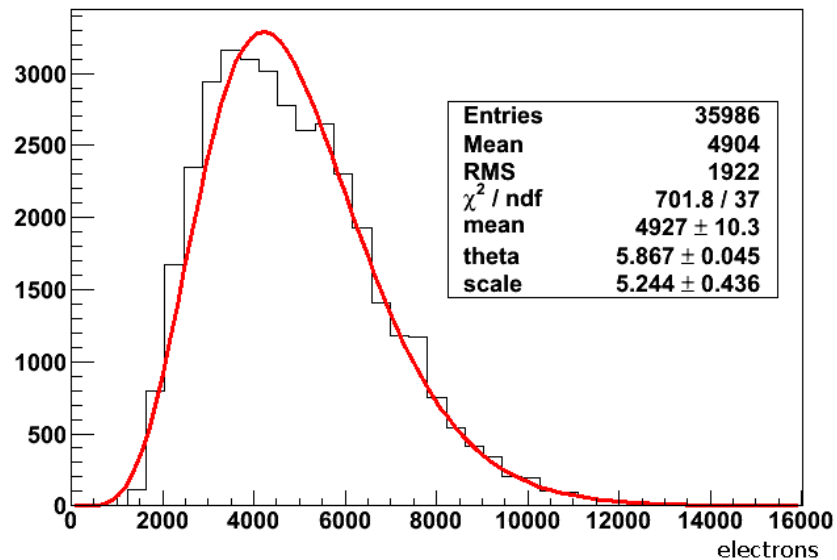
Problem: leakage current from grid to chip charges SiProt, reduces gain
⇒ Quantitative $G(f)$ measurements not possible, hot spots masked

Hit pixels in one run: LASER focus on chip, discharges at grid border

TimeOverThreshold

Laser measurements

Photo electrons per LASER pulse:
Poisson distributed: mean ≈ 4



Gain spectrum:

→ Mean $\approx 56\%$ of Micromegas gain

→ Narrow distribution (high Θ)

Could be due to problems with recent
TOT calibration (under study)

Data indicates gain drop for higher LASER repetition
rates (not as clear as for ^{55}Fe sources)

Conclusion

Fe55 spectra (primary electron counting):

- 97.8% single electron detection efficiency was reached in ArIso 95/5 with 117.9 ± 0.7 electrons in escape peak.
- A resolution of 9,73% FWHM was reached for the photo peak leading to an upper limit for the Fano factor of 0.26.

TOT mode (gain measurements):

- TOT mode can be used to measure the gain of a TimePix InGrid detector.
- Effects of the SiProt layer have to be taken into account:
 - reduces gain
 - SiProt layer can be modeled by a not perfect capacitor
 - measured time constant of capacitor ≈ 1 minute as predicted by model.
- Θ value between 0.5 and 2. for gains from 2000 to 5000.
- Pulsed LASER used to produce primary electrons by photo effect. Problems with Ingrid prevented gain measurement. Avalanche rate dependence of gain could not be analysed quantitatively.

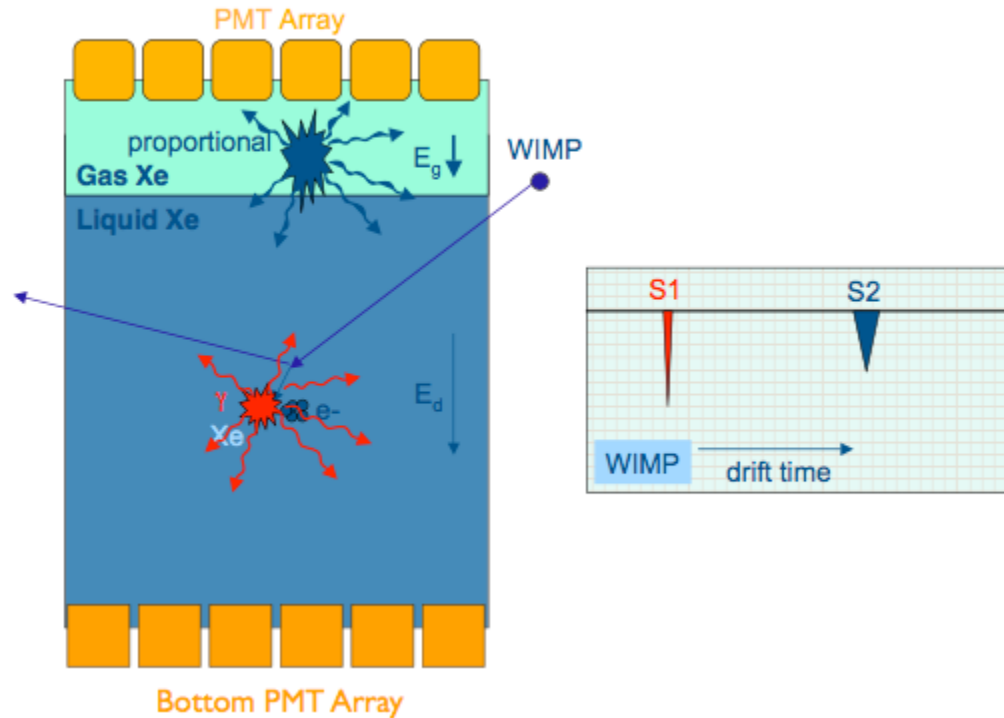
WIMP search, bi-phase Xenon

- GridPix TPC

as

WIMP / DBD

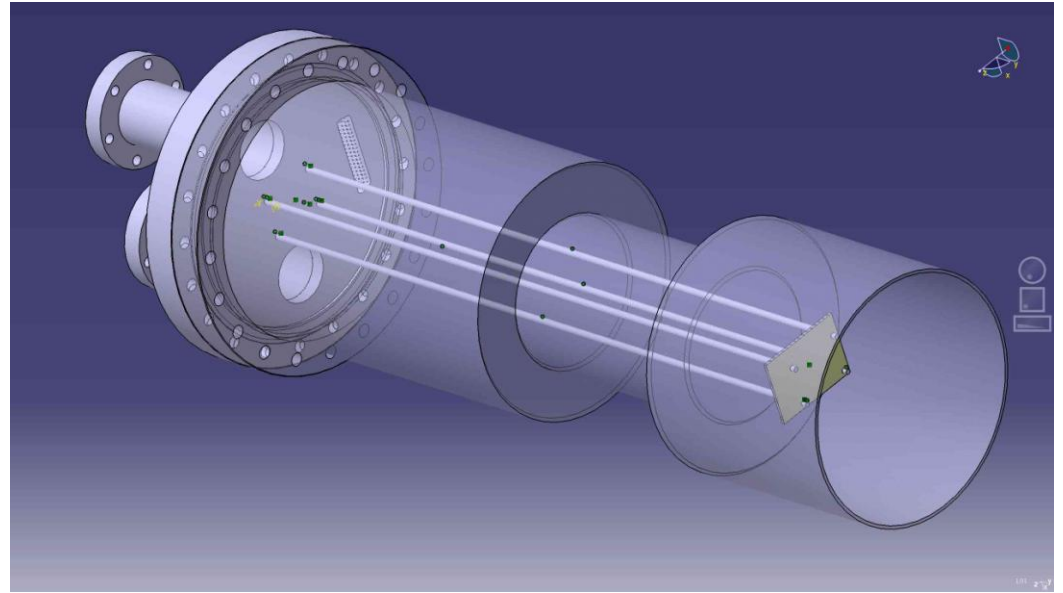
detector



Source: Direct Searches for Dark Matter, Elena Aprile, EPS - HEP, July 21 2009, Krakow, Poland

Gridpix in Xenon: Test setup

- Collaboration DARWIN/XENON
Columbia Univ., N.Y.



256

^{55}Fe in pure argon,
HVgrid = 340 V
P = 1 bar
T = -70 C
at NLR cryostat

gain: ~ 200 !

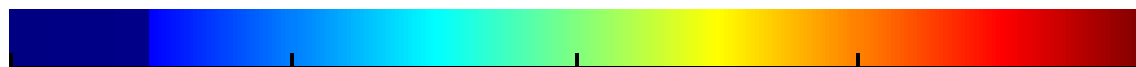
Y

1

1

X (column number)

256



1

10.75

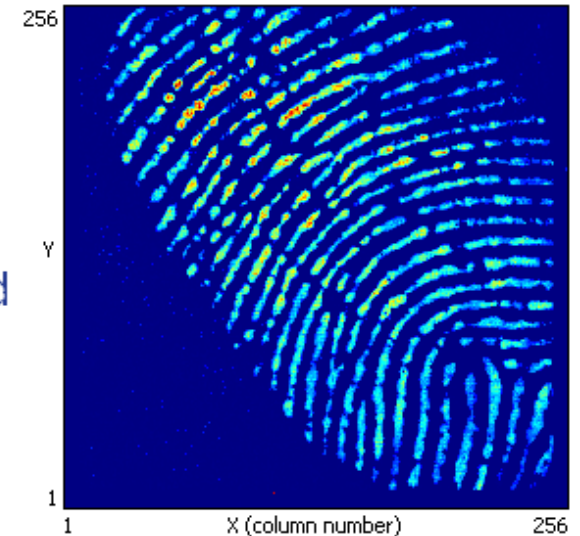
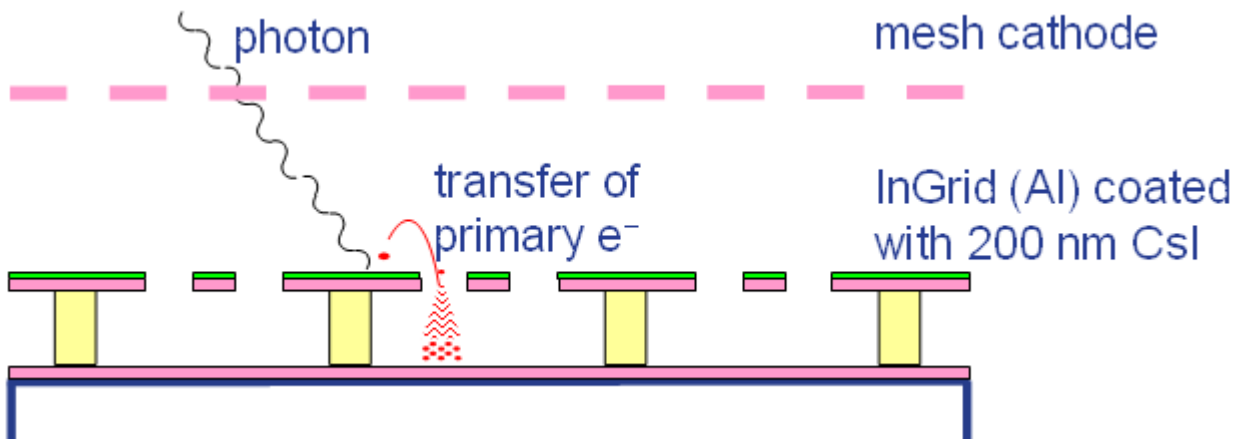
20.5

30.25

40

Expanding GridPix?

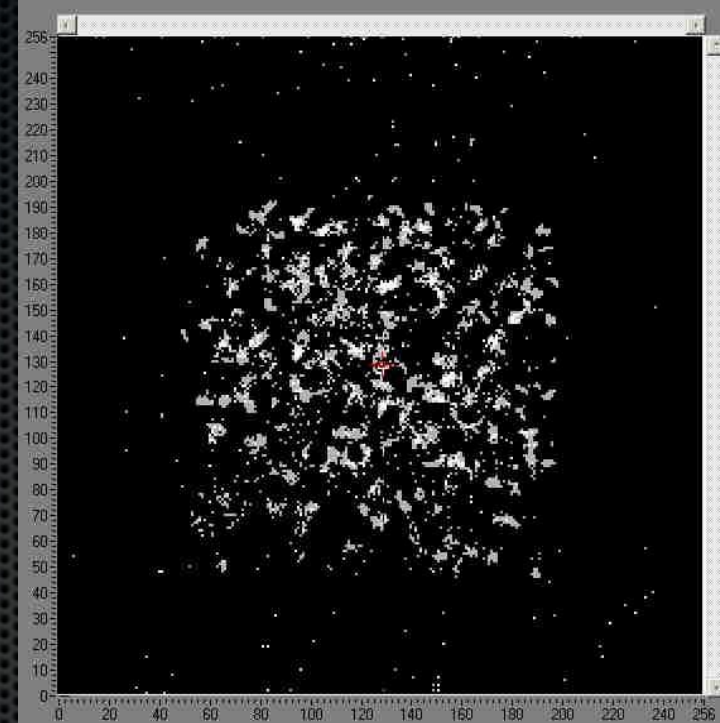
- Photoelectric effect
- Future possibility:
CsI layer on grid

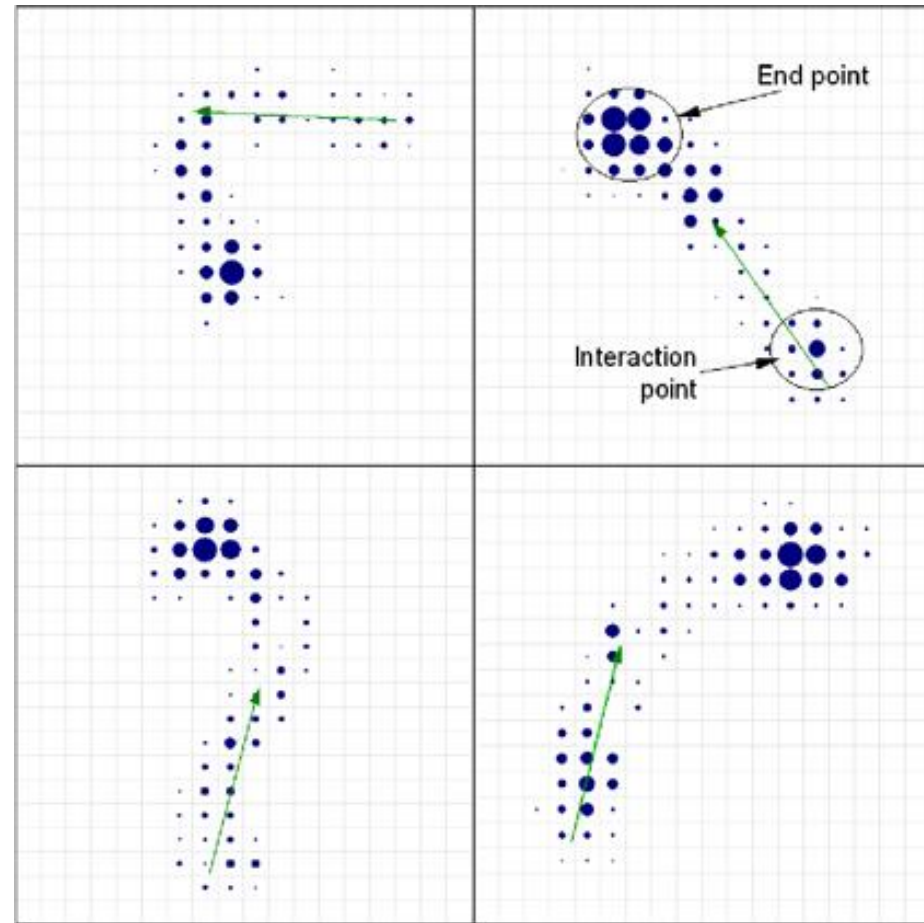
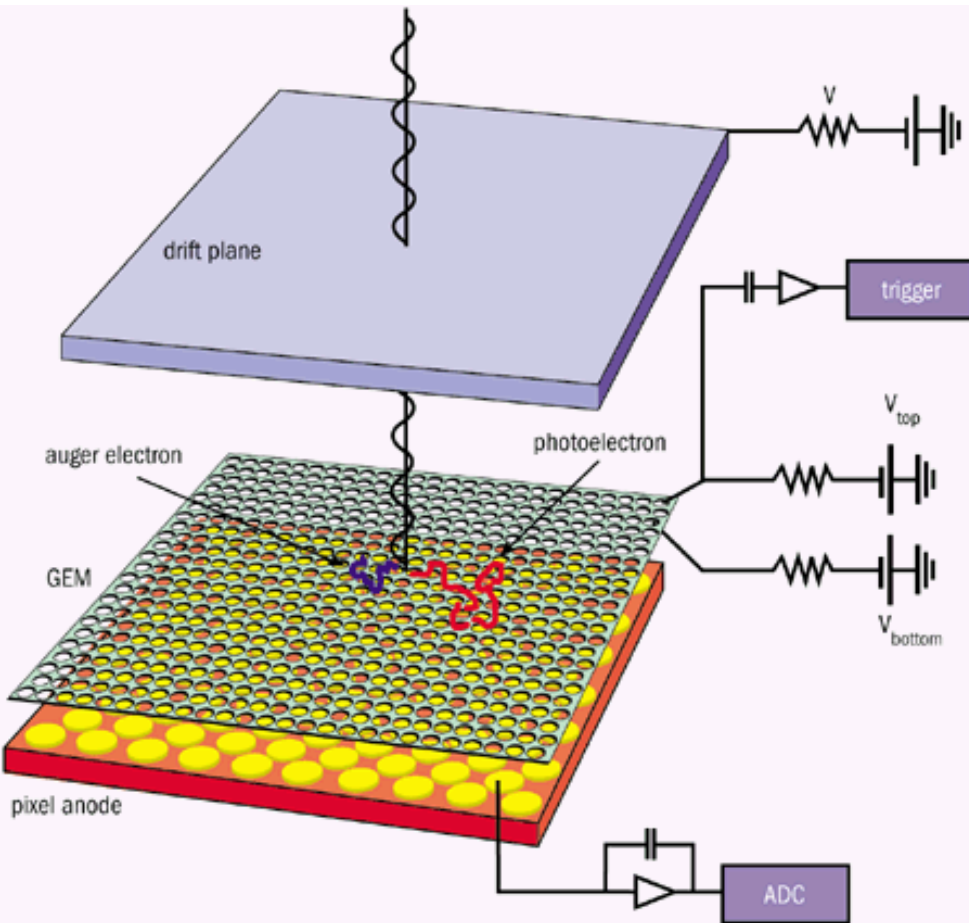


PolaPix

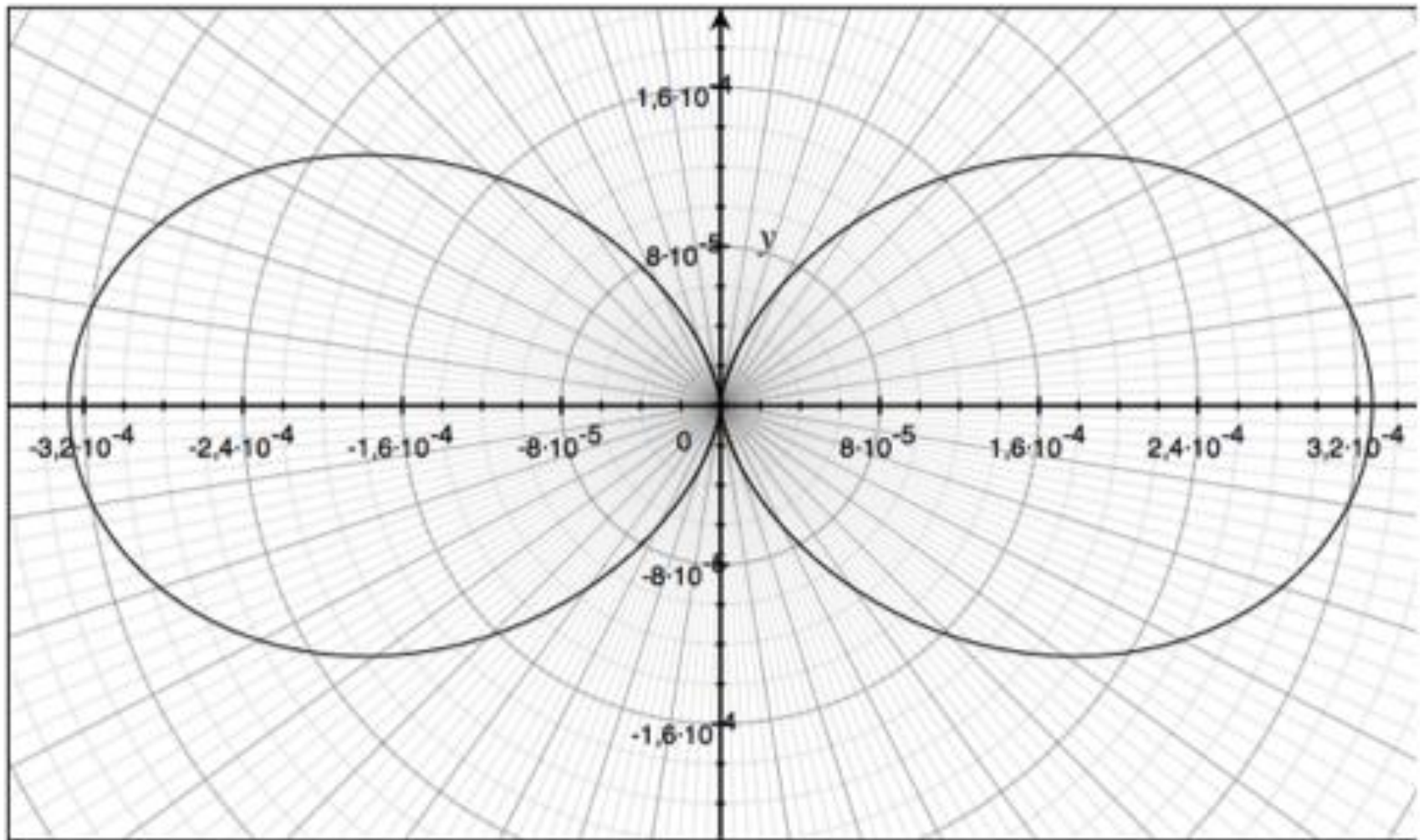
Using a GridPix detector for the 3D detection of polarized X-ray photons

Sjoerd Nauta - Nikhef





X-ray Polarimeter proposed by R. Bellazzini



Distribution of direction of photo-electron of (fully) polarised X-rays

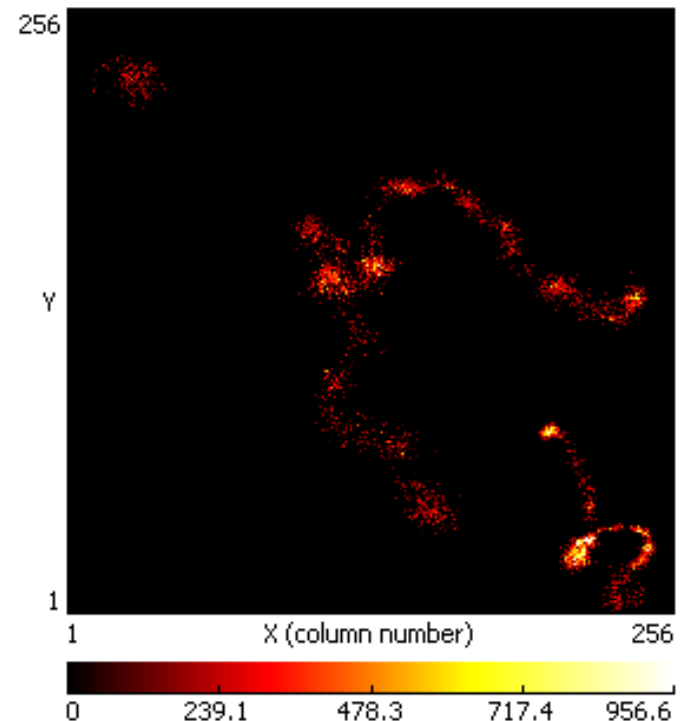
With ECAP/University of Erlangen

PolaPix

GridPix as (gas-filled) photon detector for applications in space observatories via tracking photo-electron or Compton-electron. Measurement of

- photon energy
- photon direction
- polarisation

in the range of 1 – 511 keV photons



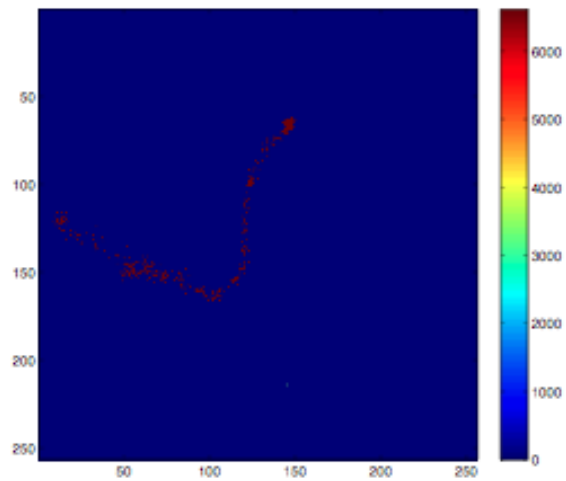


photo-electron
after photon interaction

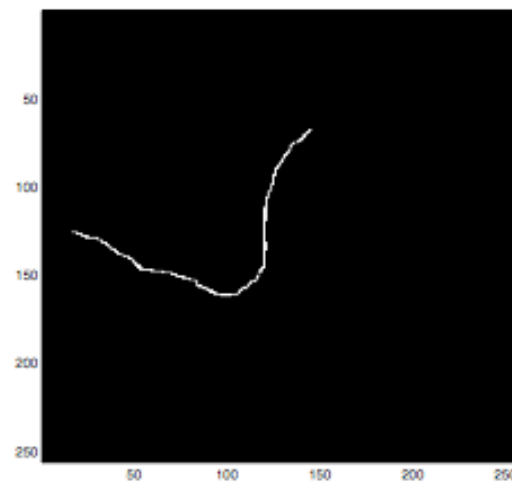
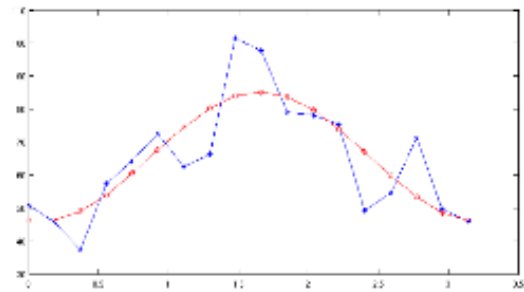
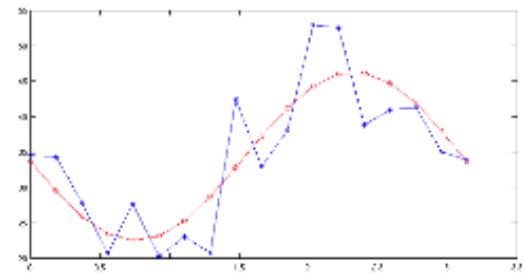


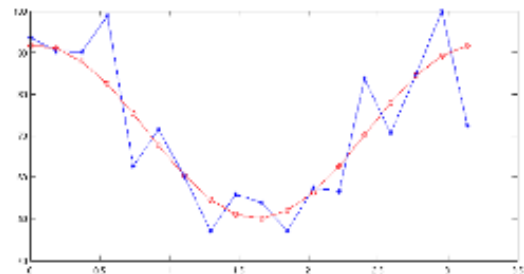
Figure 4.11: An example of a skeletonized track. On the left, the original measurement is shown, on the right the skeletonized version of the same track is shown. This picture has been made by the group at the university of Erlangen.



(a) Detector at 0 degrees



(b) Detector at 45 degrees

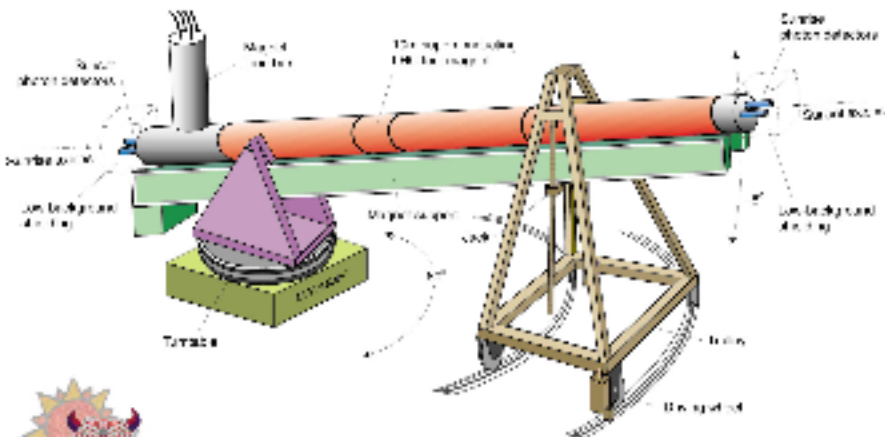


(c) Detector at 90 degrees

Figure 4.12: Distribution of angles of the polarized measurement data determined by analysis with the skeletonization algorithm (this analysis was done in Erlangen). The determined phases and asymmetries were: for 0 degrees: 3.5° , 29.4 %; for 45 degrees: 46.6° , 34.5%; for 90 degrees: 85.2° , 29.7 %. The plots were made by the astroparticle physics group in Erlangen. To make these plots, the data was corrected by using the angular distribution of a run made with an (unpolarized) Americium source. A correction factor was determined for each bin.

measured
polarisation
(beams was $\sim 90\%$
polarized)

Ingrid for CAST



Corn Axis Solar Telescope

Special attention on:

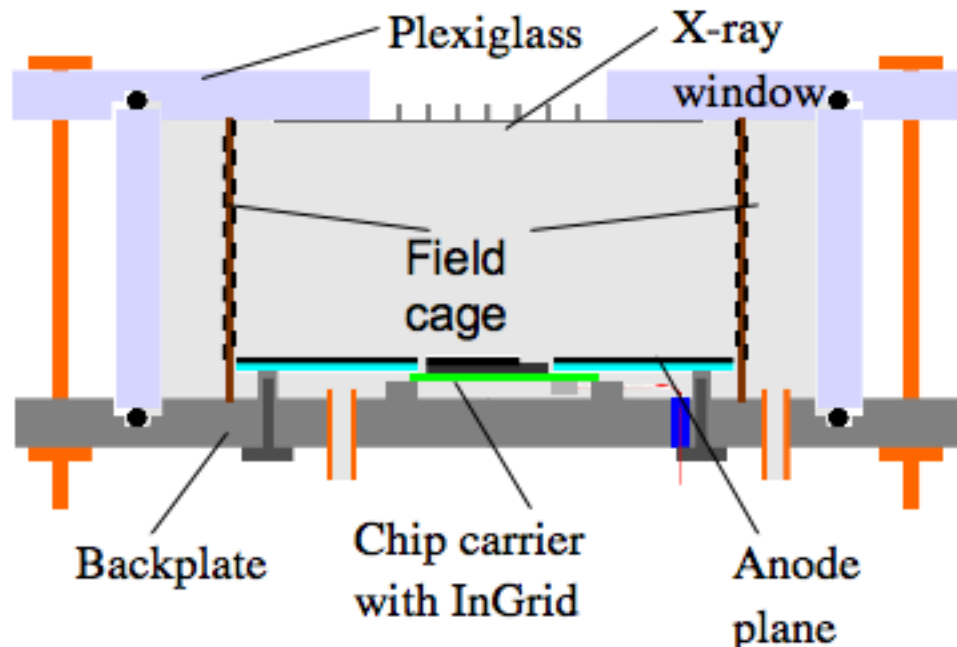
- As little copper as possible
- Radiopurity of materials

When construction is finished:

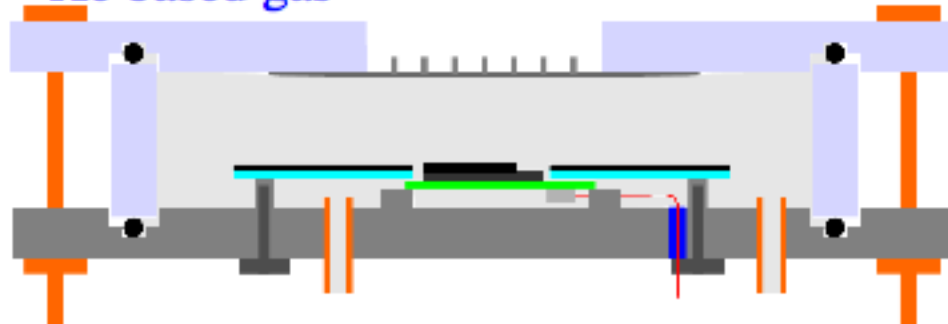
- Background rates
- X-ray spectra
- Study n background

Two detectors under discussion:

- 3 cm drift distance, field cage, Ar based gas



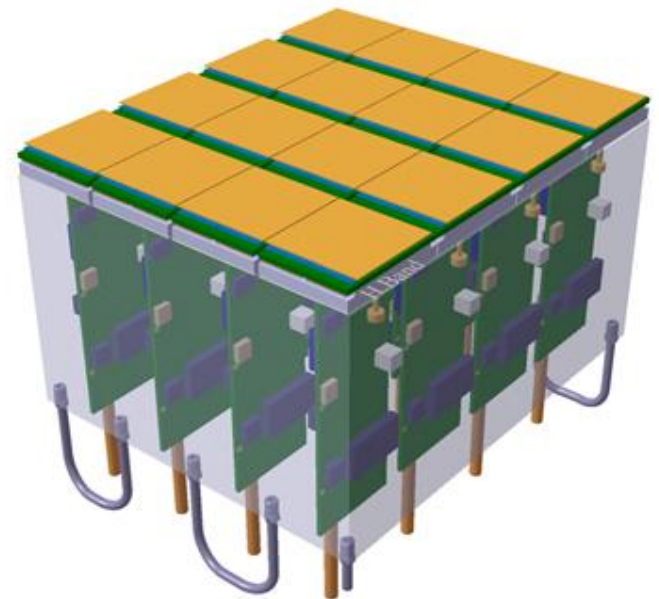
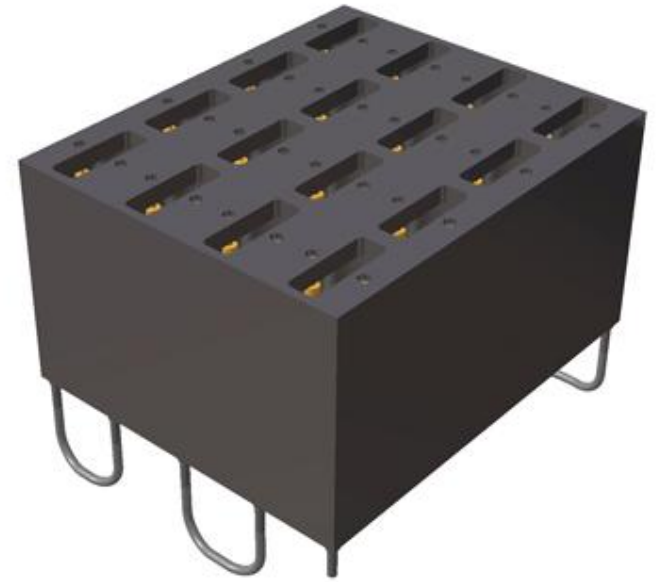
- 1 cm drift distance, without field cage, Xe based gas



Testbeam Aug 2010: ReLaXd readout for Medipix/TimePix works

Next-64 / ReLaXd / ReNexd

CO₂ cooling!





Development of miniHV at Nikhef

Small HV modules for laboratory use

Henk Boterenbrood, Harry van der Graaf,

Henk Groenstege, Ruud Kluit, Fred

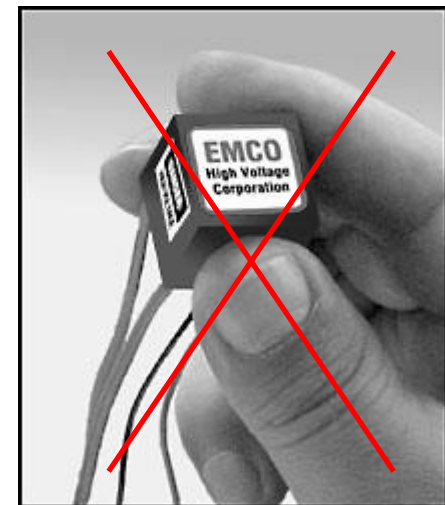
6th RD51 Collaboration workshop

Bari, 9 October 2010

Hartjes and Jaap Kuijt

Why developing HV power supplies?

- Getting a HV supply that is dedicated for gaseous detectors
 - Fast trip in sub μA region
 - Accurate current measurement in nA region
 - Small unit, not too expensive
 - Fast remote control
 - Gently ramping to target voltage

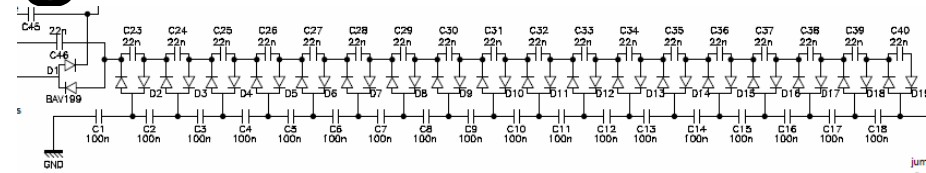


Preliminary specs of mini HV, version 2

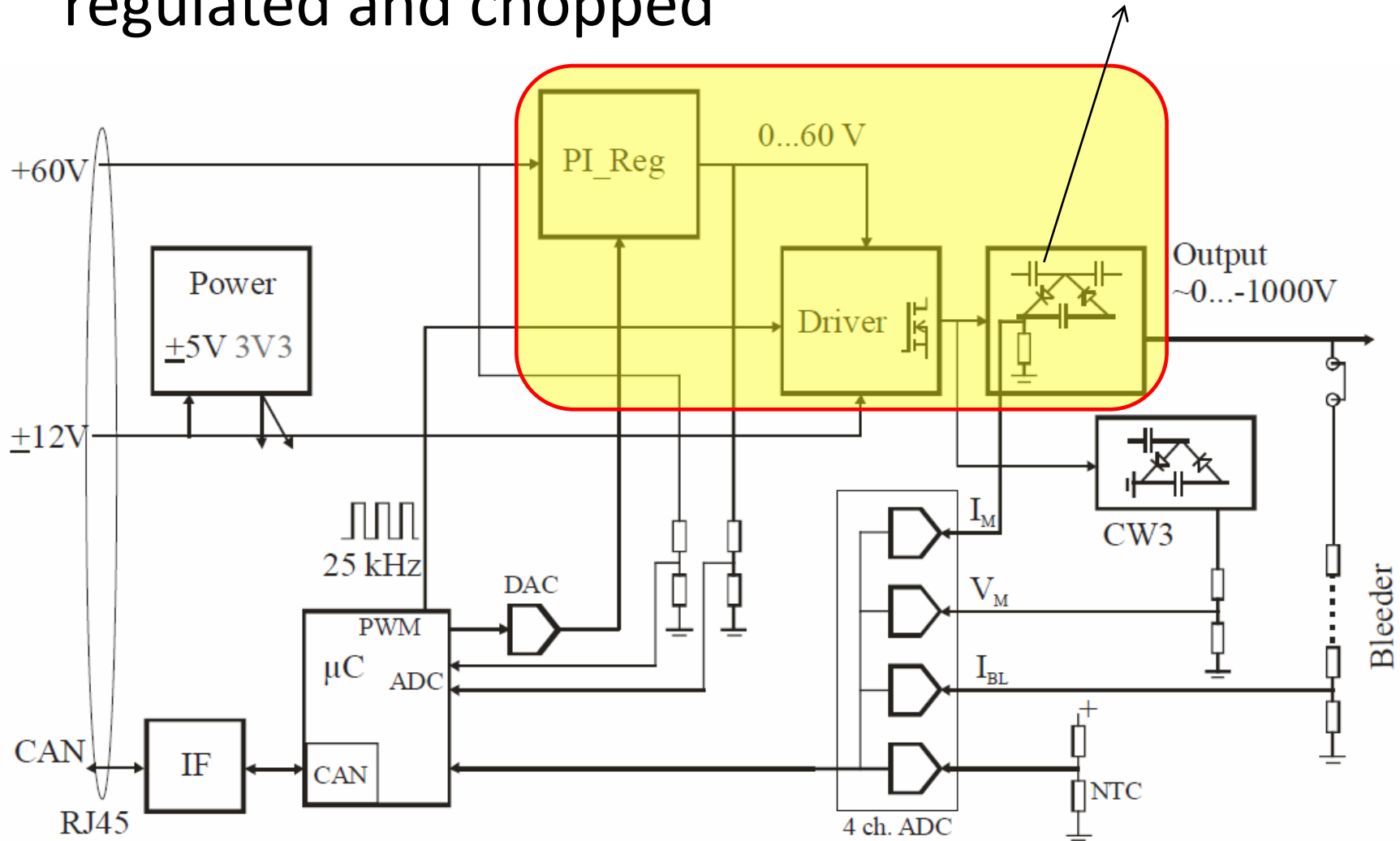
- Current measurement by 24 bit ADC
 - => high dynamic range
- Communication by **CANopen** protocol
- Single RJ45 cable for **CAN communication and supply**



High voltage generation

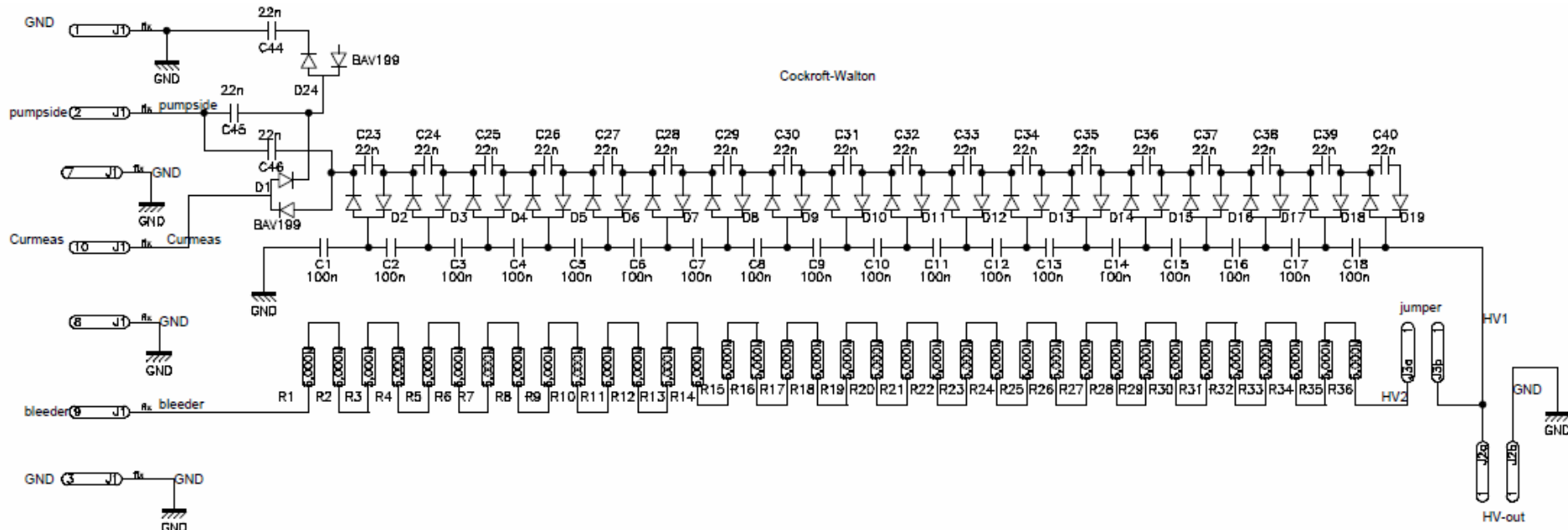


- 60 V input voltage regulated and chopped



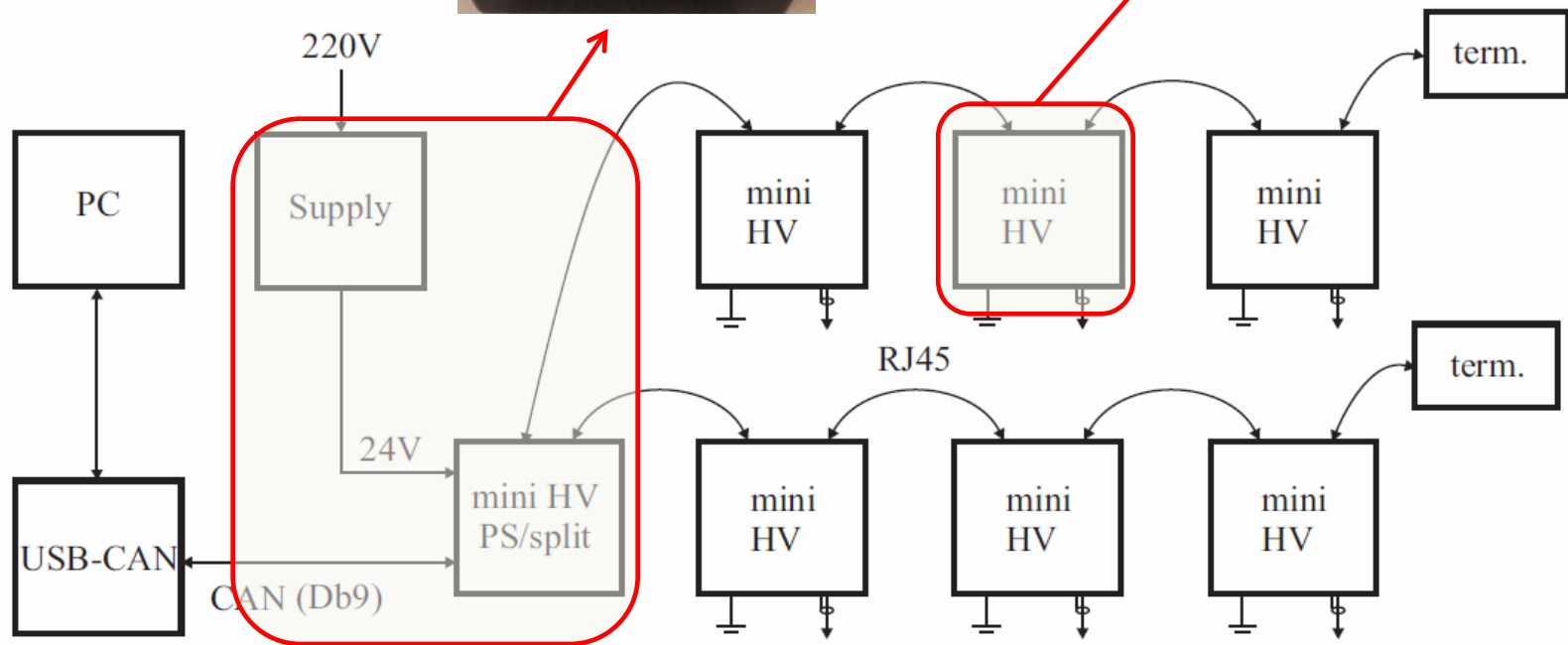
Cockcroft-Walton circuit

- In principle no feedback at end of diode chain, only from idle diode circuit
 - Regulation less direct, depending on diode



CANopen communication to multiple mini HVs

- Two RJ45 cables to supply up to 6 mini HV units

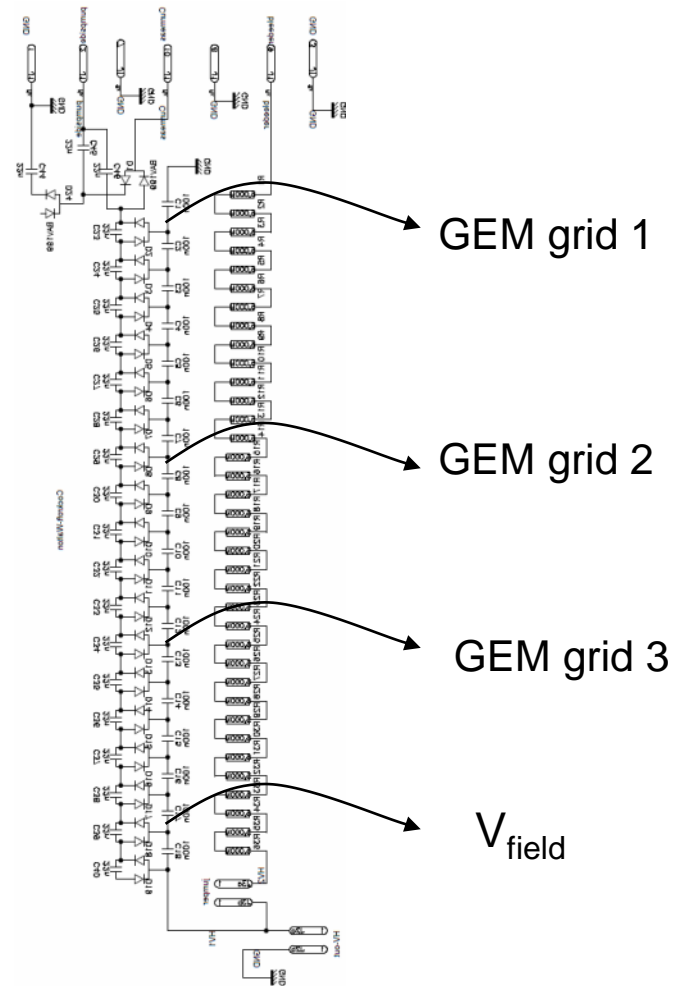


Ideas for other miniHV modules

1.-2000 V version

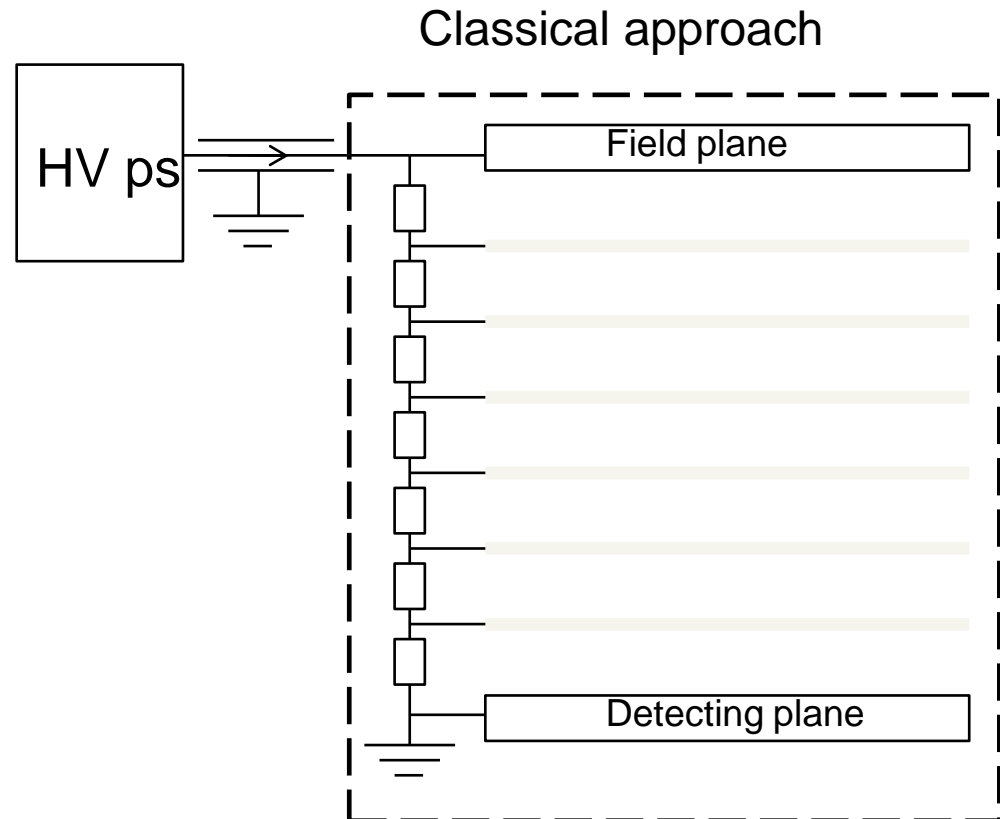
2. Single MiniHV with 3 - 5 outputs (-3000 V?) from Cockcroft Walton circuit for **triple GEM**

- Regulating GEM voltages by selecting the desired CW



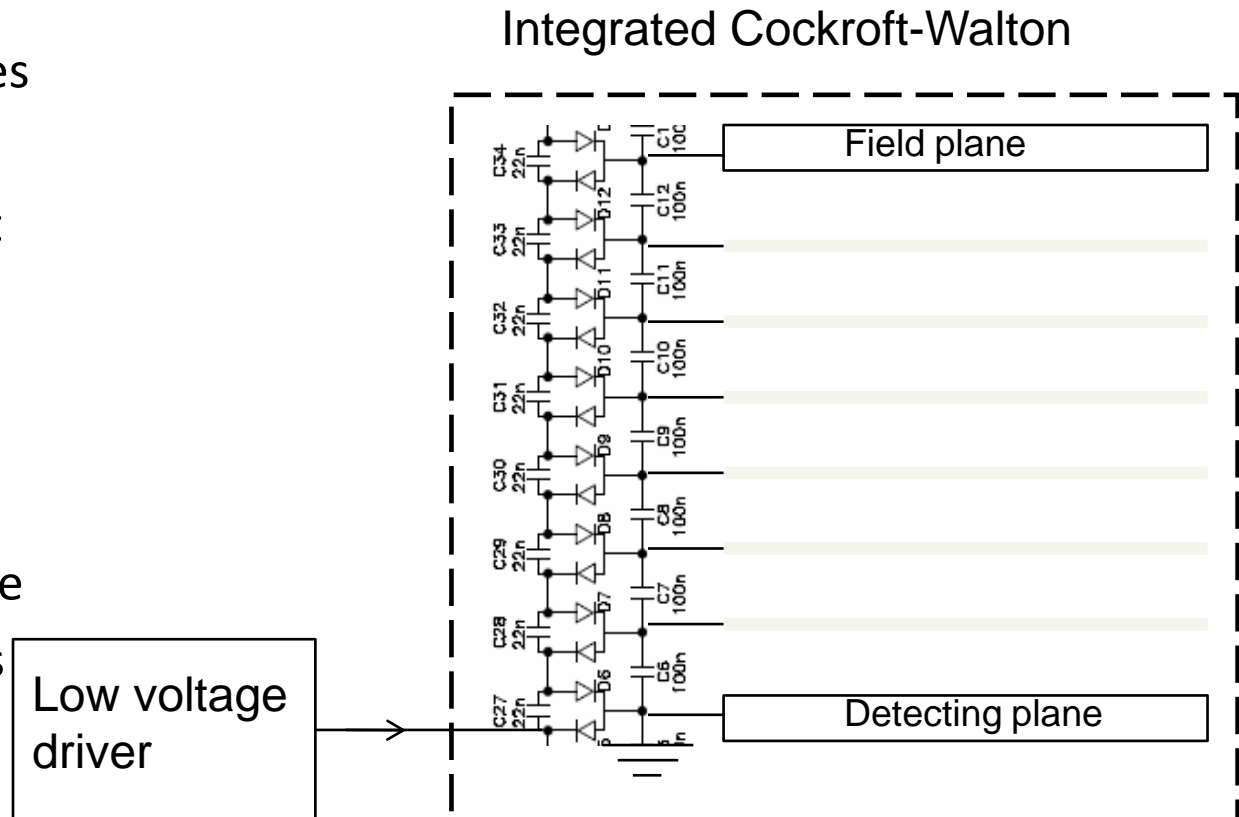
Filed cage for large TPCs

- Large TPC (1 m) requires very high voltage and low driftfield gas (CF₄ mixtures)
 - Field shaping strips to define proper drift field
- Substantial HV needed



Integrating Cockcroft Walton technology

- Cockcroft-Walton chain integrated in field cage
 - No external HV lines
 - Only LV driver
 - No bleeder current
 - => low trip level possible
- HVs in 100 kV region relatively easy to realize
 - Everything remains within the cage structure



- change name GridPix in GasPix (Bellazzini's naming!)
- need to start up production of Victor/Yevgen InGrids
- need to do R&D for all-ceramic GridPix
- formulate problems of gas gain: influence of UV photon:
 - how can Ar/CO₂ work in GasPix, while it causes multi-avalanches in ATLAS MDTs?
 - discharge quenching is now known, but
 - discharge sources/causes? high rate effects? Sharp edges?
 - Raether condition: rather empirical. Can we make a model?
 - Why is P10 (Ar/Methane 90/10) a MUCH good quenching mixture in GridPix?